

## TPS65132 シングル・インダクタ、デュアル出力電源

### 1 特長

- 入力電圧範囲: 2.5V~5.5V
- $V_{POS}$ 昇圧コンバータ:  
4V~6V (0.1Vステップ)
- $V_{NEG}$ 反転昇降圧型コンバータ:  
-6V~-4V (0.1Vステップ)
- 最大出力電流:  
80mAまたは150mA
- 非常に優れた総合効率
  - $I_{OUT} > 10\text{mA}$ において85%超
  - $I_{OUT} > 40\text{mA}$ において90%超
- 優れた性能
  - 非常に優れた過渡応答
  - 温度範囲の全体にわたって  
出力電圧精度1%
- $I^2C$ インターフェイス
  - 電源オン/オフのシーケンシング・オプションを  
プログラム可能
  - 出力電圧を柔軟にプログラム可能
  - アクティブ出力放電をプログラム可能
  - 1000回以上プログラム可能な不揮発性メモリ
- 低電圧誤動作防止と過熱保護
- 2つのパッケージ・オプション
  - 15ボールCSPパッケージ
  - 20ピンQFNパッケージ

### 2 アプリケーション

- 小型または中型のバイポーラLCDディスプレイ
  - スマートフォン、タブレット
  - カメラ、GPS
  - ホーム・オートメーション、ポイント・オブ・セールス
  - ウェアラブル機器(スマートウォッチ、活動量計)
- 汎用分割レール電源
  - 差動オーディオ、ヘッドフォン・アンプ
  - 計測機器、オペアンプ、コンパレータ
  - DAC/ADC

### 3 概要

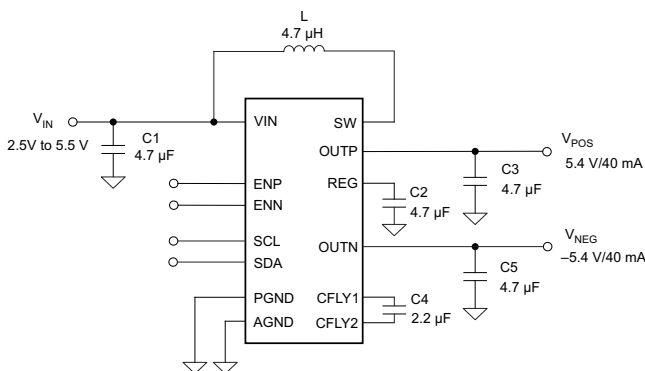
TPS65132ファミリは、一般的な正/負駆動アプリケーションに電源を供給するよう設計されています。このデバイスは、両方の出力に単一インダクタのスキーマを使用し、最小のソリューション・サイズ、少ない部品点数、高効率を実現しています。このデバイスは、低ノイズで最高のラインおよび負荷レギュレーションを実現しています。2.5V~5.5Vの入力電圧範囲により、シングル・セル・バッテリー(リチウム・イオン、ニッケル・リチウム、リチウム・ポリマー)で駆動される製品、および3.3Vと5Vの固定電圧レールに対して最適化されています。TPS65132ファミリは、80mAおよび150mAの出力電流オプションがあり、40mAにもプログラム可能です。CSPとQFNの両方のパッケージ・オプションを利用可能です。

#### 製品情報 (1)

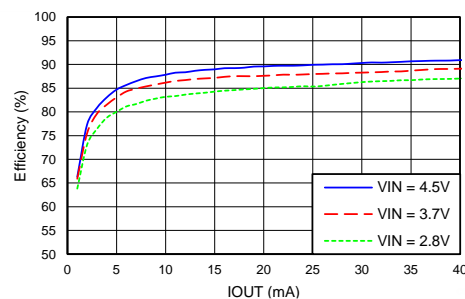
| 型番                      | パッケージ      | 本体サイズ(公称.)    |
|-------------------------|------------|---------------|
| TPS65132<br>-B、-L、-T、-S | DSBGA (15) | 2.11mm×1.51mm |
| TPS65132W               | WQFN (20)  | 4.00mm×3.00mm |

(1) 利用可能なすべてのパッケージについては、このデータシートの末尾にある注文情報を参照してください。

### 標準アプリケーション



### 効率 対 出力電流



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## 4 改訂履歴

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

| Revision G (August 2015) から Revision H に変更                            | Page |
|---|------|
| • TPS65132Sから製品プレビューを削除   | 1    |
| • Changed <a href="#">Device Comparison Table</a>                     | 4    |
| • Added description of clock stretching                               | 17   |
| • Deleted detailed I <sup>2</sup> C interface description             | 17   |
| • Added that the DLYx Register is only valid for TPS65132Sx versions. | 22   |
| • Changed <a href="#">Table 6</a>                                     | 23   |

| Revision F (June 2015) から Revision G に変更               | Page |
|--|------|
| • Changed scope figures for Boost Converter switching. | 13   |

| Revision E (November 2014) から Revision F に変更                                       | Page |
|--|------|
| • Added TPS65132L1 device to Device Comparison table                               | 4    |
| • Added TPS65132T6 device to the Device Comparison Table.                          | 4    |
| • Separated LOGIC SCL, SDA spec MIN/MAX from LOGIC EN, ENN, ENP, SYNC spec MIN/MAX | 9    |
| • Changed <a href="#">DAC Registers</a> section for clarity                        | 19   |
| • Added <a href="#">High-current Applications (≤ 150 mA)</a> section               | 44   |

| Revision D (October 2014) から Revision E に変更          | Page |
|--|------|
| • Added TPS65132L0 device to Device Comparison table | 4    |

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**Revision C (July 2014) から Revision D に変更** **Page**


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- 「製品情報」表で、パッケージの種類を業界標準の識別子に変更 ..... 1
- 

**Revision B (May 2014) から Revision C に変更** **Page**


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- Added note to Device Comparison Table ..... 4
  - Added reference to [Power-Down And Discharge \(LDO\)](#) and [Power-Down And Discharge \(CPN\)](#) ..... 12
  - Added [Table 1](#) and various references to it ..... 14
  - Added "[Power-Down And Discharge \(CPN\)](#) shows the  $V_{NEG}$  discharge behavior of each device variant"..... 16
  - Added [Table 2](#) and various references to it ..... 16
  - Added note to [Figure 18](#) ..... 23
- 

**Revision A (August 2013) から Revision B に変更** **Page**


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- 新しいデータシートの標準フォーマットに変更 ..... 1
  - 「製品情報」表に新しいパッケージ・オプション(QFN)を追加 ..... 1
  - Added new package option (QFN) to Pin Configurations section ..... 7
  - Added the ESD Ratings table ..... 8
- 

**2013年6月発行のものから更新** **Page**


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- Added TPS65132Bx devices to the Device Comparison table ..... 4
-

## 5 Device Comparison Table

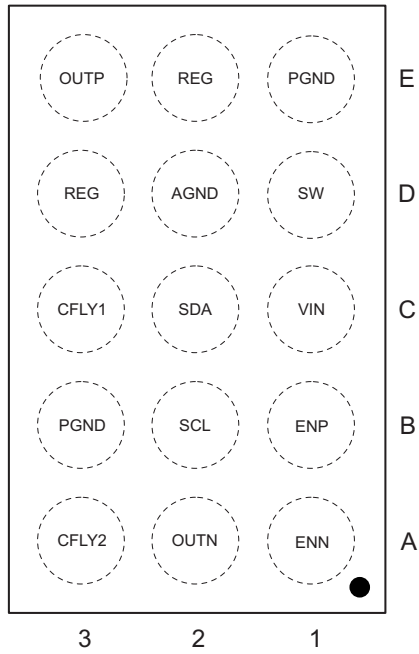
| PART NUMBER <sup>(1)</sup> | PRE-PROGRAMMED OUTPUT VOLTAGES                        | I <sub>OUT_MAX</sub> | PRE-PROGRAMMED I <sub>OUT</sub> | PRE-PROGRAMMED ACTIVE DISCHARGE <sup>(2)</sup> | STARTUP TIME V <sub>POS</sub> / V <sub>NEG</sub> <sup>(3)</sup> | I <sub>SD</sub> | PACKAGE |
|----------------------------|---|----------------------|---------------------------------|--|---|-----------------|---------|
| TPS65132A                  | V <sub>POS</sub> = 5.4 V<br>V <sub>NEG</sub> = -5.4 V | 80 mA                | 40 mA                           | V <sub>POS</sub> / V <sub>NEG</sub>            | FAST  | 30 μA           | CSP     |
| TPS65132A0                 | V <sub>POS</sub> = 5.0 V<br>V <sub>NEG</sub> = -5.0 V |                      |                                 |  |   |                 |         |
| TPS65132B                  | V <sub>POS</sub> = 5.4 V<br>V <sub>NEG</sub> = -5.4 V | 80 mA                | 40 mA                           | V <sub>POS</sub> / V <sub>NEG</sub>            | FAST  | 130 nA          | CSP     |
| TPS65132B0                 | V <sub>POS</sub> = 5.0 V<br>V <sub>NEG</sub> = -5.0 V |                      |                                 |  |   |                 |         |
| TPS65132B5                 | V <sub>POS</sub> = 5.5 V<br>V <sub>NEG</sub> = -5.5 V |                      |                                 |  |   |                 |         |
| TPS65132B2                 | V <sub>POS</sub> = 5.2 V<br>V <sub>NEG</sub> = -5.2 V | 80 mA                | 40 mA                           | V <sub>POS</sub> / V <sub>NEG</sub>            | SLOW  | 130 nA          | CSP     |
| TPS65132L                  | V <sub>POS</sub> = 5.4 V<br>V <sub>NEG</sub> = -5.4 V |                      |                                 |  |   |                 |         |
| TPS65132L0                 | V <sub>POS</sub> = 5.0 V<br>V <sub>NEG</sub> = -5.0 V |                      |                                 |  |   |                 |         |
| TPS65132L1 <sup>(4)</sup>  | V <sub>POS</sub> = 5.1 V<br>V <sub>NEG</sub> = -5.1 V | 80 mA                | 40 mA                           | V <sub>POS</sub> / V <sub>NEG</sub>            | SLOW  | 130 nA          | CSP     |
| TPS65132T6                 | V <sub>POS</sub> = 5.6 V<br>V <sub>NEG</sub> = -5.6 V | 80 mA                | 80 mA                           | V <sub>POS</sub> / V <sub>NEG</sub>            | SLOW  | 130 nA          | CSP     |
| TPS65132S                  | V <sub>POS</sub> = 5.4 V<br>V <sub>NEG</sub> = -5.4 V | 150 mA               | 80 mA                           | V <sub>POS</sub> / V <sub>NEG</sub>            | SLOW  | 130 nA          | CSP     |
| TPS65132W                  | V <sub>POS</sub> = 5.4 V<br>V <sub>NEG</sub> = -5.4 V | 80 mA                | 80 mA                           | V <sub>POS</sub> / V <sub>NEG</sub>            | SLOW  | 130 nA          | QFN     |

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at [www.ti.com](http://www.ti.com)
- (2) See [Power-Down And Discharge \(LDO\)](#) and [Power-Down And Discharge \(CPN\)](#) for a detailed description of how each device variant implements the active discharge function.
- (3) Please refer to [Power-Up And Soft-Start \(LDO\)](#) and [Power-Up And Soft-Start \(CPN\)](#) for more details.
- (4) Product preview.

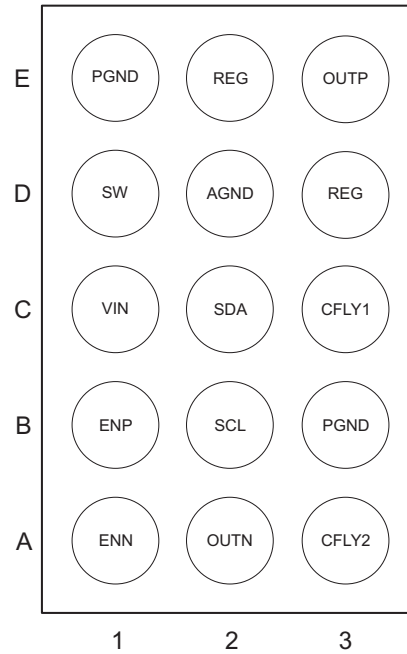
## 6 Pin Configuration and Functions

### YFF Package 15 Bumps

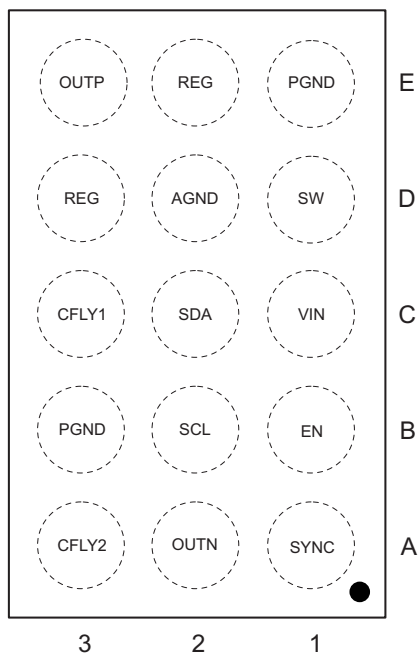
(top view)  
TPS65132Ax / Bx / Lx / Tx



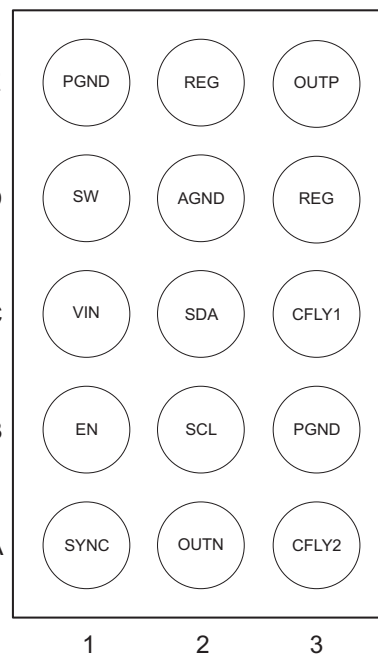
(bottom view)  
TPS65132Ax / Bx / Lx / Tx



(top view)  
TPS65132Sx

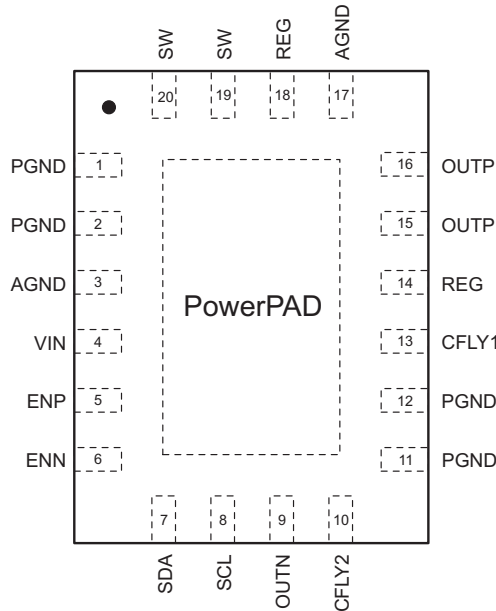
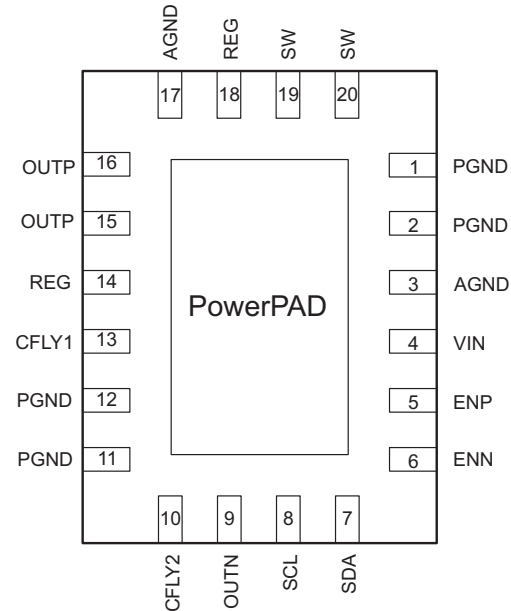


(bottom view)  
TPS65132Sx



**Pin Functions**

| PIN   |                |    | I/O | DESCRIPTION   |
|-------|----------------|----|-----|---|
| NAME  | Ax, Bx, Lx, Tx | Sx |     |   |
| AGND  | D2             | D2 | —   | Analog ground   |
| CFLY1 | C3             | C3 | I/O | Negative charge pump flying capacitor pin                               |
| CFLY2 | A3             | A3 | I/O | Negative charge pump flying capacitor pin                               |
| EN    | —              | B1 |     | Enable pin (sequence programmed)  |
| ENN   | A1             | —  | I   | Enable pin for $V_{NEG}$ rail   |
| ENP   | B1             | B1 | I   | Enable pin for $V_{POS}$ rail   |
| OUTP  | E3             | E3 | O   | Output pin of the LDO ( $V_{POS}$ )                                     |
| OUTN  | A2             | A2 | O   | Output pin of the negative charge pump ( $V_{NEG}$ )                    |
| PGND  | B3             | B3 | —   | Power ground  |
|       | E1             | E1 |     |   |
| REG   | D3             | D3 | I/O | Boost converter output pin  |
|       | E2             | E2 |     |   |
| SCL   | B2             | B2 | I/O | I <sup>2</sup> C interface clock signal pin                             |
| SDA   | C2             | C2 | I/O | I <sup>2</sup> C interface data signal pin                              |
| SW    | D1             | D1 | I/O | Switch pin of the boost converter                                       |
| SYNC  | —              | A1 | I   | Synchronization pin. 150 mA current enabled if this pin is pulled HIGH. |
| VIN   | C1             | C1 | I   | Input voltage supply pin  |

**QFN Package  
20 Pins**
**RVC package  
(top view)**

**RVC package  
(bottom view)**

**Pin Functions**

| PIN   |    | I/O | DESCRIPTION  |
|-------|----|-----|--|
| NAME  | Wx |     |  |
| AGND  | 3  | —   | Analog ground  |
|       | 17 |     |  |
| CFLY1 | 13 | I/O | Negative charge pump flying capacitor pin            |
| CFLY2 | 10 | I/O | Negative charge pump flying capacitor pin            |
| ENN   | 6  | I   | Enable pin for $V_{NEG}$ rail                        |
| ENP   | 5  | I   | Enable pin for $V_{POS}$ rail                        |
| OUTP  | 16 | O   | Output pin of the LDO ( $V_{POS}$ )                  |
|       | 15 |     |  |
| OUTN  | 9  | O   | Output pin of the negative charge pump ( $V_{NEG}$ ) |
| PGND  | 1  | —   | Power ground   |
|       | 2  |     |  |
|       | 11 |     |  |
|       | 12 |     |  |
| REG   | 14 | I/O | Boost converter output pin                           |
|       | 18 |     |  |
| SCL   | 8  | I/O | I <sup>2</sup> C interface clock signal pin          |
| SDA   | 7  | I/O | I <sup>2</sup> C interface data signal pin           |
| SW    | 19 | I/O | Switch pin of the boost converter                    |
|       | 20 |     |  |
| VIN   | 4  | I   | Input voltage supply pin                             |

## 7 Specifications

### 7.1 Absolute Maximum Ratings<sup>(1)(2)</sup>

over operating free-air temperature range (unless otherwise noted)

|  |   | VALUE                                   |     | UNIT |
|--|---|---|-----|------|
|  |   | MIN                                     | MAX |      |
| Voltage range                                  | CFLY1, EN, ENN, ENP, OUTP, REG, SCL, SDA, SW, SYNC, VIN | -0.3                                    | 7   | V    |
|  | CFLY2, OUTN   | -7                                      | 0.3 | V    |
| Continuous total power dissipation             |   | See <a href="#">Thermal Information</a> |     |      |
| Operating junction temperature, T <sub>J</sub> |   | -40                                     | 150 | °C   |
| Operating ambient temperature, T <sub>A</sub>  |   | -40                                     | 85  | °C   |
| Storage temperature, T <sub>stg</sub>          |   | -65                                     | 150 | °C   |

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to ground.

### 7.2 ESD Ratings

|                  |   | VALUE | UNIT |
|------------------|---|-------|------|
| V <sub>ESD</sub> | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>             | ±2000 | V    |
|                  | Charged device model (CDM) per JEDEC specification JESD22-C101, all pins <sup>(2)</sup> | ±500  | V    |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 7.3 Recommended Operating Conditions

|  |                                     | MIN | TYP | MAX | UNIT |
|--|-------------------------------------|-----|-----|-----|------|
| V <sub>IN</sub>  | Input voltage range                 | 2.5 |     | 5.5 | V    |
| L  | Inductor <sup>(1)</sup>             | 2.2 |     | 4.7 | μH   |
| C <sub>IN</sub>  | Input capacitor <sup>(1)(2)</sup>   | 4.7 |     |     | μF   |
| C <sub>FLY</sub>   | Flying capacitor <sup>(1)(2)</sup>  | 2.2 |     |     | μF   |
| C <sub>OUTP</sub> , C <sub>OUTN</sub> , C <sub>REG</sub> | Output capacitors <sup>(1)(2)</sup> | 4.7 |     |     | μF   |
| T <sub>A</sub>   | Operating ambient temperature       | -40 |     | 85  | °C   |
| T <sub>J</sub>   | Operating junction temperature      | -40 |     | 125 | °C   |

- (1) Please see [Detailed Description](#) section for further information.
- (2) X7R (or better dielectric material) is recommended.

### 7.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |  | TPS65132   | TPS65132  | UNIT |
|-------------------------------|--|------------|-----------|------|
|                               |  | YFF        | RVC       |      |
|                               |  | (15) BALLS | (20) PINS |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 76.5       | 39.0      | °C/W |
| R <sub>θJctop</sub>           | Junction-to-case (top) thermal resistance    | 0.2        | 42.7      | °C/W |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 44         | 13.6      | °C/W |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 1.6        | 0.6       | °C/W |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 43.4       | 13.6      | °C/W |
| R <sub>θJcbot</sub>           | Junction-to-case (bottom) thermal resistance | N/A        | 3.8       | °C/W |

- (1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).



## 7.5 Electrical Characteristics

$V_{IN} = 3.7\text{ V}$ ,  $EN = ENN = ENP = V_{IN}$ ,  $V_{POS} = 5.4\text{ V}$ ,  $V_{NEG} = -5.4\text{ V}$ ,  $T_A = -40^\circ\text{C}$  to  $85^\circ\text{C}$ ; typical values are at  $T_A = 25^\circ\text{C}$  (unless otherwise noted).

| PARAMETER   |  | TEST CONDITIONS  | MIN  | TYP  | MAX  | UNIT             |
|---|--|--|------|------|------|------------------|
| <b>SUPPLY CURRENT</b>                                   |  |  |      |      |      |                  |
| $V_{IN}$  | Input voltage range                      |  | 2.5  |      | 5.5  | V                |
| $V_{UVLO}$  | Undervoltage lockout threshold           | $V_{IN}$ rising  | 2.3  |      | 2.5  | V                |
|   |  | $V_{IN}$ falling   | 2.1  |      | 2.3  |                  |
| $I_Q$   | Quiescent current                        |  |      | 0.54 |      | mA               |
|   | Thermal shutdown                         |  |      | 140  |      | $^\circ\text{C}$ |
|   | Thermal shutdown hysteresis              |  |      | 5    |      | $^\circ\text{C}$ |
| <b>LOGIC EN, ENN, ENP, SYNC</b>                         |  |  |      |      |      |                  |
| $V_{IH}$  | High level input voltage                 | $V_{IN} = 2.5\text{ V}$ to $5.5\text{ V}$                            | 1.1  |      |      | V                |
| $V_{IL}$  | Low level input voltage                  |  |      |      | 0.4  |                  |
| $R_{EN}$  | Pulldown resistors                       |  | 200  |      |      | k $\Omega$       |
| <b>LOGIC SCL, SDA</b>                                   |  |  |      |      |      |                  |
| $V_{IH}$  | High level input voltage                 | $V_{IN} = 2.5\text{ V}$ to $5.5\text{ V}$                            | 1.1  |      |      | V                |
| $V_{IL}$  | Low level input voltage                  |  |      |      | 0.54 |                  |
| <b>BOOST CONVERTER</b>                                  |  |  |      |      |      |                  |
| $I_{LIM}$   | Boost converter valley current limit     |  | 0.9  | 1.2  | 1.5  | A                |
| $f_{SW}$  | Boost converter switching frequency      |  | 1.35 | 1.80 | 2.25 | MHz              |
| <b>LDO OUTPUT <math>V_{POS}</math></b>                  |  |  |      |      |      |                  |
| $V_{POS}$   | Positive output voltage range            |  | 4.0  |      | 6.0  | V                |
| $V_{POS\_acc}$  | Positive output voltage accuracy         |  | -1 % |      | +1 % |                  |
| $I_{POS}$   | Positive output current capability       |  | 200  |      |      | mA               |
| $V_{DO}$  | Dropout voltage                          | $V_{REG} = V_{POS(NOM)} = 5.4\text{ V}$ , $I_{OUT} = 150\text{ mA}$  |      |      | 160  | mV               |
|   | Line regulation                          | $V_{IN} = 2.5\text{ V}$ to $5.5\text{ V}$ , $I_{OUT} = 40\text{ mA}$ |      |      | 2.7  | mV               |
|   | Load regulation                          | $\Delta I_{OUT} = 80\text{ mA}$                                      |      |      | 3.4  | %/A              |
| $R_D$   | Discharge resistor                       |  |      |      | 70   | $\Omega$         |
| <b>NEGATIVE CHARGE PUMP OUTPUT <math>V_{NEG}</math></b> |  |  |      |      |      |                  |
| $V_{NEG}$   | Negative output voltage range            |  | -6.0 |      | -4.0 | V                |
| $V_{NEG\_acc}$  | Negative output voltage accuracy         |  | -1 % |      | +1 % |                  |
| $I_{NEG}$   | Negative output current capability       | 40mA MODE  | 40   |      |      | mA               |
|   |  | 80mA MODE  | 80   |      |      |                  |
| $I_{NEG}$   | Negative output current capability       | TPS65132Sx, SYNC = HIGH  | 150  |      |      | mA               |
| $f_{OSC}$   | Negative charge pump switching frequency |  | 0.8  | 1.0  | 1.2  | MHz              |
|   | Line regulation                          | $V_{IN} = 2.5\text{ V}$ to $5.5\text{ V}$ , $I_{OUT} = 40\text{ mA}$ |      |      | 3.3  | mV               |
|   | Load regulation                          | $\Delta I_{OUT} = 80\text{ mA}$                                      |      |      | 6.1  | %/A              |
| $R_D$   | Discharge resistor                       |  |      |      | 20   | $\Omega$         |

### 7.6 I<sup>2</sup>C Interface Timing Requirements / Characteristics <sup>(1)</sup>

| PARAMETER           |   | TEST CONDITIONS | MIN                    | TYP | MAX  | UNIT |
|---------------------|---|-----------------|------------------------|-----|------|------|
| f <sub>SCL</sub>    | SCL clock frequency   | Standard mode   |                        |     | 100  | kHz  |
|                     |   | Fast mode       |                        |     | 400  | kHz  |
| t <sub>LOW</sub>    | LOW period of the SCL clock   | Standard mode   | 4.7                    |     |      | μs   |
|                     |   | Fast mode       | 1.3                    |     |      | μs   |
| t <sub>HIGH</sub>   | HIGH period of the SCL clock  | Standard mode   | 4.0                    |     |      | μs   |
|                     |   | Fast mode       | 600                    |     |      | ns   |
| t <sub>BUF</sub>    | Bus free time between a STOP and START condition                                      | Standard mode   | 4.7                    |     |      | μs   |
|                     |   | Fast mode       | 1.3                    |     |      | μs   |
| t <sub>hd;STA</sub> | Hold time for a repeated START condition  | Standard mode   | 4.0                    |     |      | μs   |
|                     |   | Fast mode       | 600                    |     |      | ns   |
| t <sub>su;STA</sub> | Setup time for a repeated START condition   | Standard mode   | 4.7                    |     |      | μs   |
|                     |   | Fast mode       | 600                    |     |      | ns   |
| t <sub>su;DAT</sub> | Data setup time   | Standard mode   | 250                    |     |      | ns   |
|                     |   | Fast mode       | 100                    |     |      | ns   |
| t <sub>hd;DAT</sub> | Data hold time  | Standard mode   | 0.05                   |     | 3.45 | μs   |
|                     |   | Fast mode       | 0.05                   |     | 0.9  | μs   |
| t <sub>RCL1</sub>   | Rise time of SCL signal after a repeated START condition and after an acknowledge bit | Standard mode   | 20 + 0.1C <sub>B</sub> |     | 1000 | ns   |
|                     |   | Fast mode       | 20 + 0.1C <sub>B</sub> |     | 1000 | ns   |
| t <sub>RCL</sub>    | Rise time of SCL signal   | Standard mode   | 20 + 0.1C <sub>B</sub> |     | 1000 | ns   |
|                     |   | Fast mode       | 20 + 0.1C <sub>B</sub> |     | 300  | ns   |
| t <sub>FCL</sub>    | Fall time of SCL signal   | Standard mode   | 20 + 0.1C <sub>B</sub> |     | 300  | ns   |
|                     |   | Fast mode       | 20 + 0.1C <sub>B</sub> |     | 300  | ns   |
| t <sub>RDA</sub>    | Rise time of SDA signal   | Standard mode   | 20 + 0.1C <sub>B</sub> |     | 1000 | ns   |
|                     |   | Fast mode       | 20 + 0.1C <sub>B</sub> |     | 300  | ns   |
| t <sub>FDA</sub>    | Fall time of SDA signal   | Standard mode   | 20 + 0.1C <sub>B</sub> |     | 300  | ns   |
|                     |   | Fast mode       | 20 + 0.1C <sub>B</sub> |     | 300  | ns   |
| t <sub>su;STO</sub> | Setup time for STOP condition   | Standard mode   | 4.0                    |     |      | μs   |
|                     |   | Fast mode       | 600                    |     |      | ns   |
| C <sub>B</sub>      | Capacitive load for SDA and SCL   |                 |                        |     | 0.4  | nF   |

(1) Industry standard I<sup>2</sup>C timing characteristics according to I<sup>2</sup>C-Bus Specification, Version 2.1, January 2000. Not tested in production.

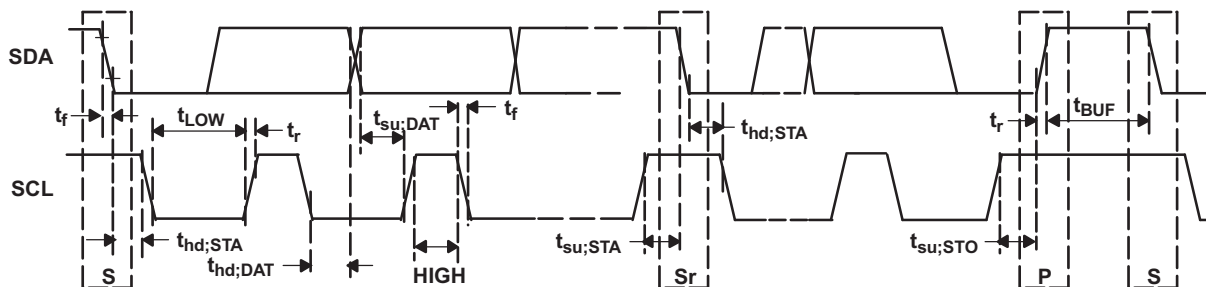


Figure 1. Serial Interface Timing For F/S-Mode

## 7.7 Typical Characteristics

$V_{IN} = 3.7\text{ V}$ ,  $V_{POS} = 5.4\text{ V}$ ,  $V_{NEG} = -5.4\text{ V}$ , unless otherwise noted

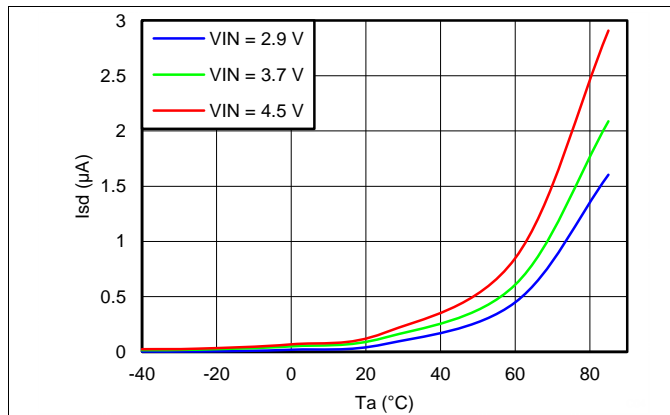


Figure 2. Shutdown Current (all versions but Ax)

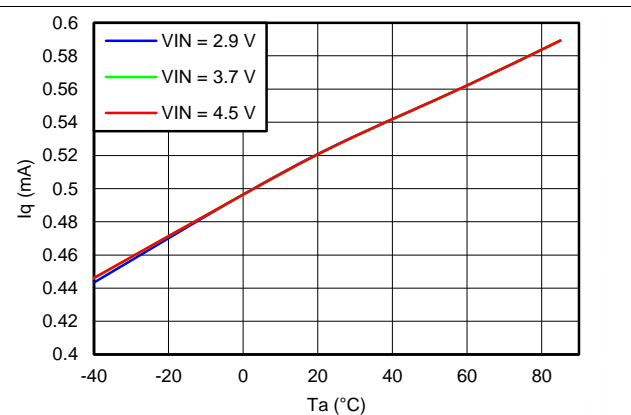


Figure 3. Quiescent Current

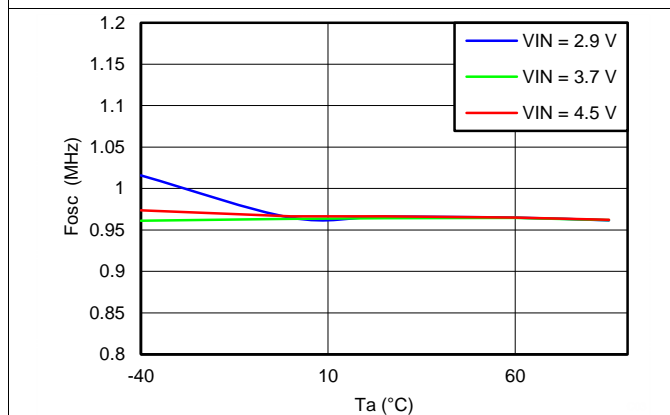


Figure 4. Main Oscillator Frequency

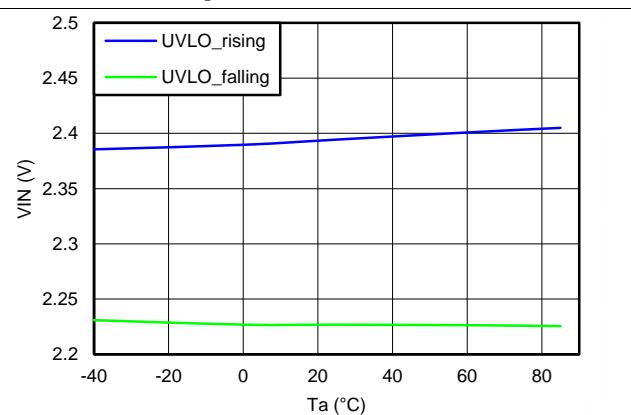


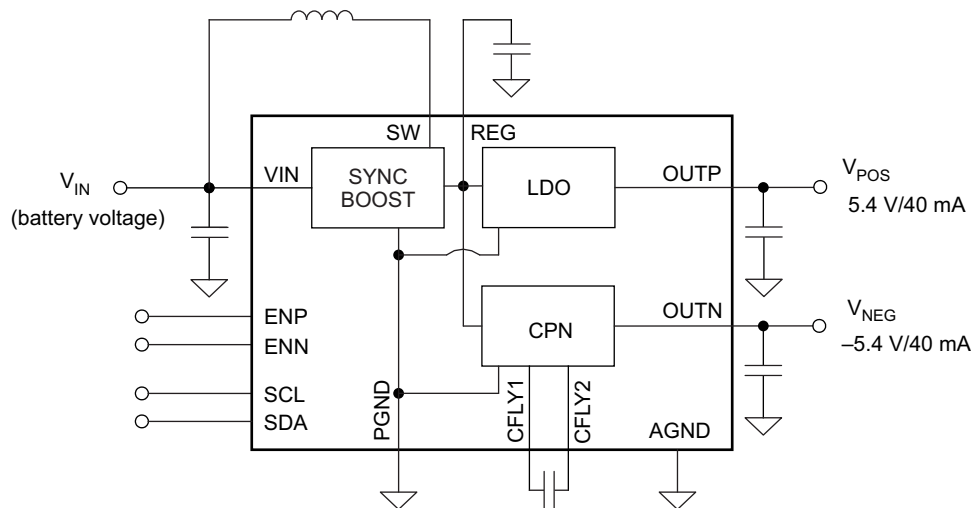
Figure 5. UVLO

## 8 Detailed Description

### 8.1 Overview

The TPS65132, supporting input voltage range from 2.5 V to 5.5 V, operates with a single inductor scheme to provide a high efficiency with a small solution size. The synchronous boost converter generates a positive voltage that is regulated down by an integrated LDO, providing the positive supply rail ( $V_{POS}$ ). The negative supply rail ( $V_{NEG}$ ) is generated by an integrated negative charge pump (or CPN) driven from the boost converter output pin, REG. The operating mode can be selected between 40mA and 80mA in order to select the necessary output current capability and to get the best efficiency possible based on the application. The device topology allows a 100% asymmetry of the output currents.

### 8.2 Functional Block Diagram



### 8.3 Feature Description

#### 8.3.1 Undervoltage Lockout (UVLO)

The TPS65132 integrates an undervoltage lockout block (UVLO) that enables the device once the voltage on the VIN pin exceeds the UVLO threshold (2.5 V maximum). No output voltage will be generated as long as the enable signals are not pulled HIGH. The device, as well as all converters (boost converter, LDO, CPN), will be disabled as soon as the  $V_{IN}$  voltage falls below the UVLO threshold. The UVLO threshold is designed in a way that the TPS65132 will continue operating as long as  $V_{IN}$  stays above 2.3 V. This guarantees a proper operation even in the event of extensive line transients when the battery gets suddenly heavily loaded.

For TPS65132Ax, a 40 ms delay is starting as soon as the UVLO threshold is reached. This delay prevents the device to be disabled and enabled by an unwanted VIN voltage spike. Once this delay has passed, the output rails can be enabled and disabled as desired with the enable signals without any delay.

#### 8.3.2 Active Discharge

An active discharge of the positive rail and/or the negative rail can be programmed (DISP and DISN bits respectively - refer to [Registers](#)). If programmed to be active, the discharge will occur at power down, when the enable signals go LOW ([Figure 37](#) and [Figure 38](#) for TPS65132Ax, Bx, Lx, Tx, Wx — [Figure 105](#) and [Figure 104](#) for TPS65132Sx). See [Power-Down And Discharge \(LDO\)](#) and [Power-Down And Discharge \(CPN\)](#) for a detailed description of how each device variant implements the active discharge function.

## Feature Description (continued)

### 8.3.3 Boost Converter

#### 8.3.3.1 Boost Converter Operation

The synchronous boost converter uses a current mode topology and operates at a quasi-fixed frequency of typically 1.8 MHz, allowing chip inductors such as 2.2  $\mu\text{H}$  or 4.7  $\mu\text{H}$  to be used. The converter is internally compensated and provides a regulated output voltage automatically adjusted depending on the programmed  $V_{\text{POS}}$  and  $V_{\text{NEG}}$  voltages. The boost converter operates either in continuous conduction mode (CCM) or Pulse Frequency Modulation mode (PFM), depending on the load current in order to provide the highest efficiency possible. The switch node waveforms for CCM and DCM operation are shown in [Figure 6](#) and [Figure 7](#).

#### 8.3.3.2 Power-Up And Soft-Start (Boost Converter)

The boost converter starts switching as soon as one enable signal is pulled HIGH and the voltage on  $V_{\text{IN}}$  pin is above the UVLO threshold. For TPS65132Ax, in the case where one enable signal is already HIGH when  $V_{\text{IN}}$  reaches the UVLO threshold, the boost converter will only start switching after a 40 ms delay has passed (see [Undervoltage Lockout \(UVLO\)](#)).

The boost converter starts up with an integrated soft-start to avoid drawing excessive inrush current from the supply. The output voltage  $V_{\text{REG}}$  is slowly ramped up to its target value. Typical startup waveforms for low-current applications are shown in [Figure 33](#) and [Figure 35](#).

#### 8.3.3.3 Power-Down (Boost Converter)

The boost converter stops switching when  $V_{\text{IN}}$  is below the UVLO threshold or when both output rails are disabled. For example, due to a special sequencing, the LDO might still be operating while the CPN is already disabled, in which case, the boost will continue operating until the LDO has been disabled. Typical power-down waveforms for low-current applications are shown in [Figure 34](#) and [Figure 36](#).

#### 8.3.3.4 Isolation (Boost Converter)

The boost converter output (REG) is isolated from the input supply  $V_{\text{IN}}$ , providing a true shutdown.

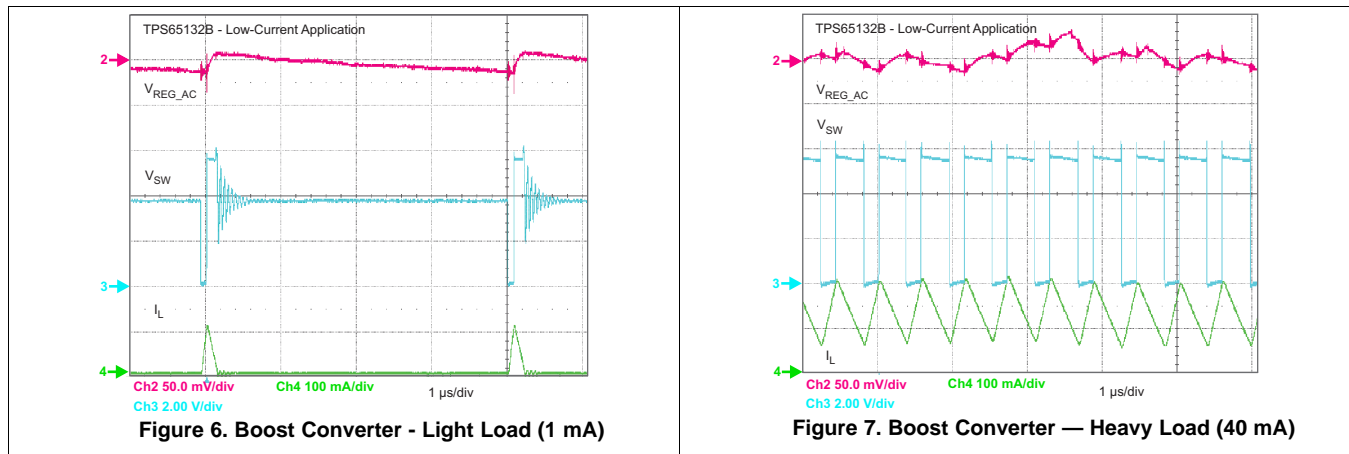
#### 8.3.3.5 Output Voltage (Boost Converter)

The output voltage of the boost converter is automatically adjusted depending on the programmed  $V_{\text{POS}}$  and  $V_{\text{NEG}}$  voltages.

#### 8.3.3.6 Advanced Power-Save Mode For Light-Load Efficiency And PFM

The TPS65132 device integrates a power save mode to improve efficiency at light load. In power save mode the converter stops switching when the inductor current reaches 0 A. The device resumes its switching activity with one or more pulses once the  $V_{\text{REG}}$  voltage falls below its regulation level, and goes again into power save mode once the inductor current reaches 0 A. The pulse duration remains constant, but the frequency of these pulses varies according to the output load. This operating mode is also known as Pulse Frequency Modulation or PFM. [Figure 6](#) provides plots of the inductor current and the switch node in PFM mode.

**Feature Description (continued)**



**8.3.4 LDO Regulator**

**8.3.4.1 LDO Operation**

The Low Dropout regulator (or LDO) generates the positive voltage rail,  $V_{POS}$ , by regulating down the output voltage of the boost converter ( $V_{REG}$ ). Its inherent power supply rejection helps filtering the output ripple of the boost converter in order to provide on OOTP pin a clean voltage, e.g. to supply the source driver IC of the display.

**8.3.4.2 Power-Up And Soft-Start (LDO)**

The LDO starts operating as soon as the ENP signal is pulled HIGH,  $V_{IN}$  voltage is above the UVLO threshold and the boost converter has reached its Power Good threshold.

In the case where the enable signal is already HIGH when  $V_{IN}$  exceeds the UVLO threshold, the boost converter will start first and the LDO will only start after the boost converter has reached its target voltage. For TPS65132Ax, the boost will start after the 40 ms delay has passed (see [Undervoltage Lockout \(UVLO\)](#)).

For TPS65132Sx the LDO startup is defined by the setting of the DLYx register and the SEQU bits, see [Registers](#) for more details.

The LDO integrates a soft-start that slowly ramps up its output voltage  $V_{POS}$  regardless of the output capacitor and the target voltage, as long as the LDO current limit is not reached. For TPS65132Ax and TPS65132Bx (except TPS65132B2), the typical startup time is 140  $\mu$ s. For TPS65132B2, TPS65132Lx, TPS65132Sx, TPS65132Tx and TPS65132Wx, the typical ramp-up time is 500  $\mu$ s and the inrush current is also reduced by a factor of 3. Typical startup waveforms for the low-current application are shown in [Figure 33](#) to [Figure 35](#).

**8.3.4.3 Power-Down And Discharge (LDO)**

The LDO stops operating when  $V_{IN}$  is below the UVLO threshold or when ENP is pulled LOW. Or for TPS65132Sx when EN is pulled LOW, and the internal sequencing has passed.

The positive rail can be actively discharged to GND during power-down if required. A discharge selection bit is available to enable or disable this function. See [Registers](#) for more details, as well as waveforms in [Figure 37](#) and [Figure 38](#). [Table 1](#) shows the  $V_{POS}$  active discharge behavior of each device variant.

**Table 1.  $V_{POS}$  Active Discharge Behavior**

| PART NUMBER | $V_{IN}$     | ENP (or EN) | ENN (or SYNC) | $V_{POS}$ DISCHARGE    |
|-------------|--------------|-------------|---------------|------------------------|
| TPS65132Ax  | $< V_{UVLO}$ | Don't Care  | Don't Care    | On                     |
|             |              | Low         | Low           | Determined by DISP bit |
|             | $> V_{UVLO}$ | Low         | High          | Determined by DISP bit |
|             |              | High        | Low           | Off                    |
|             |              | High        | High          | Off                    |

**Feature Description (continued)**
**Table 1. V<sub>POS</sub> Active Discharge Behavior (continued)**

| PART NUMBER  | V <sub>IN</sub>     | ENP (or EN) | ENN (or SYNC) | V <sub>POS</sub> DISCHARGE |
|--|---------------------|-------------|---------------|----------------------------|
| TPS65132Bx<br>TPS65132Lx<br>TPS65132Sx<br>TPS65132Tx<br>TPS65132Wx | < V <sub>UVLO</sub> | Don't Care  | Don't Care    | On                         |
|  | > V <sub>UVLO</sub> | Low         | Low           | On                         |
|  |                     | Low         | High          | Determined by DISP bit     |
|  |                     | High        | Low           | Off                        |
|  |                     | High        | High          | Off                        |

**8.3.4.4 Isolation (LDO)**

The LDO is isolating the V<sub>POS</sub> rail from V<sub>REG</sub> (boost converter output) as long as the rail is not enabled in order to ensure flexible startup like V<sub>NEG</sub> before V<sub>POS</sub>.

**8.3.4.5 Setting The Output Voltage (LDO)**

The output voltage of the LDO is programmable via a I<sup>2</sup>C compatible interface, from –6.0 V to –4.0 V in 100 mV steps. For more details, please refer to the [VPOS Register – Address: 0x00](#)

**8.3.5 Negative Charge Pump**
**8.3.5.1 Operation**

The negative charge pump (CPN) generates the negative voltage rail, V<sub>NEG</sub>, by inverting and regulating the output voltage of the boost converter (V<sub>REG</sub>). The charge pump uses 4 switches and an external flying capacitor to generate the negative rail. Two of the switches are turned on in the first phase to charge the flying capacitor up to V<sub>REG</sub>, and in the second phase they are turned-off and the two others turn on to pump the energy negatively out of the OUTN capacitor.

**8.3.5.2 Power-Up And Soft-Start (CPN)**

The CPN starts operating as soon as the ENN signal is pulled HIGH, V<sub>IN</sub> voltage is above the UVLO threshold and the boost converter has reached its Power Good threshold.

In the case where the enable signal is already HIGH when V<sub>IN</sub> reaches the UVLO threshold, the boost converter will start first and the CPN will only start after the boost converter has reached its target voltage. For TPS65132Ax, the boost will start after the 40 ms delay has passed (see [Undervoltage Lockout \(UVLO\)](#)).

For TPS65132Sx the CPN startup is defined by the setting of the DLYx register and the SEQU bits, see [Registers](#) for more details.

The CPN integrates a soft-start that slowly ramps up its output voltage V<sub>NEG</sub> within a time defined by the selected mode (40mA or 80mA), the output voltage and the output capacitor value. For TPS65132Ax and TPS65132Bx (except TPS65132B2), the startup current charging the output capacitor in 40mA mode is 50 mA, and 100 mA typically in 80mA mode. For TPS65132B2, TPS65132Lx, TPS65132Tx, and TPS65132Wx, the typical ramp-up times are slowed down by a factor of 4 (i.e 12.5 mA and 25 mA typical output current for 40mA and 80mA modes respectively) and the inrush current is also reduced by a factor of about 4. Typical startup waveforms for the low-current application are shown in [Figure 39](#) to [Figure 42](#).

For TPS65132Sx, the negative rail starts-up in 40mA or 80mA mode, thus the startup current is set by the mode the device is programmed to, and not related to the SYNC pin state. The full current of 150 mA minimum is only released once both rails (V<sub>POS</sub> and V<sub>NEG</sub>) have reached their Power Good levels.

The estimated startup time can be calculated using the following formula:

$$t_{\text{STARTUP}} = \frac{C_{\text{OUT}} \times V_{\text{NEG}}}{I_{\text{STARTUP}}}$$

Where:

- t<sub>STARTUP</sub> = startup time of the V<sub>NEG</sub> rail
- C<sub>OUT</sub> = output capacitance of the V<sub>NEG</sub> rail
- V<sub>NEG</sub> = target output voltage

$I_{\text{STARTUP}}$  = output current of the  $V_{\text{NEG}}$  rail charging up the output capacitor at startup (12.5 mA, 25 mA, 50 mA or 100 mA as described above)

### 8.3.5.3 Power-Down And Discharge (CPN)

The CPN stops operating when  $V_{\text{IN}}$  is below the UVLO threshold or when ENN is pulled LOW.

Or when EN is pulled LOW in the TPS65132Sx, and the internal sequencing has passed.

The negative rail can be actively discharged to GND during power-down if required. A discharge selection bit is available to enable or disable this function. See for more details, as well as waveforms [Figure 37](#) and [Figure 38](#). [Table 2](#) shows the  $V_{\text{NEG}}$  discharge behavior of each device variant.

**Table 2.  $V_{\text{NEG}}$  Active Discharge Behavior**

| PART NUMBER  | $V_{\text{IN}}$     | ENP (or EN) | ENN (or SYNC) | $V_{\text{NEG}}$ DISCHARGE |
|--|---------------------|-------------|---------------|----------------------------|
| TPS65132Ax   | $< V_{\text{UVLO}}$ | Don't Care  | Don't Care    | On                         |
|  | $> V_{\text{UVLO}}$ | Low         | Low           | Determined by DISN bit     |
|  |                     | Low         | High          | Off                        |
|  |                     | High        | Low           | Determined by DISN bit     |
|  |                     | High        | High          | Off                        |
| TPS65132Bx<br>TPS65132Lx<br>TPS65132Tx<br>TPS65132Wx | $< V_{\text{UVLO}}$ | Don't Care  | Don't Care    | On                         |
|  | $> V_{\text{UVLO}}$ | Low         | Low           | On                         |
|  |                     | Low         | High          | Off                        |
|  |                     | High        | Low           | Determined by DISN bit     |
|  |                     | High        | High          | Off                        |
| TPS65132Sx   | $< V_{\text{UVLO}}$ | Don't Care  | Don't Care    | On                         |
|  | $> V_{\text{UVLO}}$ | Low         | Low           | On                         |
|  |                     | Low         | High          | Determined by DISN bit     |
|  |                     | High        | Low           | Off                        |
|  |                     | High        | High          | Off                        |

### 8.3.5.4 Isolation (CPN)

The CPN isolates the  $V_{\text{NEG}}$  rail from  $V_{\text{REG}}$  (boost converter output) as long as the rail is not enabled in order to ensure flexible startup like  $V_{\text{POS}}$  before  $V_{\text{NEG}}$ .

### 8.3.5.5 Setting The Output Voltage (CPN)

The output voltage of the CPN is programmable via a I<sup>2</sup>C compatible interface, from –4.0 V to –6.0 V in 100 mV steps. For more details, please refer to the [VNEG Register – Address 0x01](#).

## 8.4 Device Functional Modes

### 8.4.1 Enabling and Disabling the Device

At startup ( $V_{\text{IN}}$  goes above UVLO and at least one of the enable pins (ENP, ENN, or EN) goes HIGH), the EEPROM content is loaded into the DAC registers and the IC starts with these default values. The TPS65132 is enabled as long as the  $V_{\text{IN}}$  voltage is above the UVLO and one of the enable pins (ENP, ENN, or EN) is HIGH.

Pulling ENP or ENN LOW disables either rail ( $V_{\text{POS}}$  or  $V_{\text{NEG}}$  respectively); and, pulling both pins LOW disables the device entirely (the internal oscillator of the TPS65132Ax continues running to allow access to the I<sup>2</sup>C interface).

For TPS65132Sx, pulling EN LOW disables the device.



## 8.5 Programming

### 8.5.1 I<sup>2</sup>C Serial Interface Description

The TPS65132 communicates through an industry standard I<sup>2</sup>C compatible interface, to receive data in slave mode. I<sup>2</sup>C is a 2-wire serial interface developed by Philips Semiconductor (see I<sup>2</sup>C-Bus Specification, Version 2.1, January 2000).

The TPS65132 integrates a non-volatile memory (EEPROM) that allows the storage of the register values with a capability of up to 1000 programming cycles. At startup the TPS65132 loads first the EEPROM content into the registers and uses these voltages to start.

It is recommended to stop I<sup>2</sup>C communication with the TPS65132 for 50 ms after the command "Write EEPROM data" was sent. If the device is accessed via I<sup>2</sup>C during EEPROM programming, the device will pull down the SCL line (clock stretch) after it recognized its I<sup>2</sup>C address. The SCL line will be released after EEPROM programming is finished.

The TPS65132 works as a slave and supports the following data transfer modes, as defined in the I<sup>2</sup>C-Bus specification: standard mode (100 kbps) and fast mode (400 kbps). The data transfer protocol for standard and fast modes is exactly the same, therefore they are referred to as F/S-mode in this document. The TPS65132 supports 7-bit addressing. The device 7-bit address is 3E (see Figure 8), and the LSB enables the write or read function.

Figure 8. TPS65132 Slave Address Byte

| MSB                  |   | TPS65132 |   |   |   | Address |   | LSB          |
|----------------------|---|----------|---|---|---|---------|---|--------------|
| 0                    | 1 | 1        | 1 | 1 | 1 | 1       | 0 | R/ $\bar{W}$ |
| R/ $\bar{W}$ = R/(W) |   |          |   |   |   |         |   |              |

#### NOTE

With TPS65132Ax, the I<sup>2</sup>C interface is accessible as long as the input voltage is above the undervoltage lockout threshold. In all other versions, the I<sup>2</sup>C interface is accessible only as soon as one of the enable pins is pulled HIGH while the input voltage is above the undervoltage lockout.

### 8.5.2 I<sup>2</sup>C Interface Protocol

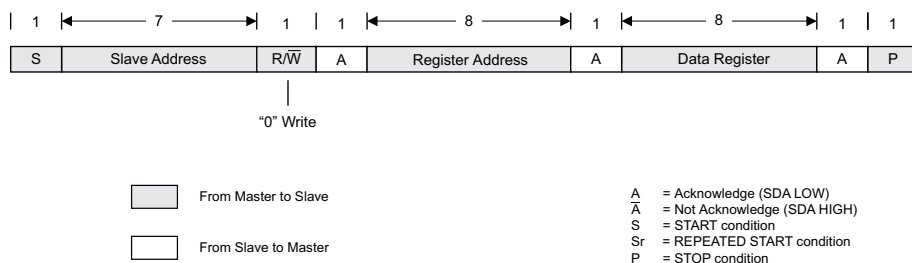
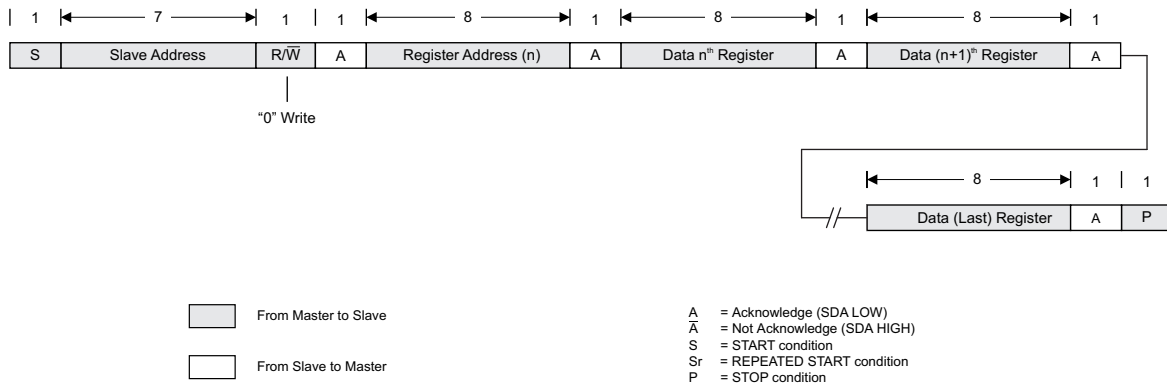
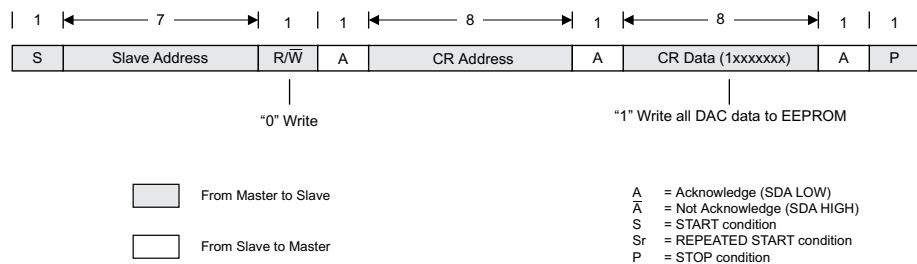


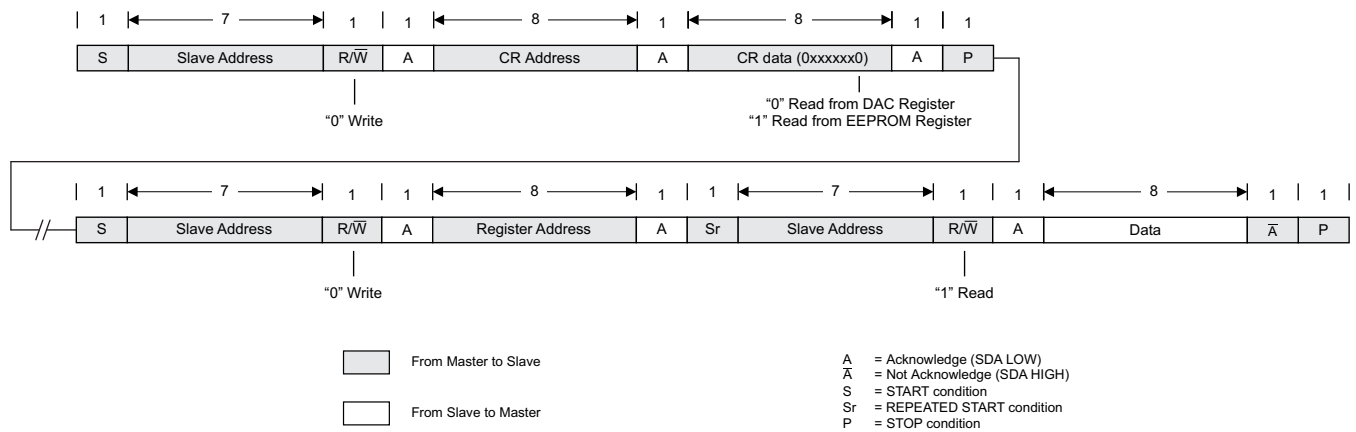
Figure 9. "Write" Data To DAC – Transfer Format In F/S-Mode



**Figure 10. "Write" Data To DAC – Transfer Format In F/S-Mode Featuring Register Address Auto-Increment**



**Figure 11. "Write" Data To EEPROM – Transfer Format In F/S-Mode**



**Figure 12. "Read" Data From DAC/EEPROM – Transfer Format In F/S-Mode**

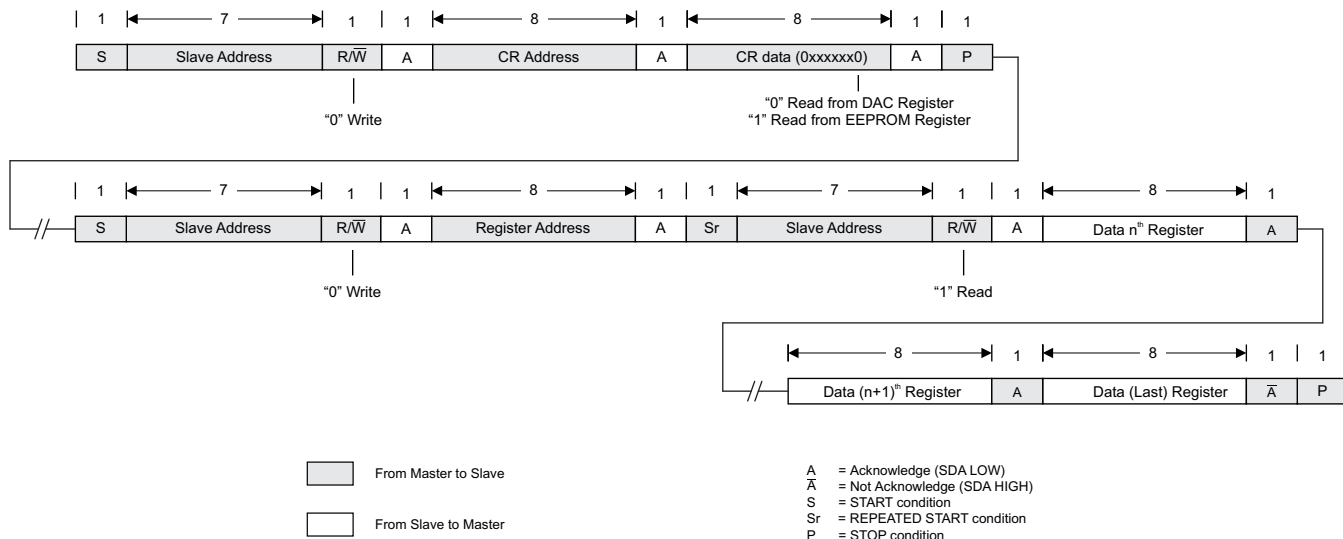


Figure 13. “Read” Data From DAC/EEPROM – Transfer Format In F/S-Mode Featuring Register Address Auto-Increment

## 8.6 Register Maps

The TPS65132 has a non-volatile memory (EEPROM) which contains the initial values and one volatile memory (Registers) which contains the actual settings. The EEPROM and the Registers are accessed with the same address.

**Startup option:** At power-up, the values contained in the EEPROM are loaded into the Registers to the last stored setting within less than 20  $\mu$ s. The programmed factory value of the EEPROM of each address is described in section [Factory Default Register Value](#).

**Write description:** The user has to program all Registers first (0x00 to 0x03), then set the WED (Write EEPROM Data) bit to 1. A dead time of 50 ms is then initiated during which the register content or all registers (0x00 ~ 0x03) are stored into the non-volatile EEPROM cells. During that time, there should be no data flowing through the I<sup>2</sup>C because the I<sup>2</sup>C interface is momentarily not responding.

After the 50 ms have passed, the WED bit is automatically reset to 0, and the user is able to read the values or program again.

**Slave address:** 0x3E

X = R/W            R/W = 1 → read mode

                      R/W = 0 → write mode

### 8.6.1 Registers

Attempting to read data from register addresses not listed in the following section will result in 0x00 being read out.

#### 8.6.1.1 VPOS Register – Address: 0x00

Figure 14. VPOS Register

| 7    | 6    | 5    | 4         | 3 | 2 | 1 | 0 |
|------|------|------|-----------|---|---|---|---|
| RSVD | RSVD | RSVD | VPOS[4:0] |   |   |   |   |
| 0    | 0    | 0    | 0         | 1 | 1 | 1 | 0 |
| R    |      |      | R/W       |   |   |   |   |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 3. VPOS Register Field Descriptions**

| Bit | Field     | Description                     |                                |                                 |                                |
|-----|-----------|---------------------------------|--------------------------------|---------------------------------|--------------------------------|
| 7:5 | RSVD[2:0] | Reserved, always set to 0       |                                |                                 |                                |
| 4:0 | VPOS[4:0] | VPOS output voltage adjustment  |                                |                                 |                                |
|     |           | <b>VPOS[4:0] Value (binary)</b> | <b>VPOS Output Voltage (V)</b> | <b>VPOS[4:0] Value (binary)</b> | <b>VPOS Output Voltage (V)</b> |
|     |           | 00000                           | 4.0                            | 01011                           | 5.1                            |
|     |           | 00001                           | 4.1                            | 01100                           | 5.2                            |
|     |           | 00010                           | 4.2                            | 01101                           | 5.3                            |
|     |           | 00011                           | 4.3                            | 01110                           | 5.4                            |
|     |           | 00100                           | 4.4                            | 01111                           | 5.5                            |
|     |           | 00101                           | 4.5                            | 10000                           | 5.6                            |
|     |           | 00110                           | 4.6                            | 10001                           | 5.7                            |
|     |           | 00111                           | 4.7                            | 10010                           | 5.8                            |
|     |           | 01000                           | 4.8                            | 10011                           | 5.9                            |
|     |           | 01001                           | 4.9                            | 10100                           | 6.0                            |
|     |           | 01010                           | 5.0                            |                                 |                                |

**8.6.1.2 VNEG Register – Address 0x01**
**Figure 15. VNEG Register**

|      |      |      |           |   |   |   |   |
|------|------|------|-----------|---|---|---|---|
| 7    | 6    | 5    | 4         | 3 | 2 | 1 | 0 |
| RSVD | RSVD | RSVD | VNEG[4:0] |   |   |   |   |
| 0    | 0    | 0    | 0         | 1 | 1 | 1 | 0 |
| R    |      |      | R/W       |   |   |   |   |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 4. VNEG Register Field Descriptions**

| Bit   | Field     | Description  |                          |                          |                          |                         |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |  |  |
|-------|-----------|--|--------------------------|--------------------------|--------------------------|-------------------------|-------|------|-------|------|-------|------|-------|------|-------|------|-------|------|-------|------|-------|------|-------|------|-------|------|-------|------|-------|------|-------|------|-------|------|-------|------|-------|------|-------|------|-------|------|-------|------|-------|------|-------|------|--|--|
| 7:5   | RSVD[2:0] | Reserved, always set to 0  |                          |                          |                          |                         |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |  |  |
| 4:0   | VNEG[4:0] | VNEG output voltage adjustment   |                          |                          |                          |                         |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |  |  |
|       |           | <table border="1"> <thead> <tr> <th>VNEG[4:0] Value (binary)</th> <th>VNEG Output Voltage (V)</th> <th>VNEG[4:0] Value (binary)</th> <th>VNEG Output Voltage (V)</th> </tr> </thead> <tbody> <tr> <td>00000</td> <td>-4.0</td> <td>01011</td> <td>-5.1</td> </tr> <tr> <td>00001</td> <td>-4.1</td> <td>01100</td> <td>-5.2</td> </tr> <tr> <td>00010</td> <td>-4.2</td> <td>01101</td> <td>-5.3</td> </tr> <tr> <td>00011</td> <td>-4.3</td> <td>01110</td> <td>-5.4</td> </tr> <tr> <td>00100</td> <td>-4.4</td> <td>01111</td> <td>-5.5</td> </tr> <tr> <td>00101</td> <td>-4.5</td> <td>10000</td> <td>-5.6</td> </tr> <tr> <td>00110</td> <td>-4.6</td> <td>10001</td> <td>-5.7</td> </tr> <tr> <td>00111</td> <td>-4.7</td> <td>10010</td> <td>-5.8</td> </tr> <tr> <td>01000</td> <td>-4.8</td> <td>10011</td> <td>-5.9</td> </tr> <tr> <td>01001</td> <td>-4.9</td> <td>10100</td> <td>-6.0</td> </tr> <tr> <td>01010</td> <td>-5.0</td> <td></td> <td></td> </tr> </tbody> </table> | VNEG[4:0] Value (binary) | VNEG Output Voltage (V)  | VNEG[4:0] Value (binary) | VNEG Output Voltage (V) | 00000 | -4.0 | 01011 | -5.1 | 00001 | -4.1 | 01100 | -5.2 | 00010 | -4.2 | 01101 | -5.3 | 00011 | -4.3 | 01110 | -5.4 | 00100 | -4.4 | 01111 | -5.5 | 00101 | -4.5 | 10000 | -5.6 | 00110 | -4.6 | 10001 | -5.7 | 00111 | -4.7 | 10010 | -5.8 | 01000 | -4.8 | 10011 | -5.9 | 01001 | -4.9 | 10100 | -6.0 | 01010 | -5.0 |  |  |
|       |           | VNEG[4:0] Value (binary)   | VNEG Output Voltage (V)  | VNEG[4:0] Value (binary) | VNEG Output Voltage (V)  |                         |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |  |  |
|       |           | 00000  | -4.0                     | 01011                    | -5.1                     |                         |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |  |  |
|       |           | 00001  | -4.1                     | 01100                    | -5.2                     |                         |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |  |  |
|       |           | 00010  | -4.2                     | 01101                    | -5.3                     |                         |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |  |  |
|       |           | 00011  | -4.3                     | 01110                    | -5.4                     |                         |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |  |  |
|       |           | 00100  | -4.4                     | 01111                    | -5.5                     |                         |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |  |  |
|       |           | 00101  | -4.5                     | 10000                    | -5.6                     |                         |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |  |  |
|       |           | 00110  | -4.6                     | 10001                    | -5.7                     |                         |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |  |  |
|       |           | 00111  | -4.7                     | 10010                    | -5.8                     |                         |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |  |  |
|       |           | 01000  | -4.8                     | 10011                    | -5.9                     |                         |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |  |  |
|       |           | 01001  | -4.9                     | 10100                    | -6.0                     |                         |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |  |  |
| 01010 | -5.0      |  |                          |                          |                          |                         |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |       |      |  |  |

**8.6.1.3 DLYx Register – Address 0x02 (Only valid for TPS65132Sx)**
**Figure 16. DLYx Register**

| 7     | 6     | 5     | 4     | 3     | 2     | 1     | 0     |
|-------|-------|-------|-------|-------|-------|-------|-------|
| DLYP2 | DLYP2 | DLYN2 | DLYN2 | DLYP1 | DLYP1 | DLYN1 | DLYN1 |
| 0     | 0     | 0     | 0     | 0     | 0     | 0     | 1     |
| R/W   |       |       |       |       |       |       |       |

**Table 5. DLYx Register Field Descriptions**

| Bit | Field      | Description                |                        |
|-----|------------|----------------------------|------------------------|
| 7:6 | DLYP2[1:0] | Delay in milliseconds      |                        |
| 5:4 | DLYN2[1:0] |                            |                        |
| 3:2 | DLYP1[1:0] |                            |                        |
| 1:0 | DLYN1[1:0] |                            |                        |
|     | DLYx[1:0]  | <b>DLYx Value (binary)</b> | <b>DLYx Delay (ms)</b> |
|     |            | 00                         | 0                      |
|     |            | 01                         | 1                      |
|     |            | 10                         | 5                      |
|     |            | 11                         | 10                     |

**8.6.1.4 APPS - SEQU - SEQD - DISP - DISN Register – Address 0x03**
**Figure 17. APPS - SEQU - SEQD - DISP - DISN Register**

| 7    | 6    | 5    | 4    | 3    | 2    | 1    | 0    |
|------|------|------|------|------|------|------|------|
| RSVD | APPS | SEQU | SEQU | SEQD | SEQD | DISP | DISN |
| 0    | 0    | 0    | 0    | 0    | 0    | 1    | 0    |
| R    | R/W  | R/W  | R/W  | R/W  | R/W  | R/W  | R/W  |

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

**Table 6. APPS - SEQU - SEQD - DISP - DISN Field Descriptions**

| Bit | Field               | Description                | Value (binary) | Action |   |
|-----|---------------------|----------------------------|----------------|--------|---|
| 7   | RSVD                | Reserved, always set to 0  |                |        |   |
| 6   | APPS                | Application                | APPS Value     | 0      | 40mA  |
|     |                     |                            |                | 1      | 80mA  |
| 5:4 | SEQU <sup>(1)</sup> | Sequencing at Startup      | SEQU Value     | 00     | V <sub>POS</sub> and V <sub>NEG</sub> simultaneously (DLYP1 after EN goes HIGH)                       |
|     |                     |                            |                | 01     | V <sub>POS</sub> (DLYP1 after EN goes HIGH) and then V <sub>NEG</sub> (DLYN1 after V <sub>POS</sub> ) |
|     |                     |                            |                | 10     | V <sub>NEG</sub> (DLYN1 after EN goes HIGH) and then V <sub>POS</sub> (DLYP1 after V <sub>NEG</sub> ) |
|     |                     |                            |                | 11     | V <sub>POS</sub> only   |
| 3:2 | SEQD <sup>(1)</sup> | Sequencing at Shutdown     | SEQD Value     | 00     | V <sub>POS</sub> and V <sub>NEG</sub> simultaneously (DLYP2 after EN goes LOW)                        |
|     |                     |                            |                | 01     | V <sub>POS</sub> (DLYP2 after EN goes LOW) and then V <sub>NEG</sub> (DLYN2 after V <sub>POS</sub> )  |
|     |                     |                            |                | 10     | V <sub>NEG</sub> (DLYN2 after EN goes LOW) and then V <sub>POS</sub> (DLYP2 after V <sub>NEG</sub> )  |
|     |                     |                            |                | 11     | Ignored   |
| 1   | DISP <sup>(2)</sup> | Discharge V <sub>POS</sub> | DISP Value     | 0      | No discharge  |
|     |                     |                            |                | 1      | V <sub>POS</sub> actively discharged  |
| 0   | DISN <sup>(2)</sup> | Discharge V <sub>NEG</sub> | DISN Value     | 0      | No discharge  |
|     |                     |                            |                | 1      | V <sub>NEG</sub> actively discharged  |

(1) SEQU and SEQD bits are just valid for TPS65132Sx

(2) See [Power-Down And Discharge \(LDO\)](#) and [Power-Down And Discharge \(CPN\)](#) for a detailed description of how each device variant implements the active discharge function.

**8.6.1.5 Control Register – Address 0xFF**
**Figure 18. Control Register**

|     |           |   |   |   |   |   |         |
|-----|-----------|---|---|---|---|---|---------|
| 7   | 6         | 5 | 4 | 3 | 2 | 1 | 0       |
| WED | RSVD[6:1] |   |   |   |   |   | EE/(DR) |

The **Reserved** bits are ignored when written and return either 0 or 1 when read.

**Table 7. Control Register Field Descriptions**

| Bit | Field     | Value (binary) | Description         |
|-----|-----------|----------------|---------------------|
| 7   | WED       | 0              | No action           |
|     |           | 1              | Write EEPROM Data   |
| 6:1 | RSVD[6:1] | Reserved       |                     |
| 0   | EE/(DR)   | 0              | Read from Registers |
|     |           | 1              | Read from EEPROM    |



### 8.6.2 Factory Default Register Value

| Part number               | Register address |       |      |      |
|---------------------------|------------------|-------|------|------|
|                           | 0x00             | 0x01  | 0x02 | 0x03 |
| TPS65132A                 | 0x0E             | 0x0E  | —    | 0x03 |
| TPS65132A0                | 0x0A             | 0x0A  | —    | 0x03 |
| TPS65132B                 | 0x0E             | 0x0E  | —    | 0x03 |
| TPS65132B0                | 0x0A             | 0x0A  | —    | 0x03 |
| TPS65132B2                | 0x0C             | 0x0C  | —    | 0x03 |
| TPS65132B5                | 0x0F             | 0x0F  | —    | 0x03 |
| TPS65132L                 | 0x0E             | 0x0E  | —    | 0x03 |
| TPS65132L0                | 0x0A             | 0x0A  | —    | 0x03 |
| TPS65132L1 <sup>(1)</sup> | 0x0B             | 0x0B  | —    | 0x03 |
| TPS65132S                 | 0x0E             | 0x0E  | 0x00 | 0x43 |
| TPS65132T6                | 0x10h            | 0x10h | —    | 0x43 |
| TPS65132W                 | 0x0E             | 0x0E  | —    | 0x43 |

(1) Product preview.

## 9 Application and Implementation

### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

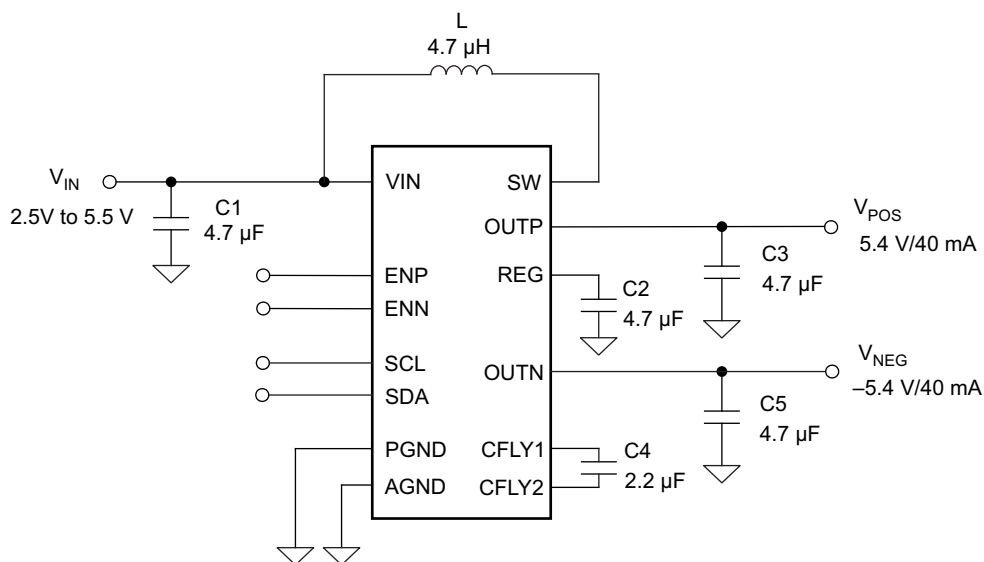
### 9.1 Application Information

The TPS65132xx devices, primarily intended to supplying TFT LCD displays, can be used for any application that requires positive and negative supplies, ranging from  $\pm 4$  V to  $\pm 6$  V and current up to 80 mA (150 mA for the TPS65132Sx version). Both output voltages can be set independently and their sequencing is also independent. The following section presents the different operating modes that the device can support as well as the different features that the user can select.

### 9.2 Typical Applications

#### 9.2.1 Low-current Applications ( $\leq 40$ mA)

The TPS65132 can be programmed to 40mA mode with the APPS bit to support applications that require output currents up to 40 mA (refer to [Figure 17](#)). The 40mA mode limits the negative charge pump output current to 40 mA DC in order to provide the highest efficiency possible. The  $V_{POS}$  rail can deliver up to 200 mA DC regardless of the mode. Output peak currents are supported by the output capacitors.



**Figure 19. Typical Low-current Application Circuit**

#### 9.2.1.1 Design Requirements

**Table 8. Design Parameters**

| PARAMETERS                               | EXAMPLE VALUES                   |
|--|----------------------------------|
| Input Voltage Range                      | 2.5 V to 5.5 V                   |
| Output Voltages                          | 4.0 V to 6.0 V, -4.0 V to -6.0 V |
| Output Current Rating                    | 40 mA                            |
| Boost Converter Switching Frequency      | 1.8 MHz                          |
| Negative Charge Pump Switching Frequency | 1.0 MHz                          |

## 9.2.1.2 Detailed Design Procedure

### 9.2.1.2.1 Sequencing

Each output rail ( $V_{POS}$  and  $V_{NEG}$ ) is enabled and disabled using an external enable signal. If not explicitly specified, the enable signal in the rest of the document refers to ENN or ENP: ENP for the positive rail  $V_{POS}$  and ENN for the negative rail  $V_{NEG}$ . [Figure 33](#) to [Figure 36](#) show the typical sequencing waveforms.

#### NOTE

In the case where  $V_{IN}$  falls below the UVLO threshold while one of the enable signals is still high, all converters will be shut down instantaneously and both  $V_{POS}$  and  $V_{NEG}$  output rails will be actively discharged to GND.

### 9.2.1.2.2 Boost Converter Design Procedure

The first step in the design procedure is to verify whether the maximum possible output current of the boost converter supports the specific application requirements. A simple approach is to estimate the converter efficiency, by taking the efficiency number from the provided efficiency curves at the application's maximum load or to use a worst case assumption for the expected efficiency, e.g., 85%.

1. Duty Cycle:  $D = 1 - \frac{V_{IN\_min} \times \eta}{V_{REG}}$
2. Inductor ripple current:  $\Delta I_L = \frac{V_{IN\_min} \times D}{f_{SW} \times L}$
3. Maximum output current:  $I_{OUT\_max} = \left( I_{LIM\_min} + \frac{\Delta I_L}{2} \right) \times (1-D)$
4. Peak switch current of the application:  $I_{SWPEAK} = \frac{I_{OUT}}{1-D} + \frac{\Delta I_L}{2}$   
 $\eta$  = Estimated boost converter efficiency (use the number from the efficiency plots or 85% as an estimation)  
 $f_{SW}$  = Boost converter switching frequency (1.8 MHz)  
 $L$  = Selected inductor value for the boost converter (see the Inductor Selection section)  
 $I_{SWPEAK}$  = Boost converter switch current at the desired output current (must be  $< [ I_{LIM\_min} + \Delta I_L ]$ )  
 $\Delta I_L$  = Inductor peak-to-peak ripple current  
 $V_{REG} = \max(V_{POS}, |V_{NEG}|) + 200 \text{ mV}$  (in 40mA mode — + 300 mV in 80mA mode — + 500 mV with TPS65132Sx with SYNC = HIGH)  
 $I_{OUT} = I_{OUT\_VPOS} + |I_{OUT\_VNEG}|$  ( $I_{OUT\_max}$  being the maximum current delivered on each rail)

The peak switch current is the current that the integrated switch and the inductor have to handle. The calculation must be done for the minimum input voltage where the peak switch current is highest.

#### 9.2.1.2.2.1 Inductor Selection (Boost Converter)

**Saturation current:** the inductor must handle the maximum peak current ( $I_{L\_SAT} > I_{SWPEAK}$ , or  $I_{L\_SAT} > [ I_{LIM\_min} + \Delta I_L ]$  as conservative approach)

**DC Resistance:** the lower the DCR, the lower the losses

**Inductor value:** in order to keep the ratio  $I_{OUT}/\Delta I_L$  low enough for proper sensing operation purpose, it is recommended to use a 4.7  $\mu\text{H}$  inductor for 40mA mode (a 2.2  $\mu\text{H}$  might however be used, but the efficiency might be lower than with 4.7  $\mu\text{H}$  at light loads depending on the inductor characteristics).

**Table 9. Inductor Selection Boost<sup>(1)</sup>**

| L<br>( $\mu$ H) | SUPPLIER <sup>(1)</sup> | COMPONENT CODE   | EIA SIZE | DCR TYP<br>(m $\Omega$ ) | I <sub>SAT</sub><br>(A) |
|-----------------|-------------------------|------------------|----------|--------------------------|-------------------------|
| 2.2             | Toko                    | 1269AS-H-2R2N=P2 | 1008     | 130                      | 2.4                     |
| 2.2             | Murata                  | LQM2HPN2R2MG0    | 1008     | 80                       | 1.3                     |
| 2.2             | Murata                  | LQM21PN2R2NGC    | 0805     | 250                      | 0.8                     |
| 4.7             | Toko                    | 1269AS-H-4R7N=P2 | 1008     | 250                      | 1.6                     |
| 4.7             | Murata                  | LQM21PN4R7MGR    | 0805     | 230                      | 0.8                     |
| 4.7             | FDK                     | MIPS2520D4R7     | 1008     | 280                      | 0.7                     |

(1) See [Third-Party Products Disclaimer](#)

#### 9.2.1.2.2.2 Input Capacitor Selection (Boost Converter)

For best input voltage filtering low ESR ceramic capacitors are recommended. TPS65132 has an analog input pin VIN. A 4.7  $\mu$ F minimum bypass capacitor is required as close as possible from VIN to GND. This capacitor is also used as the boost converter input capacitor.

For better input voltage filtering, this value can be increased or two capacitors can be used: one 4.7  $\mu$ F input capacitor for the boost converter as well as a 1  $\mu$ F bypass capacitor close to the VIN pin. Refer to the [Recommended Operating Conditions](#), [Table 10](#) and [Figure 19](#) for input capacitor recommendations.

#### 9.2.1.2.2.3 Output Capacitor Selection (Boost Converter)

For the best output voltage filtering, low-ESR ceramic capacitors are recommended. A minimum of 4.7  $\mu$ F ceramic output capacitor is required. Higher capacitor values can be used to improve the load transient response. Refer to the [Recommended Operating Conditions](#), [Table 10](#) and [Figure 19](#) for output capacitor recommendations.

**Table 10. Input And Output Capacitor Selection<sup>(1)</sup>**

| CAPACITOR<br>( $\mu$ F) | SUPPLIER | COMPONENT CODE    | EIA SIZE (Thickness<br>max.) | VOLTAGE RATING<br>(V) | COMMENTS  |
|-------------------------|----------|-------------------|------------------------------|-----------------------|---|
| 2.2                     | Murata   | GRM188R61C225KAAD | 0603 (0.9 mm)                | 16                    | C <sub>FLY</sub>  |
| 4.7                     | Murata   | GRM188R61C475KAAJ | 0603 (0.95 mm)               | 16                    | C <sub>IN</sub> , C <sub>NEG</sub> , C <sub>POS</sub> ,<br>C <sub>REG</sub> |
| 10                      | Murata   | GRM219R61C106KA73 | 0603 (0.95 mm)               | 16                    | C <sub>NEG</sub> , C <sub>REG</sub>   |

(1) See [Third-Party Products Disclaimer](#)

#### 9.2.1.2.3 Input Capacitor Selection (LDO)

The LDO input capacitor is also the boost converter output capacitor. Refer to the [Recommended Operating Conditions](#), [Table 10](#) and [Figure 19](#).

#### 9.2.1.2.4 Output Capacitor Selection (LDO)

The LDO is designed to operate with a 4.7  $\mu$ F minimum ceramic output capacitor. Refer to the [Recommended Operating Conditions](#), [Table 10](#) and [Figure 19](#).

#### 9.2.1.2.5 Input Capacitor Selection (CPN)

The CPN input capacitor is also the boost converter output capacitor. Refer to the [Recommended Operating Conditions](#), [Table 10](#) and [Figure 19](#).

#### 9.2.1.2.6 Output Capacitor Selection (CPN)

The CPN is designed to operate with a 4.7  $\mu$ F minimum ceramic output capacitor. Refer to the [Recommended Operating Conditions](#), [Table 10](#) and [Figure 19](#).

### 9.2.1.2.7 Flying Capacitor Selection (CPN)

The CPN needs an external flying capacitor. The minimum value is 2.2  $\mu\text{F}$ . Special care must be taken while choosing the flying capacitor as it will directly impact the output voltage accuracy and load regulation performance. Therefore, a minimum capacitance of 1  $\mu\text{F}$  must be achieved by the capacitor at a DC bias voltage of  $|V_{\text{NEG}}| + 300 \text{ mV}$ . For proper operation, the flying capacitor value must be lower than the output capacitor of the boost converter on REG pin.

### 9.2.1.3 Application Curves

$V_{\text{IN}} = 3.7 \text{ V}$ ,  $V_{\text{POS}} = 5.4 \text{ V}$ ,  $V_{\text{NEG}} = -5.4 \text{ V}$ , unless otherwise noted

**Table 11. Component List Used For The Application Curves**

| REFERENCE | DESCRIPTION  | MANUFACTURER AND PART NUMBER <sup>(1)</sup> |
|-----------|--|---|
| C         | 2.2 $\mu\text{F}$ , 16 V, 0603, X5R, ceramic                                       | Murata - GRM188R61C225KAAD                  |
|           | 4.7 $\mu\text{F}$ , 16 V, 0603, X5R, ceramic                                       | Murata - GRM188R61C475KAAJ                  |
|           | 10 $\mu\text{F}$ , 16 V, 0603, X5R, ceramic  | Murata - GRM188R61E106MA73                  |
| L         | 2.2 $\mu\text{H}$ , 2.4 A, 130 m $\Omega$ , 2.5 mm $\times$ 2.0 mm $\times$ 1.0 mm | Toko - DFE252010C (1269AS-H-2R2N=P2)        |
|           | 4.7 $\mu\text{H}$ , 1.6 A, 250 m $\Omega$ , 2.5 mm $\times$ 2.0 mm $\times$ 1.0 mm | Toko - DFE252010C (1269AS-H-4R7N=P2)        |
| U1        | TPS65132AYFF   | Texas Instruments                           |

(1) See [Third-Party Products Disclaimer](#)

**Table 12. Table Of Graphs**

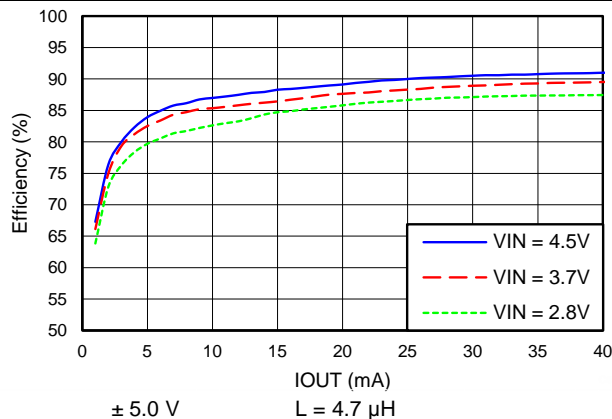
| PARAMETER                      | CONDITIONS  | Figure                    |
|--------------------------------|---|---------------------------|
| <b>EFFICIENCY</b>              |   |                           |
| Efficiency vs. Output Current  | $\pm 5.0 \text{ V} - 40\text{mA Mode} - L = 4.7 \mu\text{H}$  | <a href="#">Figure 20</a> |
| Efficiency vs. Output Current  | $\pm 5.4 \text{ V} - 40\text{mA Mode} - L = 4.7 \mu\text{H}$  | <a href="#">Figure 21</a> |
| Efficiency vs. Output Current  | $\pm 5.0 \text{ V} - 40\text{mA Mode} - L = 2.2 \mu\text{H}$  | <a href="#">Figure 22</a> |
| Efficiency vs. Output Current  | $\pm 5.4 \text{ V} - 40\text{mA Mode} - L = 2.2 \mu\text{H}$  | <a href="#">Figure 23</a> |
| <b>CONVERTERS WAVEFORMS</b>    |   |                           |
| $V_{\text{NEG}}$ Output Ripple | $I_{\text{NEG}} = 2 \text{ mA} / 20 \text{ mA} / 40 \text{ mA} - 40\text{mA Mode} - C_{\text{OUT}} = 4.7 \mu\text{F}$   | <a href="#">Figure 24</a> |
| $V_{\text{NEG}}$ Output Ripple | $I_{\text{NEG}} = 2 \text{ mA} / 20 \text{ mA} / 40 \text{ mA} - 40\text{mA Mode} - C_{\text{OUT}} = 2 \times 4.7 \mu\text{F}$  | <a href="#">Figure 25</a> |
| $V_{\text{POS}}$ Output Ripple | Any load  | <a href="#">Figure 26</a> |
| <b>LOAD TRANSIENT</b>          |   |                           |
| Load Transient                 | $V_{\text{IN}} = 2.9 \text{ V} - I_{\text{POS}} = -I_{\text{NEG}} = 5 \text{ mA} \rightarrow 35 \text{ mA} \rightarrow 5 \text{ mA} - 40\text{mA Mode} - L = 4.7 \mu\text{H}$   | <a href="#">Figure 27</a> |
| Load Transient                 | $V_{\text{IN}} = 3.7 \text{ V} - I_{\text{POS}} = -I_{\text{NEG}} = 5 \text{ mA} \rightarrow 35 \text{ mA} \rightarrow 5 \text{ mA} - 40\text{mA Mode} - L = 4.7 \mu\text{H}$   | <a href="#">Figure 28</a> |
| Load Transient                 | $V_{\text{IN}} = 4.5 \text{ V} - I_{\text{POS}} = -I_{\text{NEG}} = 5 \text{ mA} \rightarrow 35 \text{ mA} \rightarrow 5 \text{ mA} - 40\text{mA Mode} - L = 4.7 \mu\text{H}$   | <a href="#">Figure 29</a> |
| <b>LINE TRANSIENT</b>          |   |                           |
| Line Transient                 | $V_{\text{IN}} = 2.8 \text{ V} \rightarrow 4.5 \text{ V} \rightarrow 2.8 \text{ V} - I_{\text{POS}} = -I_{\text{NEG}} = 0 \text{ mA} - 40\text{mA Mode} - L = 4.7 \mu\text{H}$  | <a href="#">Figure 30</a> |
| Line Transient                 | $V_{\text{IN}} = 2.8 \text{ V} \rightarrow 4.5 \text{ V} \rightarrow 2.8 \text{ V} - I_{\text{POS}} = -I_{\text{NEG}} = 5 \text{ mA} - 40\text{mA Mode} - L = 4.7 \mu\text{H}$  | <a href="#">Figure 31</a> |
| Line Transient                 | $V_{\text{IN}} = 2.8 \text{ V} \rightarrow 4.5 \text{ V} \rightarrow 2.8 \text{ V} - I_{\text{POS}} = -I_{\text{NEG}} = 35 \text{ mA} - 40\text{mA Mode} - L = 4.7 \mu\text{H}$ | <a href="#">Figure 32</a> |

**Table 12. Table Of Graphs (continued)**

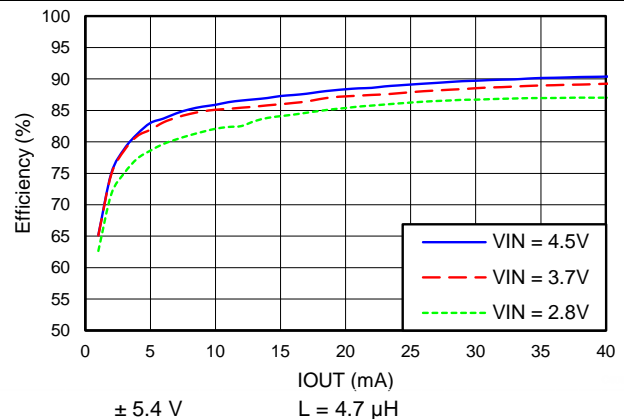
| PARAMETER                          | CONDITIONS  | Figure    |
|------------------------------------|---|-----------|
| <b>POWER SEQUENCING</b>            |   |           |
| Power-up Sequencing                | Simultaneous — no load  | Figure 33 |
| Power-down Sequencing              | Simultaneous — no load with Active Discharge  | Figure 34 |
| Power-up Sequencing                | Sequential — no load  | Figure 35 |
| Power-down Sequencing              | Sequential — no load with Active Discharge  | Figure 36 |
| Power-up/down Sequencing           | Simultaneous — no load with Active Discharge  | Figure 37 |
| Power-up/down Sequencing           | Simultaneous — no load without Active Discharge   | Figure 38 |
| <b>INRUSH CURRENT</b>              |   |           |
| Inrush Current                     | Simultaneous — no load — 40mA Mode  | Figure 39 |
| Inrush Current                     | Sequential — no load — 40mA Mode  | Figure 40 |
| Inrush Current                     | Simultaneous — no load — 40mA Mode — TPS65132B2, -Lx, -Sx, -Tx, -Wx   | Figure 41 |
| Inrush Current                     | Sequential — no load — 40mA Mode — TPS65132B2, -Lx, -Sx, -Tx, -Wx   | Figure 42 |
| <b>LOAD REGULATION</b>             |   |           |
| V <sub>POS</sub> vs Output Current | V <sub>POS</sub> = 5.0 V — 40mA Mode — I <sub>POS</sub> = 0 mA to 40 mA — L = 4.7 μH and 2.2 μH                             | Figure 43 |
| V <sub>POS</sub> vs Output Current | V <sub>POS</sub> = 5.4 V — 40mA Mode — I <sub>POS</sub> = 0 mA to 40 mA — L = 4.7 μH and 2.2 μH                             | Figure 44 |
| V <sub>NEG</sub> vs Output Current | V <sub>NEG</sub> = -5.0 V — 40mA Mode — I <sub>NEG</sub> = 0 mA to 40 mA — L = 4.7 μH and 2.2 μH                            | Figure 45 |
| V <sub>NEG</sub> vs Output Current | V <sub>NEG</sub> = -5.4 V — 40mA Mode — I <sub>NEG</sub> = 0 mA to 40 mA — L = 4.7 μH and 2.2 μH                            | Figure 46 |
| <b>LINE REGULATION</b>             |   |           |
| V <sub>POS</sub> vs Output Voltage | V <sub>IN</sub> = 2.5 V to 5.5 V — V <sub>POS</sub> = 5.0 V — 40mA Mode — I <sub>POS</sub> = 20 mA — L = 4.7 μH and 2.2 μH  | Figure 47 |
| V <sub>POS</sub> vs Output Voltage | V <sub>IN</sub> = 2.5 V to 5.5 V — V <sub>POS</sub> = 5.4 V — 40mA Mode — I <sub>POS</sub> = 20 mA — L = 4.7 μH and 2.2 μH  | Figure 48 |
| V <sub>NEG</sub> vs Output Voltage | V <sub>IN</sub> = 2.5 V to 5.5 V — V <sub>NEG</sub> = -5.0 V — 40mA Mode — I <sub>NEG</sub> = 20 mA — L = 4.7 μH and 2.2 μH | Figure 49 |
| V <sub>NEG</sub> vs Output Voltage | V <sub>IN</sub> = 2.5 V to 5.5 V — V <sub>NEG</sub> = -5.4 V — 40mA Mode — I <sub>NEG</sub> = 20 mA — L = 4.7 μH and 2.2 μH | Figure 50 |

**NOTE**

In this section, I<sub>OUT</sub> means that the outputs are loaded with I<sub>POS</sub> = -I<sub>NEG</sub> simultaneously.



**Figure 20. Combined Efficiency — 40mA Mode**



**Figure 21. Combined Efficiency — 40mA Mode**

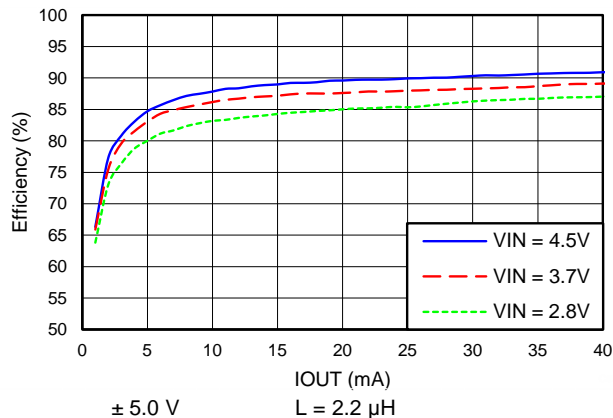


Figure 22. Combined Efficiency — 40mA Mode

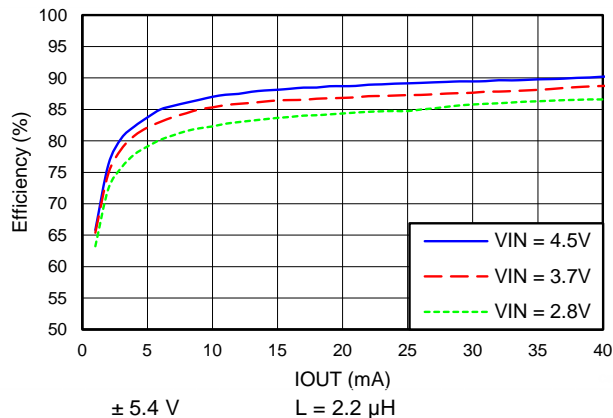


Figure 23. Combined Efficiency — 40mA Mode

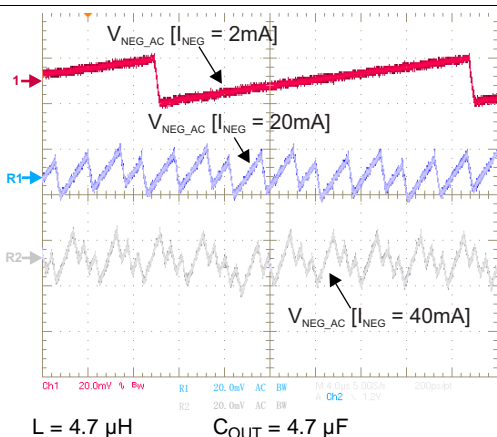


Figure 24.  $V_{NEG}$  Output Voltage Ripple — 40mA Mode

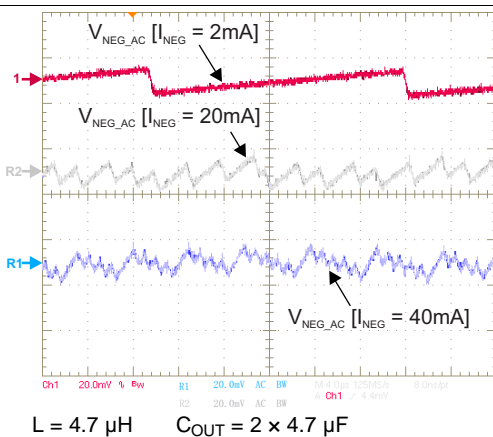


Figure 25.  $V_{NEG}$  Output Voltage Ripple — 40mA Mode

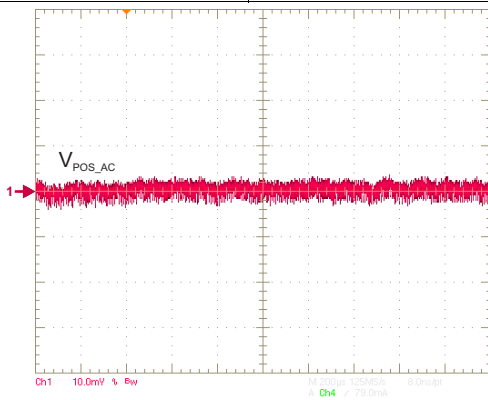


Figure 26.  $V_{POS}$  Output Voltage Ripple

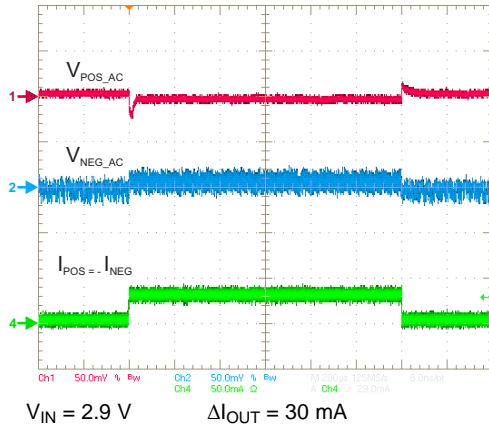


Figure 27. Load Transient — 40mA Mode

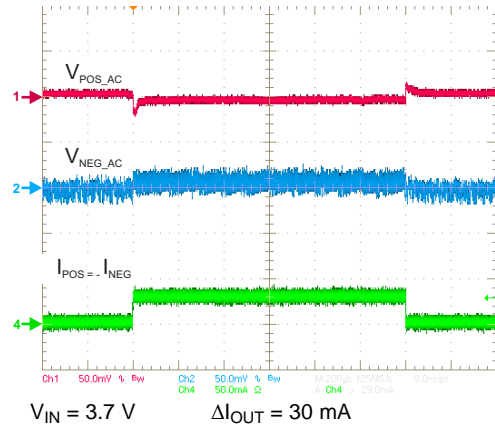


Figure 28. Load Transient — 40mA Mode

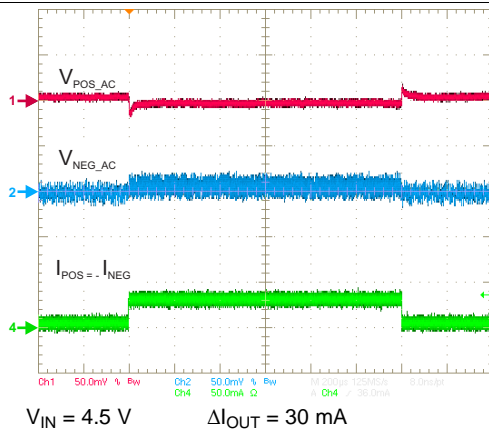


Figure 29. Load Transient — 40mA Mode

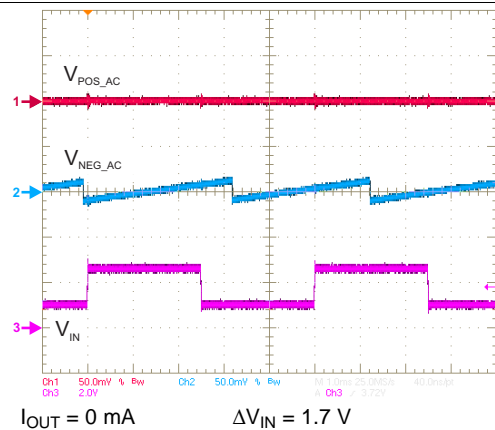


Figure 30. Line Transient — 40mA Mode

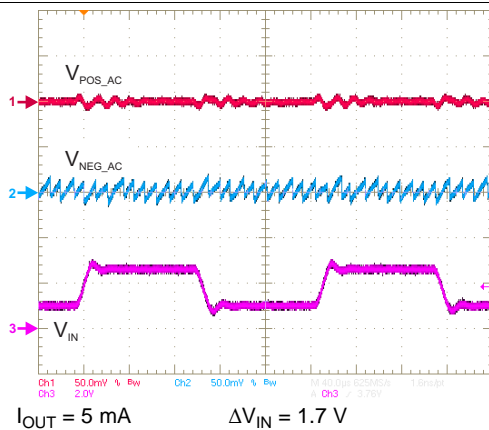


Figure 31. Line Transient — 40mA Mode

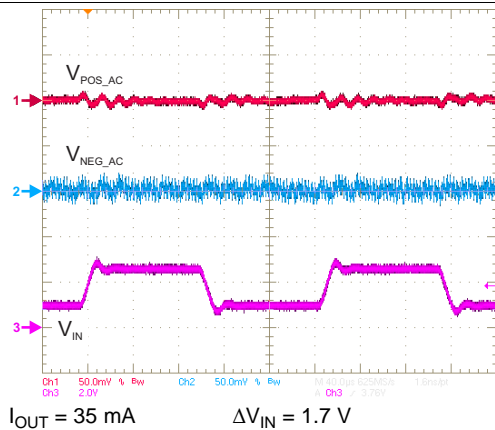


Figure 32. Line Transient — 40mA Mode



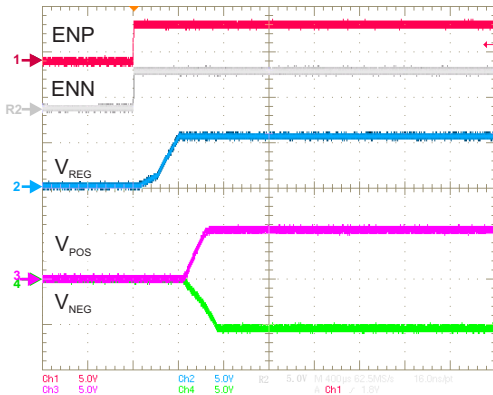


Figure 33. Power-Up Sequencing — Simultaneous

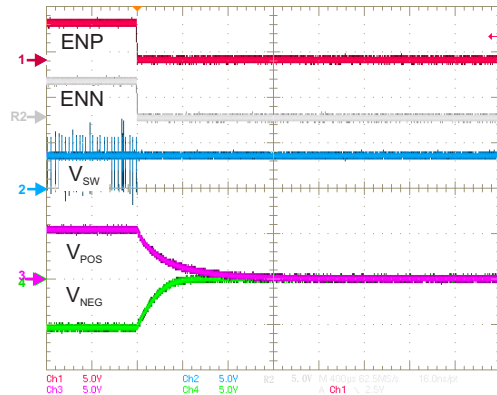


Figure 34. Power-Down Sequencing — Simultaneous (with Active Discharge)

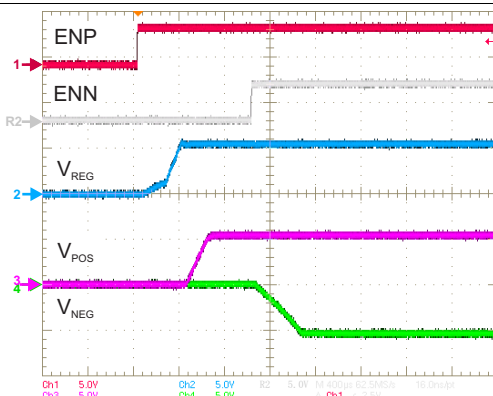


Figure 35. Power-Up Sequencing — Sequential

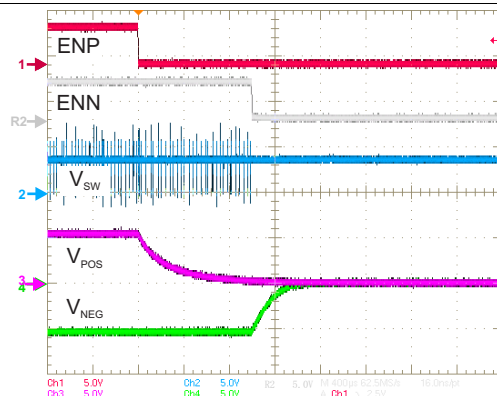


Figure 36. Power-Down Sequencing — Sequential (with Active Discharge)

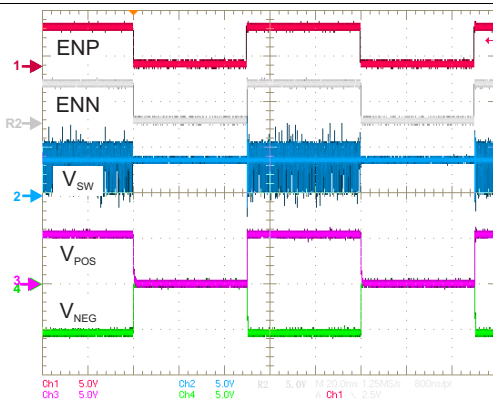


Figure 37. Power-Up/Down With Active Discharge

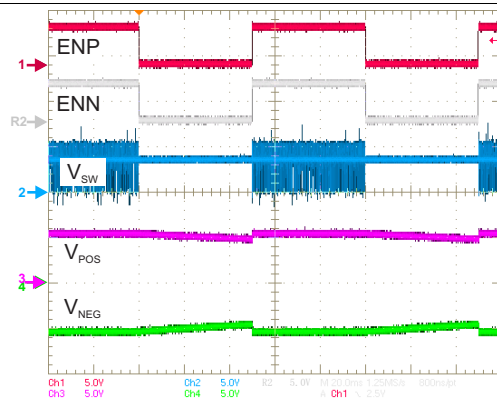


Figure 38. Power-Up/Down Without Active Discharge (TPS65132Ax only)

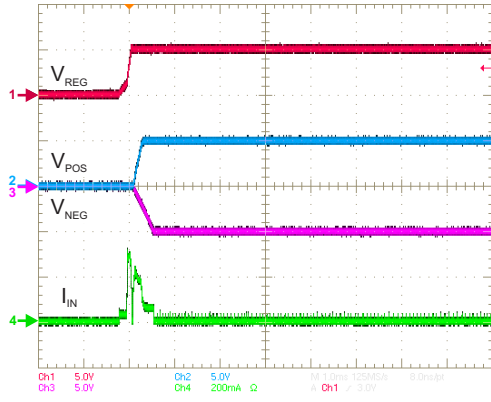


Figure 39. Inrush Current — Simultaneous

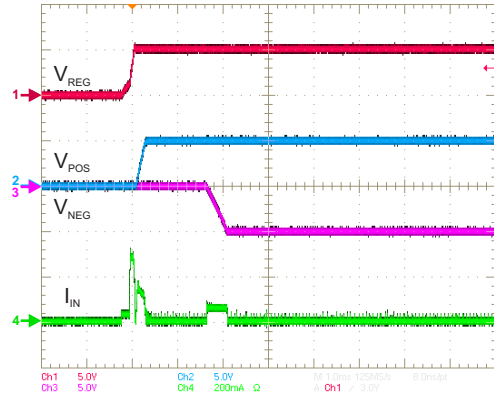


Figure 40. Inrush Current — Sequential

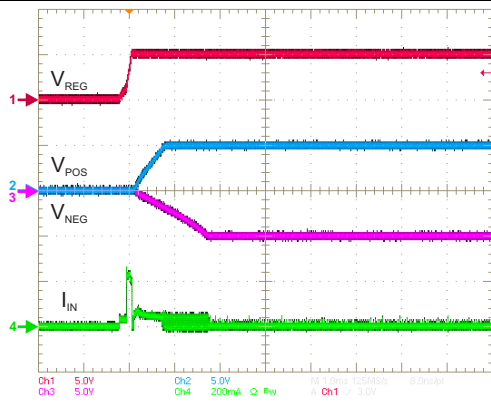


Figure 41. Inrush Current — Simultaneous (TPS65132B2, -Lx, -Sx, -Tx, -Wx)

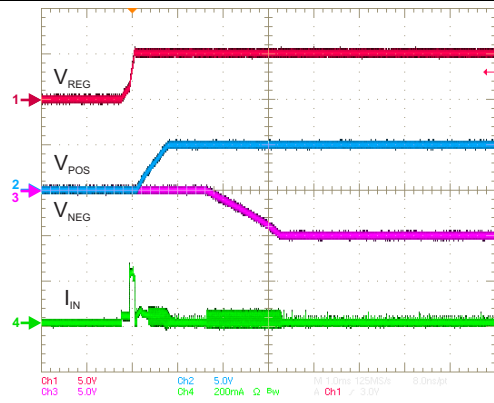


Figure 42. Inrush Current — Sequential (TPS65132B2, -Lx, -Sx, -Tx, -Wx)

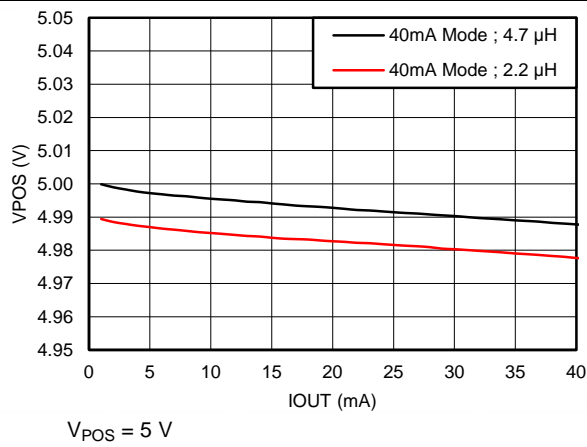


Figure 43. Load Regulation

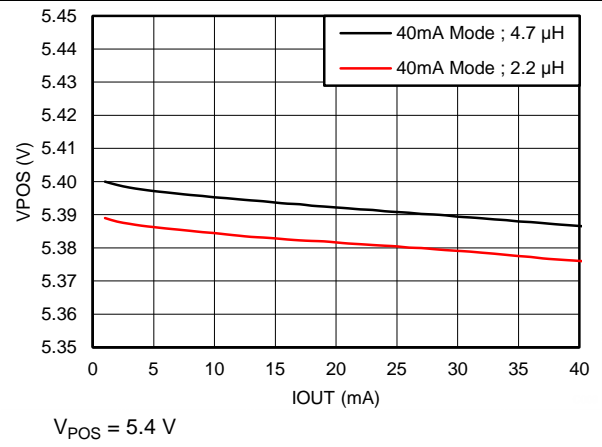


Figure 44. Load Regulation

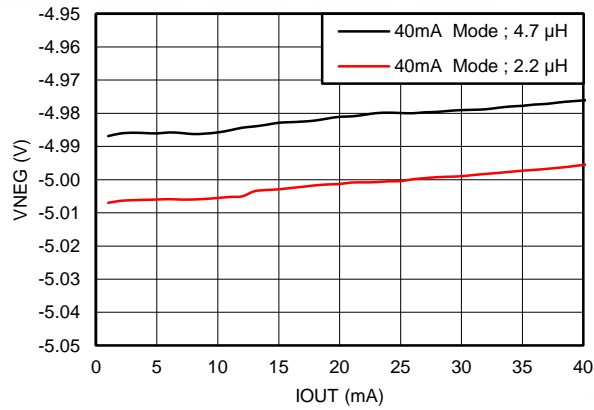


Figure 45. Load Regulation

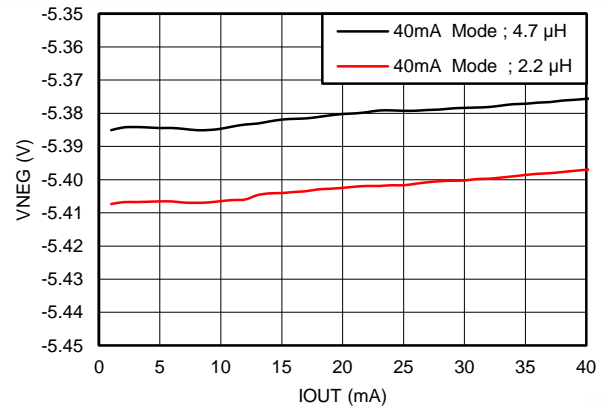


Figure 46. Load Regulation

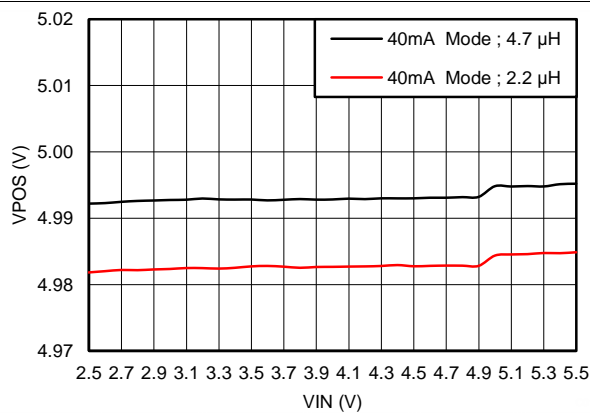


Figure 47. Line Regulation

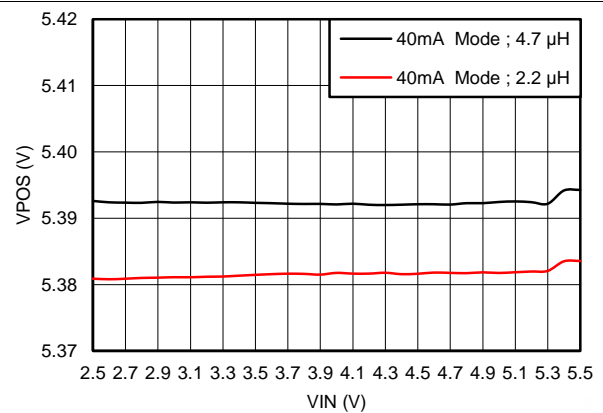


Figure 48. Line Regulation

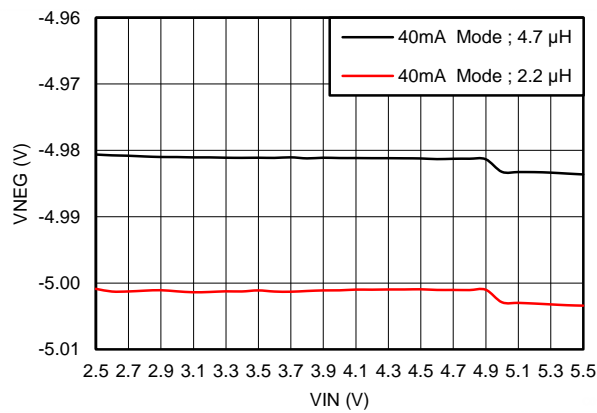


Figure 49. Line Regulation

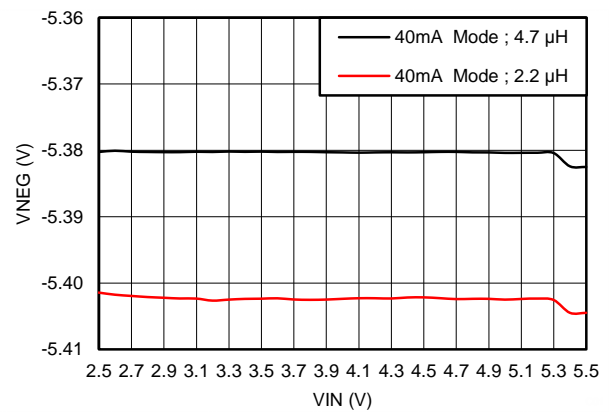


Figure 50. Line Regulation

### 9.2.2 Mid-current Applications ( $\leq 80\text{ mA}$ )

The TPS65132 can be programmed to 80mA mode with the APPS bit to support applications that require output currents up to 80 mA (refer to Figure 17). The 80mA mode is limiting the negative charge pump (CPN) output current to 80 mA DC in order to provide the highest efficiency possible where the  $V_{(POS)}$  rail can deliver up to 200 mA DC regardless of the mode. Output peak currents are supported by the output capacitors.

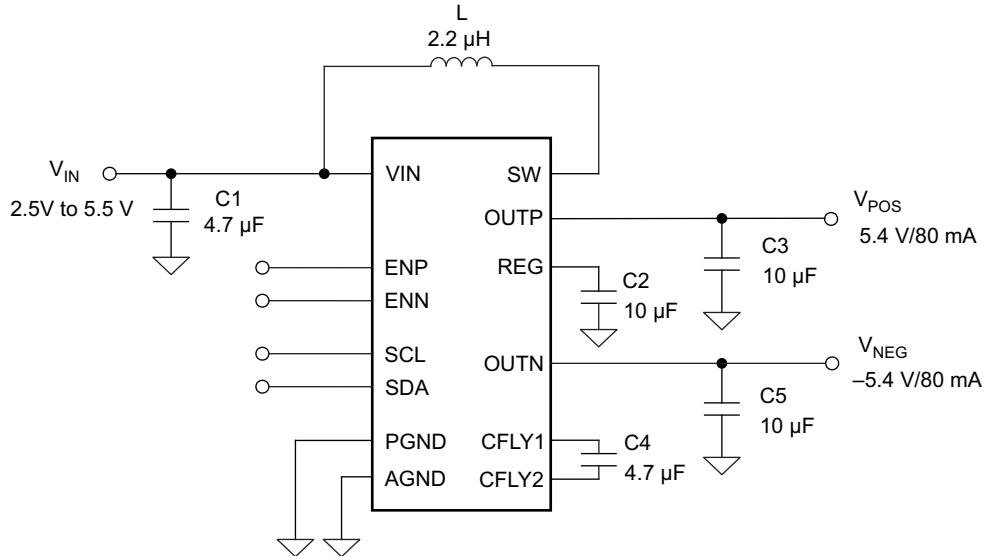


Figure 51. Typical Mid-current Application Circuit

#### 9.2.2.1 Design Requirements

Table 13. Design Parameters

| PARAMETERS                               | EXAMPLE VALUES                   |
|--|----------------------------------|
| Input Voltage Range                      | 2.5 V to 5.5 V                   |
| Output Voltages                          | 4.0 V to 6.0 V, -4.0 V to -6.0 V |
| Output Current Rating                    | 80 mA                            |
| Boost Converter Switching Frequency      | 1.8 MHz                          |
| Negative Charge Pump Switching Frequency | 1.0 MHz                          |

#### 9.2.2.2 Detailed Design Procedure

The design procedure for the mid-current applications (80mA mode) is identical to the one for the low-current applications (40mA mode), except for the BOM (bill of materials). Refer to the [Detailed Design Procedure](#) for details about the sequencing and the general component selection.

##### 9.2.2.2.1 Boost Converter Design Procedure

###### 9.2.2.2.1.1 Inductor Selection (Boost Converter)

In order to keep the ratio  $I_{OUT}/\Delta I_L$  low enough for proper sensing operation purpose, it is recommended to use a 2.2  $\mu\text{H}$  inductor for 80mA mode. For details, see [Inductor Selection \(Boost Converter\)](#).

###### 9.2.2.2.1.2 Input Capacitor Selection (Boost Converter)

A 4.7  $\mu\text{F}$  minimum bypass capacitor is required as close as possible from VIN to GND. This capacitor is also used as the boost converter input capacitor.

For better input voltage filtering, this value can be increased or two capacitors can be used: one 4.7  $\mu\text{F}$  input capacitor for the boost converter as well as a 1  $\mu\text{F}$  bypass capacitor close to the VIN pin. Refer to the [Recommended Operating Conditions](#), Table 10 and Figure 51 for input capacitor recommendations.

### 9.2.2.2.1.3 Output Capacitor Selection (Boost Converter)

For best output voltage filtering low ESR ceramic capacitors are recommended. A minimum of 10  $\mu\text{F}$  ceramic output capacitor is required. Higher capacitor values can be used to improve the load transient response. Refer to the [Recommended Operating Conditions, Table 10](#) and [Figure 51](#) for output capacitor recommendations.

### 9.2.2.2.2 Input Capacitor Selection (LDO)

The LDO input capacitor is also the boost converter output capacitor. Refer to the [Recommended Operating Conditions, Table 10](#) and [Figure 51](#).

### 9.2.2.2.3 Output Capacitor Selection (LDO)

The LDO is designed to operate with a 4.7  $\mu\text{F}$  minimum ceramic output capacitor. Refer to the [Recommended Operating Conditions, Table 10](#) and [Figure 51](#).

### 9.2.2.2.4 Input Capacitor Selection (CPN)

The CPN input capacitor is also the boost converter output capacitor. Refer to the [Recommended Operating Conditions, Table 10](#) and [Figure 51](#).

### 9.2.2.2.5 Output Capacitor Selection (CPN)

The CPN is designed to operate with a 10  $\mu\text{F}$  minimum ceramic output capacitor. Refer to the [Recommended Operating Conditions, Table 10](#) and [Figure 51](#).

### 9.2.2.2.6 Flying Capacitor Selection (CPN)

The CPN needs an external flying capacitor. The minimum value is 4.7  $\mu\text{F}$ . Special care must be taken while choosing the flying capacitor as it will directly impact the output voltage accuracy and load regulation performance. Therefore, a minimum capacitance of 2.2  $\mu\text{F}$  must be achieved by the capacitor at a DC bias voltage of  $|V_{\text{NEG}}| + 300 \text{ mV}$ . For proper operation, the flying capacitor value must be lower than the output capacitor of the boost converter on REG pin.

## 9.2.2.3 Application Curves

$V_{\text{IN}} = 3.7 \text{ V}$ ,  $V_{\text{POS}} = 5.4 \text{ V}$ ,  $V_{\text{NEG}} = -5.4 \text{ V}$ , unless otherwise noted

**Table 14. Component List For Typical Characteristics Circuits**

| REFERENCE | DESCRIPTION  | MANUFACTURER AND PART NUMBER <sup>(1)</sup> |
|-----------|--|---|
| C         | 2.2 $\mu\text{F}$ , 16 V, 0603, X5R, ceramic                                       | Murata - GRM188R61C225KAAAD                 |
|           | 4.7 $\mu\text{F}$ , 16 V, 0603, X5R, ceramic                                       | Murata - GRM188R61C475KAAJ                  |
|           | 10 $\mu\text{F}$ , 16 V, 0603, X5R, ceramic  | Murata - GRM188R61E106MA73                  |
| L         | 2.2 $\mu\text{H}$ , 2.4 A, 130 m $\Omega$ , 2.5 mm $\times$ 2.0 mm $\times$ 1.0 mm | Toko - DFE252010C (1269AS-H-2R2N=P2)        |
| U1        | TPS65132AYFF   | Texas Instruments                           |

(1) See [Third-Party Products Disclaimer](#)

**Table 15. Table Of Graphs**

| PARAMETER                          | CONDITIONS  | Figure                    |
|------------------------------------|---|---------------------------|
| <b>EFFICIENCY</b>                  |   |                           |
| Efficiency vs. Output Current      | $\pm 5.0\text{ V}$ — 80mA Mode — $L = 2.2\ \mu\text{H}$   | <a href="#">Figure 52</a> |
| Efficiency vs. Output Current      | $\pm 5.4\text{ V}$ — 80mA Mode — $L = 2.2\ \mu\text{H}$   | <a href="#">Figure 53</a> |
| <b>CONVERTERS WAVEFORMS</b>        |   |                           |
| $V_{\text{NEG}}$ Output Ripple     | $I_{\text{NEG}} = 4\text{ mA} / 40\text{ mA} / 80\text{ mA}$ — 80mA Mode — $C_{\text{OUT}} = 10\ \mu\text{F}$   | <a href="#">Figure 54</a> |
| $V_{\text{NEG}}$ Output Ripple     | $I_{\text{NEG}} = 4\text{ mA} / 40\text{ mA} / 80\text{ mA}$ — 80mA Mode — $C_{\text{OUT}} = 2 \times 10\ \mu\text{F}$  | <a href="#">Figure 55</a> |
| $V_{\text{POS}}$ Output Ripple     | $I_{\text{POS}} = 150\text{ mA}$ — 80mA Mode  | <a href="#">Figure 56</a> |
| <b>LOAD TRANSIENT</b>              |   |                           |
| Load Transient                     | $V_{\text{IN}} = 2.9\text{ V}$ — $I_{\text{POS}} = -I_{\text{NEG}} = 10\text{ mA} \rightarrow 70\text{ mA} \rightarrow 10\text{ mA}$ — 80mA Mode — $L = 2.2\ \mu\text{H}$ | <a href="#">Figure 57</a> |
| Load Transient                     | $V_{\text{IN}} = 3.7\text{ V}$ — $I_{\text{POS}} = -I_{\text{NEG}} = 10\text{ mA} \rightarrow 70\text{ mA} \rightarrow 10\text{ mA}$ — 80mA Mode — $L = 2.2\ \mu\text{H}$ | <a href="#">Figure 58</a> |
| Load Transient                     | $V_{\text{IN}} = 4.5\text{ V}$ — $I_{\text{POS}} = -I_{\text{NEG}} = 10\text{ mA} \rightarrow 70\text{ mA} \rightarrow 10\text{ mA}$ — 80mA Mode — $L = 2.2\ \mu\text{H}$ | <a href="#">Figure 59</a> |
| <b>LINE TRANSIENT</b>              |   |                           |
| Line Transient                     | $V_{\text{IN}} = 2.8\text{ V} \rightarrow 4.5\text{ V} \rightarrow 2.8\text{ V}$ — $I_{\text{POS}} = -I_{\text{NEG}} = 0\text{ mA}$ — 80mA Mode — $L = 2.2\ \mu\text{H}$  | <a href="#">Figure 60</a> |
| Line Transient                     | $V_{\text{IN}} = 2.8\text{ V} \rightarrow 4.5\text{ V} \rightarrow 2.8\text{ V}$ — $I_{\text{POS}} = -I_{\text{NEG}} = 40\text{ mA}$ — 80mA Mode — $L = 2.2\ \mu\text{H}$ | <a href="#">Figure 61</a> |
| Line Transient                     | $V_{\text{IN}} = 2.8\text{ V} \rightarrow 4.5\text{ V} \rightarrow 2.8\text{ V}$ — $I_{\text{POS}} = -I_{\text{NEG}} = 70\text{ mA}$ — 80mA Mode — $L = 2.2\ \mu\text{H}$ | <a href="#">Figure 62</a> |
| <b>POWER SEQUENCING</b>            |   |                           |
| Power-up Sequencing                | Simultaneous — no load  | <a href="#">Figure 63</a> |
| Power-down Sequencing              | Simultaneous — no load with Active Discharge  | <a href="#">Figure 64</a> |
| Power-up Sequencing                | Sequential — no load  | <a href="#">Figure 65</a> |
| Power-down Sequencing              | Sequential — no load with Active Discharge  | <a href="#">Figure 66</a> |
| Power-up/down Sequencing           | Simultaneous — no load with Active Discharge  | <a href="#">Figure 67</a> |
| Power-up/down Sequencing           | Simultaneous — no load without Active Discharge   | <a href="#">Figure 68</a> |
| <b>INRUSH CURRENT</b>              |   |                           |
| Inrush Current                     | Simultaneous — no load — 80mA Mode  | <a href="#">Figure 69</a> |
| Inrush Current                     | Sequential — no load — 80mA Mode  | <a href="#">Figure 70</a> |
| Inrush Current                     | Simultaneous — no load — 80mA Mode — TPS65132B2, -Lx, -Sx, -Tx, -Wx   | <a href="#">Figure 71</a> |
| Inrush Current                     | Sequential — no load — 80mA Mode — TPS65132B2, -Lx, -Sx, -Tx, -Wx   | <a href="#">Figure 72</a> |
| <b>LOAD REGULATION</b>             |   |                           |
| $V_{\text{POS}}$ vs Output Current | $V_{\text{POS}} = 5.0\text{ V}$ — 80mA Mode — $I_{\text{POS}} = 0\text{ mA}$ to 80 mA — $L = 2.2\ \mu\text{H}$  | <a href="#">Figure 73</a> |
| $V_{\text{POS}}$ vs Output Current | $V_{\text{POS}} = 5.4\text{ V}$ — 80mA Mode — $I_{\text{POS}} = 0\text{ mA}$ to 80 mA — $L = 2.2\ \mu\text{H}$  | <a href="#">Figure 74</a> |
| $V_{\text{NEG}}$ vs Output Current | $V_{\text{NEG}} = -5.0\text{ V}$ — 80mA Mode — $I_{\text{NEG}} = 0\text{ mA}$ to 80 mA — $L = 2.2\ \mu\text{H}$   | <a href="#">Figure 75</a> |
| $V_{\text{NEG}}$ vs Output Current | $V_{\text{NEG}} = -5.4\text{ V}$ — 80mA Mode — $I_{\text{NEG}} = 0\text{ mA}$ to 80 mA — $L = 2.2\ \mu\text{H}$   | <a href="#">Figure 76</a> |
| <b>LINE REGULATION</b>             |   |                           |
| $V_{\text{POS}}$ vs Output Voltage | $V_{\text{IN}} = 2.5\text{ V}$ to 5.5 V — $V_{\text{POS}} = 5.0\text{ V}$ — 80mA Mode — $I_{\text{POS}} = 60\text{ mA}$ — $L = 2.2\ \mu\text{H}$                          | <a href="#">Figure 77</a> |
| $V_{\text{POS}}$ vs Output Voltage | $V_{\text{IN}} = 2.5\text{ V}$ to 5.5 V — $V_{\text{POS}} = 5.4\text{ V}$ — 80mA Mode — $I_{\text{POS}} = 60\text{ mA}$ — $L = 2.2\ \mu\text{H}$                          | <a href="#">Figure 78</a> |
| $V_{\text{NEG}}$ vs Output Voltage | $V_{\text{IN}} = 2.5\text{ V}$ to 5.5 V — $V_{\text{NEG}} = -5.0\text{ V}$ — 80mA Mode — $I_{\text{NEG}} = 60\text{ mA}$ — $L = 2.2\ \mu\text{H}$                         | <a href="#">Figure 79</a> |
| $V_{\text{NEG}}$ vs Output Voltage | $V_{\text{IN}} = 2.5\text{ V}$ to 5.5 V — $V_{\text{NEG}} = -5.4\text{ V}$ — 80mA Mode — $I_{\text{NEG}} = 60\text{ mA}$ — $L = 2.2\ \mu\text{H}$                         | <a href="#">Figure 80</a> |

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**NOTE**

In this section,  $I_{\text{OUT}}$  means that the outputs are loaded with  $I_{\text{POS}} = -I_{\text{NEG}}$  simultaneously.

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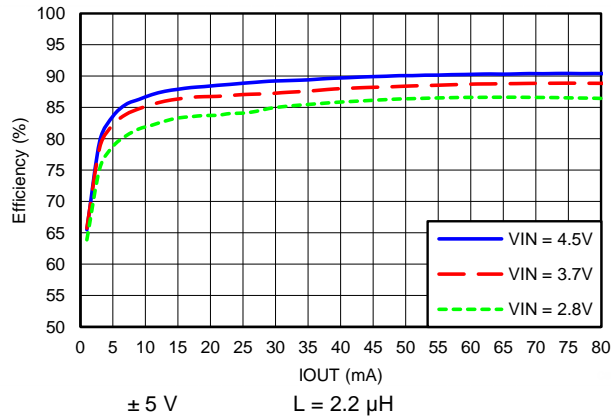


Figure 52. Combined Efficiency — 80mA Mode

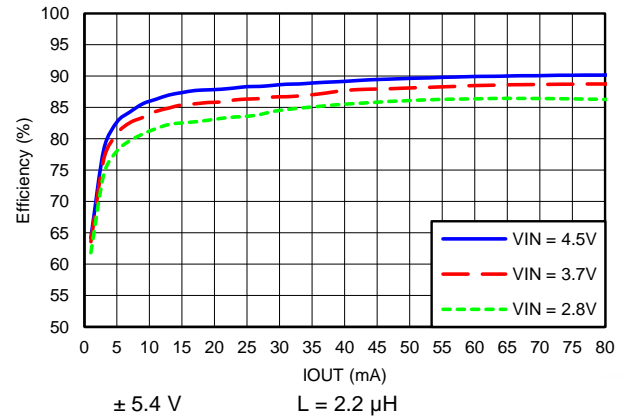


Figure 53. Combined Efficiency — 80mA Mode

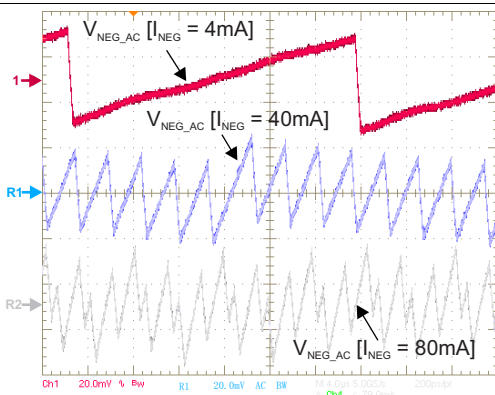


Figure 54.  $V_{NEG\_AC}$  Output Voltage Ripple — 80mA Mode

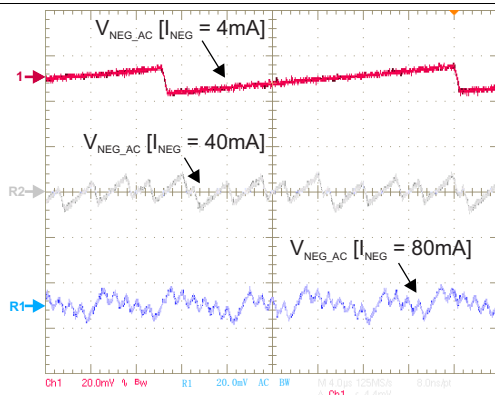


Figure 55.  $V_{NEG\_AC}$  Output Voltage Ripple — 80mA Mode

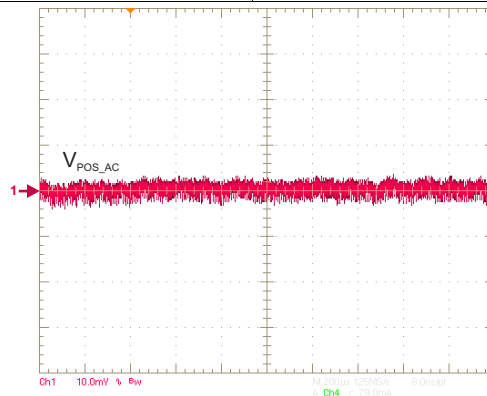


Figure 56.  $V_{POS\_AC}$  Output Voltage Ripple

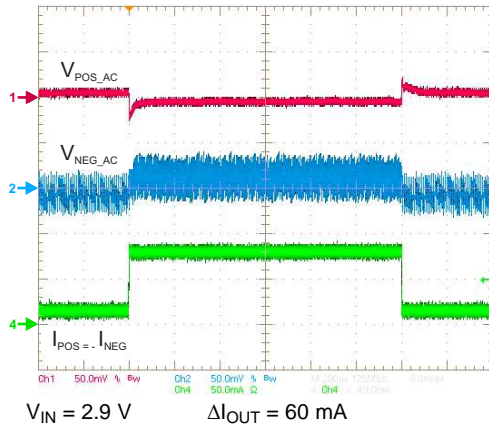


Figure 57. Load Transient — 80mA Mode

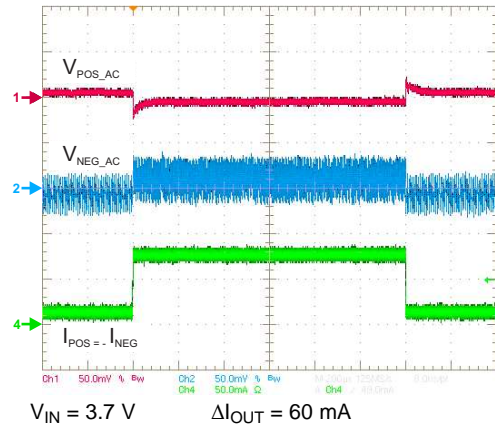


Figure 58. Load Transient — 80mA Mode

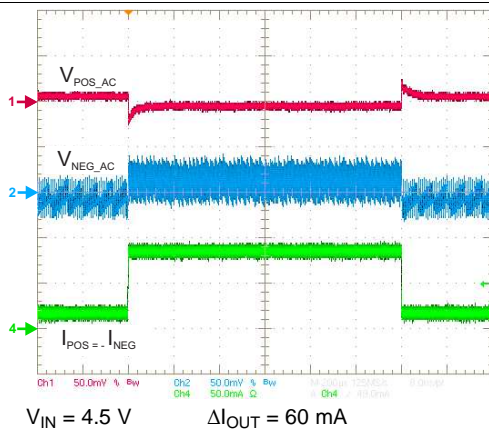


Figure 59. Load Transient — 80mA Mode

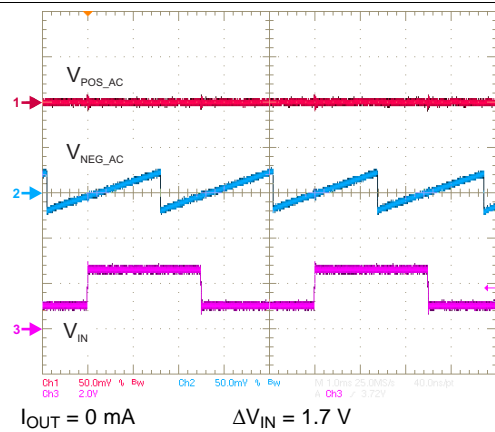


Figure 60. Line Transient — 80mA Mode

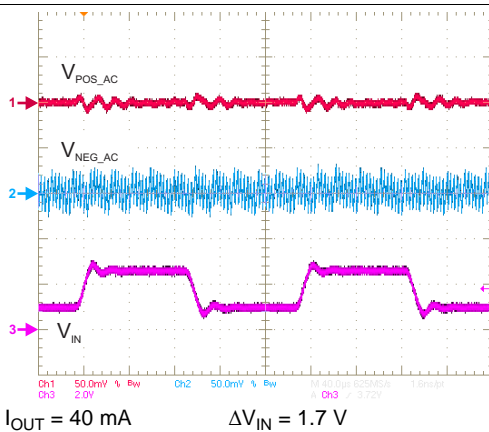


Figure 61. Line Transient — 80mA Mode

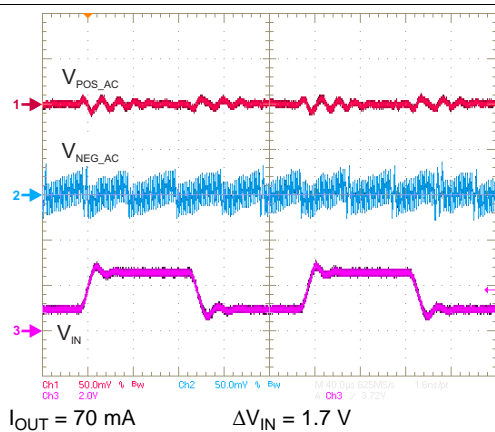


Figure 62. Line Transient — 80mA Mode



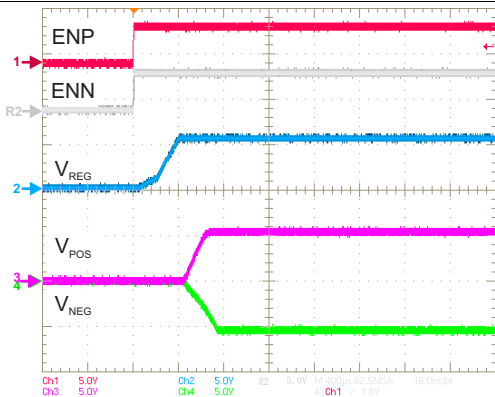


Figure 63. Power-Up Sequencing — Simultaneous

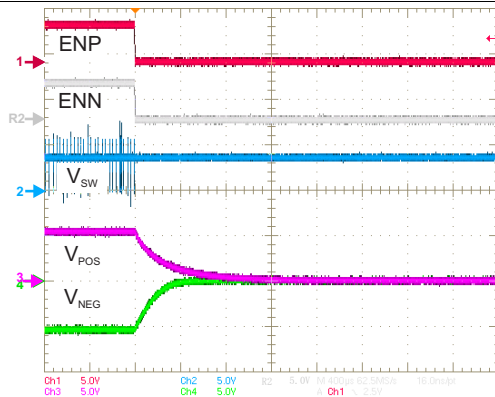


Figure 64. Power-Down Sequencing — Simultaneous (with Active Discharge)

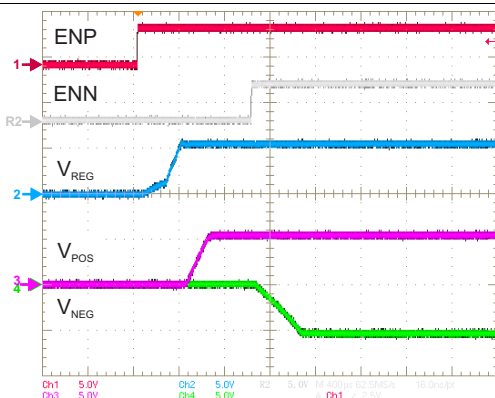


Figure 65. Power-Up Sequencing — Sequential

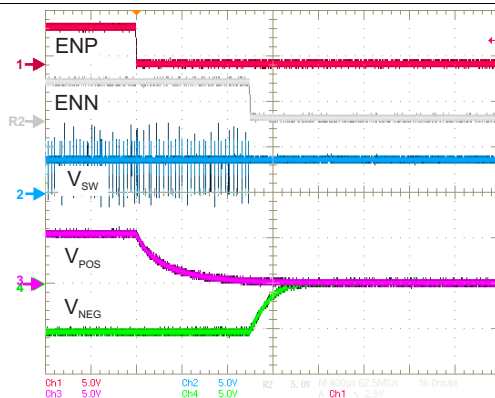


Figure 66. Power-Down Sequencing — Sequential (with Active Discharge)

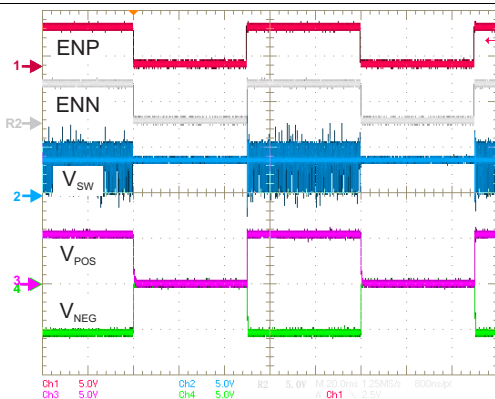


Figure 67. Power-Up/Down With Active Discharge

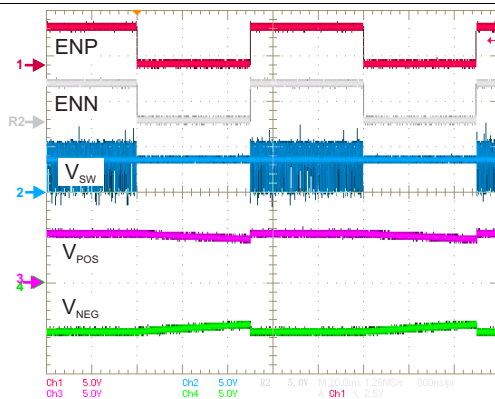


Figure 68. Power-Up/Down Without Active Discharge (TPS65132Ax only)

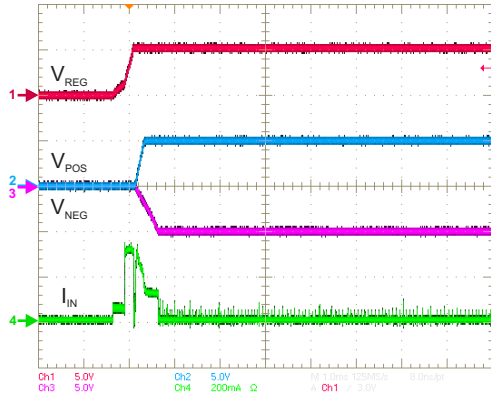


Figure 69. Inrush Current — Simultaneous

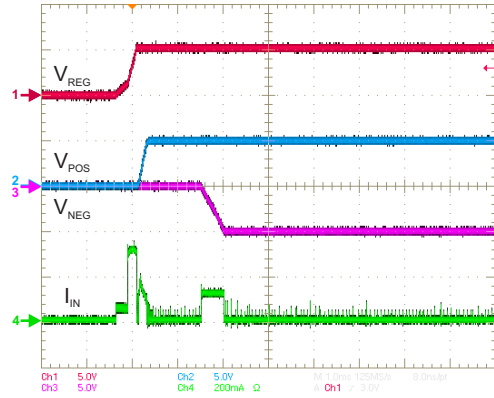


Figure 70. Inrush Current — Sequential

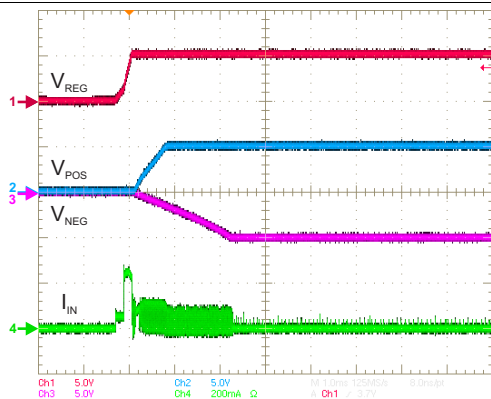


Figure 71. Inrush Current — Simultaneous (TPS65132B2, -Lx, -Sx, -Wx)

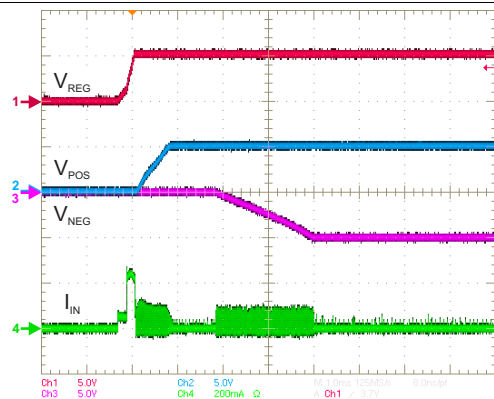


Figure 72. Inrush Current — Sequential (TPS65132B2, -Lx, -Sx, -Wx)

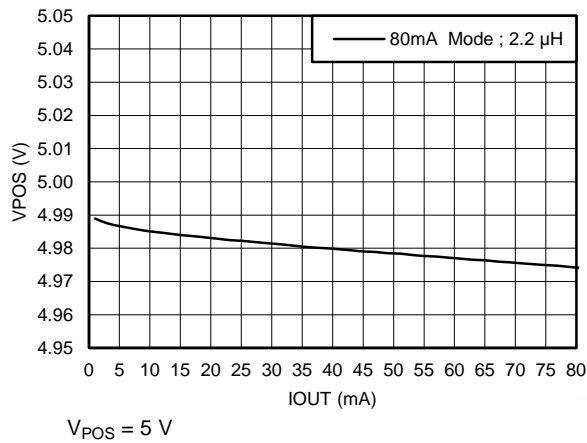


Figure 73. Load Regulation

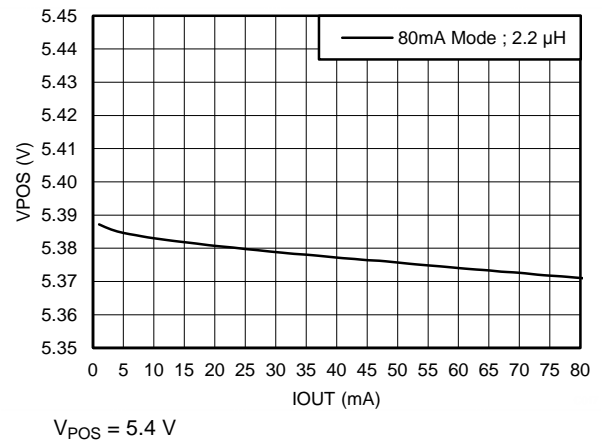


Figure 74. Load Regulation

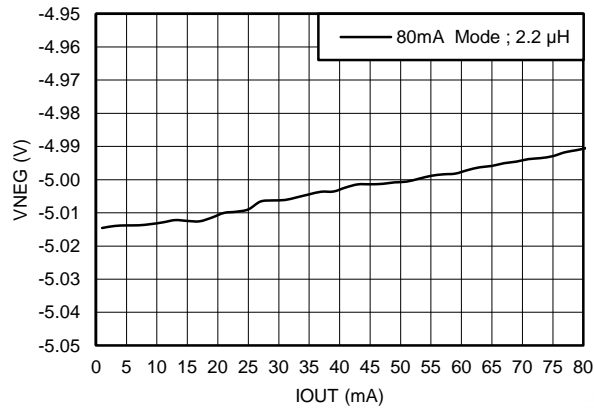


Figure 75. Load Regulation

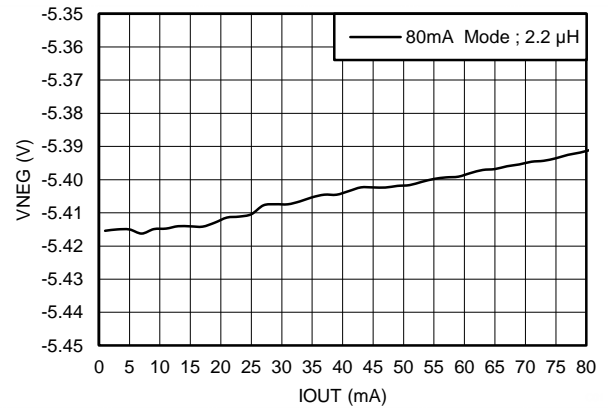


Figure 76. Load Regulation

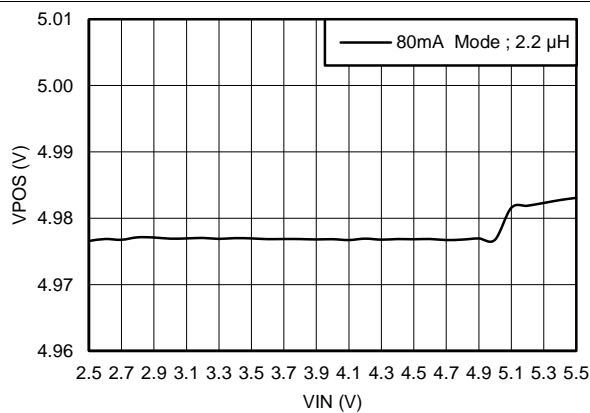


Figure 77. Line Regulation

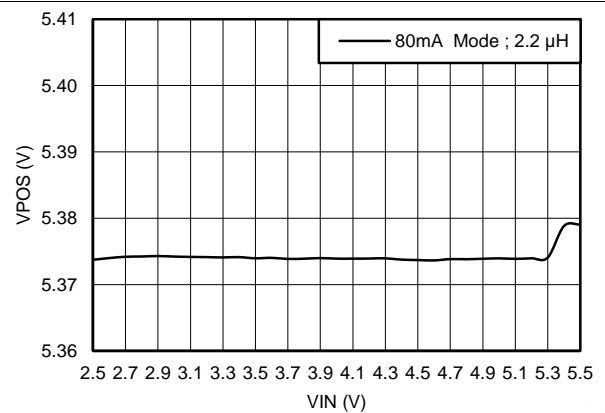


Figure 78. Line Regulation

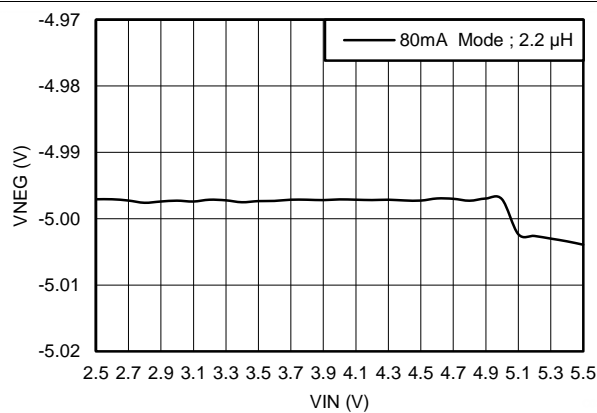


Figure 79. Line Regulation

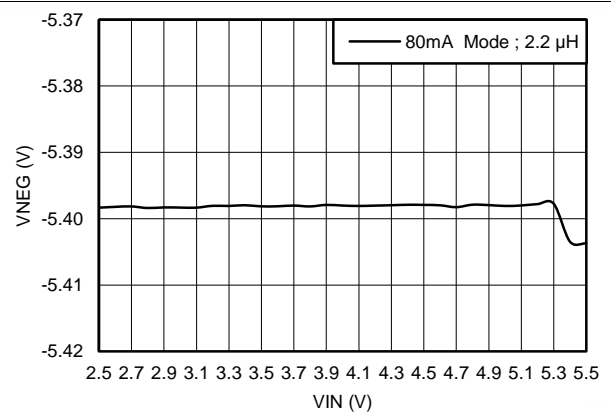
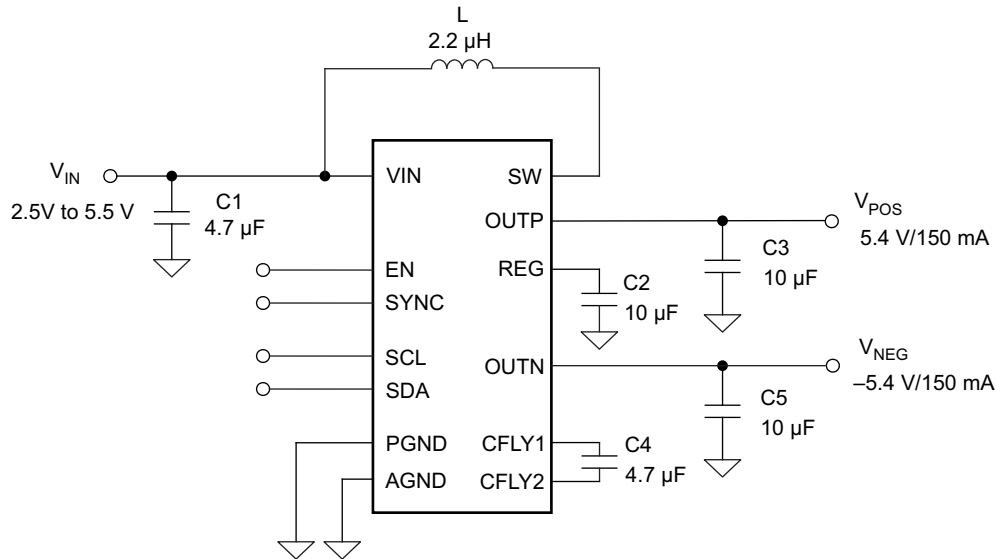


Figure 80. Line Regulation

### 9.2.3 High-current Applications ( $\leq 150$ mA)

The TPS65132Sx version allows output current up to 150 mA on both  $V_{POS}$  and  $V_{NEG}$  when the SYNC pin is pulled HIGH. If the SYNC pin is pulled LOW, the TPS65132Sx can be programmed to 40mA or 80mA mode with the APPS bit to lower the output current capability of the  $V_{NEG}$  rail if needed (in the case the efficiency is an important parameter). See [Low-current Applications \( \$\leq 40\$  mA\)](#) and [Mid-current Applications \( \$\leq 80\$  mA\)](#) for more details about the 40mA and 80mA modes.



**Figure 81. Typical Application Circuit For High Current**

#### 9.2.3.1 Design Requirements

**Table 16. Design Parameters**

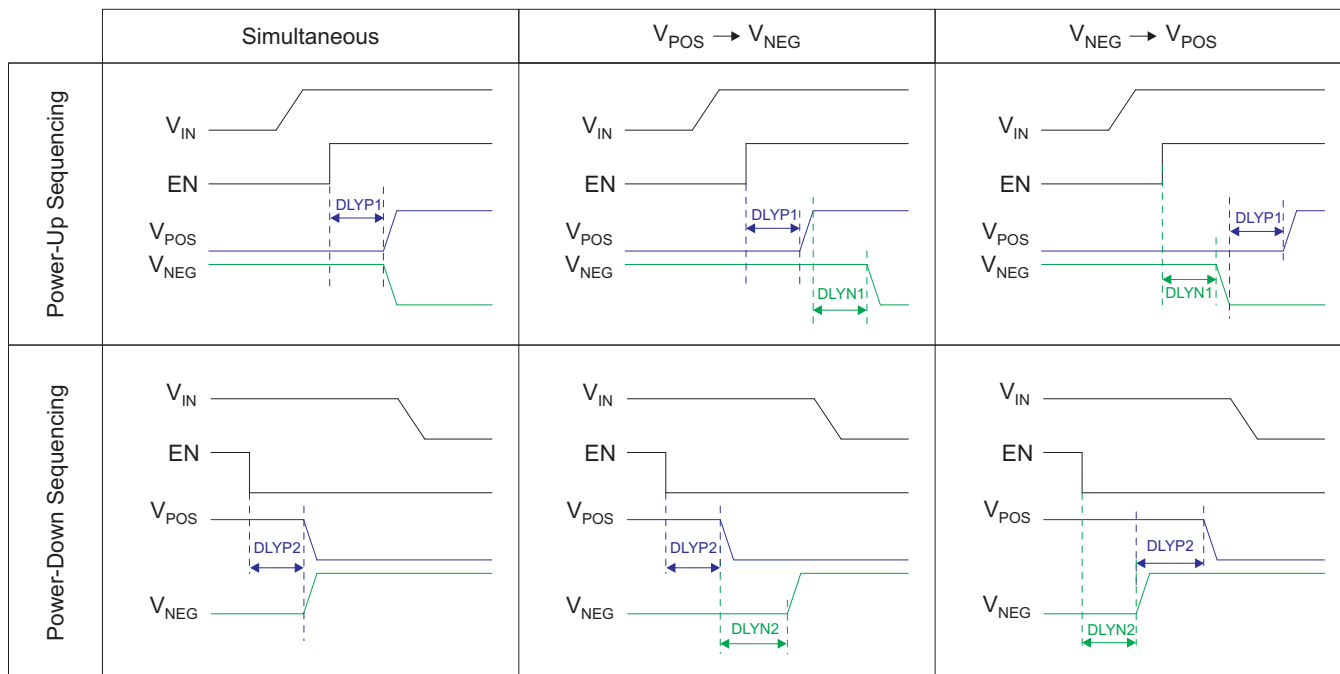
| PARAMETERS                               | EXAMPLE VALUES                   |
|--|----------------------------------|
| Input Voltage Range                      | 2.5 V to 5.5 V                   |
| Output Voltages                          | 4.0 V to 6.0 V, -4.0 V to -6.0 V |
| Output Current Rating                    | 150 mA                           |
| Boost Converter Switching Frequency      | 1.8 MHz                          |
| Negative Charge Pump Switching Frequency | 1.0 MHz                          |

#### 9.2.3.2 Detailed Design Procedure

The design procedure and BOM list of the TPS65132Sx is identical to the 80mA mode. Please refer to the [Mid-current Applications \( \$\leq 80\$  mA\)](#) for more details about the general component selection.

### 9.2.3.2.1 Sequencing

The output rails ( $V_{POS}$  and  $V_{NEG}$ ) are enabled and disabled using an external logic signal on the EN pin. The power-up and power-down sequencing events are programmable. Please refer to [Programmable Sequencing Scenarios](#) for the different sequencing as well as [Registers](#) for the programming options. [Figure 98](#) to [Figure 103](#) show the typical sequencing waveforms.



**Figure 82. Programmable Sequencing Scenarios**

#### NOTE

- In the case where the UVLO falling threshold is triggered while the enable signal is still HIGH (EN), all converters will be shut down instantaneously and both  $V_{POS}$  and  $V_{NEG}$  output rails will be actively discharged to GND.
- The power-up and power-down sequencing must be finalized (all delays have passed) before re-toggling the EN pin.

### 9.2.3.2.2 SYNC = HIGH

When the SYNC pin is pulled HIGH, the boost converter voltage increases instantaneously to allow enough headroom to deliver the 150 mA. See [Figure 88](#) to [Figure 91](#) for detailed waveforms.

When SYNC pin is pulled LOW, the boost converter keeps its offset for 300  $\mu$ s typically, and during this time, the device is still capable of supplying 150 mA on both output rail. After these 300  $\mu$ s have passed, current limit settles at 40 mA or 80 mA maximum, depending on the application mode it is programmed to (40mA or 80mA — see [Low-current Applications \( \$\leq 40\$  mA\)](#) and [Mid-current Applications \( \$\leq 80\$  mA\)](#) for more details ) and the boost output voltage regulates down to its nominal value.

### 9.2.3.2.3 Startup

The TPS65132Sx can startup with SYNC = HIGH, however, the boost offset as well as the 150 mA output current capability will only be available as soon as the last rail to start is in regulation.

### 9.2.3.3 Application Curves

 $V_{IN} = 3.7\text{ V}$ ,  $V_{POS} = 5.4\text{ V}$ ,  $V_{NEG} = -5.4\text{ V}$ , unless otherwise noted

**Table 17. Component List For Typical Characteristics Circuits**

| REFERENCE | DESCRIPTION  | MANUFACTURER AND PART NUMBER         |
|-----------|--|--------------------------------------|
| C         | 2.2 $\mu\text{F}$ , 16 V, 0603, X5R, ceramic                                       | Murata - GRM188R61C225KAAD           |
|           | 4.7 $\mu\text{F}$ , 16 V, 0603, X5R, ceramic                                       | Murata - GRM188R61C475KAAJ           |
|           | 10 $\mu\text{F}$ , 16 V, 0603, X5R, ceramic  | Murata - GRM188R61E106MA73           |
| L         | 2.2 $\mu\text{H}$ , 2.4 A, 130 m $\Omega$ , 2.5 mm $\times$ 2.0 mm $\times$ 1.0 mm | Toko - DFE252010C (1269AS-H-2R2N=P2) |
| U1        | TPS65132SYFF   | Texas Instruments                    |

**Table 18. Table Of Graphs**

| PARAMETER                     | CONDITIONS   | Figure                     |
|-------------------------------|--|----------------------------|
| <b>EFFICIENCY</b>             |  |                            |
| Efficiency vs. Output Current | $\pm 5.0\text{ V}$ — SYNC = HIGH — L = 2.2 $\mu\text{H}$   | <a href="#">Figure 83</a>  |
| Efficiency vs. Output Current | $\pm 5.4\text{ V}$ — SYNC = HIGH — L = 2.2 $\mu\text{H}$   | <a href="#">Figure 84</a>  |
| <b>CONVERTERS WAVEFORMS</b>   |  |                            |
| $V_{POS}$ Output Ripple       | $I_{POS} = 150\text{ mA}$ — SYNC = HIGH  | <a href="#">Figure 85</a>  |
| $V_{NEG}$ Output Ripple       | $I_{NEG} = 10\text{ mA} / 80\text{ mA} / 150\text{ mA}$ — SYNC = HIGH — $C_{OUT} = 10\text{ }\mu\text{F}$  | <a href="#">Figure 86</a>  |
| $V_{NEG}$ Output Ripple       | $I_{NEG} = 4\text{ mA} / 40\text{ mA} / 80\text{ mA}$ — SYNC = HIGH — $C_{OUT} = 2 \times 10\text{ }\mu\text{F}$                                       | <a href="#">Figure 87</a>  |
| <b>SYNC = HIGH Signal</b>     |  |                            |
| SYNC = HIGH                   | $I_{POS} = -I_{NEG} = 10\text{ mA}$  | <a href="#">Figure 88</a>  |
| SYNC = HIGH                   | $I_{POS} = -I_{NEG} = 150\text{ mA}$   | <a href="#">Figure 89</a>  |
| SYNC = HIGH Zoom              | $I_{POS} = -I_{NEG} = 10\text{ mA}$  | <a href="#">Figure 90</a>  |
| SYNC = LOW Zoom               | $I_{POS} = -I_{NEG} = 10\text{ mA}$  | <a href="#">Figure 91</a>  |
| <b>LOAD TRANSIENT</b>         |  |                            |
| Load Transient                | $V_{IN} = 2.9\text{ V}$ — $I_{POS} = -I_{NEG} = 10\text{ mA} \rightarrow 150\text{ mA} \rightarrow 10\text{ mA}$ — SYNC = HIGH — L = 2.2 $\mu\text{H}$ | <a href="#">Figure 92</a>  |
| Load Transient                | $V_{IN} = 3.7\text{ V}$ — $I_{POS} = -I_{NEG} = 10\text{ mA} \rightarrow 150\text{ mA} \rightarrow 10\text{ mA}$ — SYNC = HIGH — L = 2.2 $\mu\text{H}$ | <a href="#">Figure 93</a>  |
| Load Transient                | $V_{IN} = 4.5\text{ V}$ — $I_{POS} = -I_{NEG} = 10\text{ mA} \rightarrow 150\text{ mA} \rightarrow 10\text{ mA}$ — SYNC = HIGH — L = 2.2 $\mu\text{H}$ | <a href="#">Figure 94</a>  |
| <b>LINE TRANSIENT</b>         |  |                            |
| Line Transient                | $V_{IN} = 2.8\text{ V} \rightarrow 4.5\text{ V} \rightarrow 2.8\text{ V}$ — $I_{POS} = -I_{NEG} = 10\text{ mA}$ — SYNC = HIGH — L = 2.2 $\mu\text{H}$  | <a href="#">Figure 95</a>  |
| Line Transient                | $V_{IN} = 2.8\text{ V} \rightarrow 4.5\text{ V} \rightarrow 2.8\text{ V}$ — $I_{POS} = -I_{NEG} = 100\text{ mA}$ — SYNC = HIGH — L = 2.2 $\mu\text{H}$ | <a href="#">Figure 96</a>  |
| Line Transient                | $V_{IN} = 2.8\text{ V} \rightarrow 4.5\text{ V} \rightarrow 2.8\text{ V}$ — $I_{POS} = -I_{NEG} = 150\text{ mA}$ — SYNC = HIGH — L = 2.2 $\mu\text{H}$ | <a href="#">Figure 97</a>  |
| <b>POWER SEQUENCING</b>       |  |                            |
| Power-up Sequencing           | Simultaneous — no load   | <a href="#">Figure 98</a>  |
| Power-down Sequencing         | Simultaneous — no load with Active Discharge   | <a href="#">Figure 99</a>  |
| Power-up Sequencing           | Sequential ( $V_{POS} \rightarrow V_{NEG}$ ) — no load   | <a href="#">Figure 100</a> |
| Power-down Sequencing         | Sequential ( $V_{NEG} \rightarrow V_{POS}$ ) — no load with Active Discharge   | <a href="#">Figure 101</a> |
| Power-up Sequencing           | Sequential ( $V_{NEG} \rightarrow V_{POS}$ ) — no load   | <a href="#">Figure 102</a> |
| Power-down Sequencing         | Sequential ( $V_{POS} \rightarrow V_{NEG}$ ) — no load with Active Discharge   | <a href="#">Figure 103</a> |

**Table 18. Table Of Graphs (continued)**

| PARAMETER                          | CONDITIONS   | Figure                     |
|------------------------------------|--|----------------------------|
| Power-up/down Sequencing           | Simultaneous — no load without Active Discharge  | <a href="#">Figure 104</a> |
| Power-up/down Sequencing           | Simultaneous — no load with Active Discharge   | <a href="#">Figure 105</a> |
| <b>INRUSH CURRENT</b>              |  |                            |
| Inrush Current                     | Simultaneous — no load — SYNC = HIGH — L = 2.2 $\mu$ H   | <a href="#">Figure 106</a> |
| Inrush Current                     | Sequential — no load — SYNC = HIGH — L = 2.2 $\mu$ H   | <a href="#">Figure 107</a> |
| <b>LOAD REGULATION</b>             |  |                            |
| V <sub>POS</sub> vs Output Current | V <sub>POS</sub> = 5.0 V — SYNC = HIGH — I <sub>POS</sub> = 0 mA to 150 mA — L = 2.2 $\mu$ H                             | <a href="#">Figure 108</a> |
| V <sub>POS</sub> vs Output Current | V <sub>POS</sub> = 5.4 V — SYNC = HIGH — I <sub>POS</sub> = 0 mA to 150 mA — L = 2.2 $\mu$ H                             | <a href="#">Figure 109</a> |
| V <sub>NEG</sub> vs Output Current | V <sub>NEG</sub> = -5.0 V — SYNC = HIGH — I <sub>NEG</sub> = 0 mA to 150 mA — L = 2.2 $\mu$ H                            | <a href="#">Figure 110</a> |
| V <sub>NEG</sub> vs Output Current | V <sub>NEG</sub> = -5.4 V — SYNC = HIGH — I <sub>NEG</sub> = 0 mA to 150 mA — L = 2.2 $\mu$ H                            | <a href="#">Figure 111</a> |
| <b>LINE REGULATION</b>             |  |                            |
| V <sub>POS</sub> vs Output Voltage | V <sub>IN</sub> = 2.5 V to 5.5 V — V <sub>POS</sub> = 5.0 V — SYNC = HIGH — I <sub>POS</sub> = 120 mA — L = 2.2 $\mu$ H  | <a href="#">Figure 112</a> |
| V <sub>POS</sub> vs Output Voltage | V <sub>IN</sub> = 2.5 V to 5.5 V — V <sub>POS</sub> = 5.4 V — SYNC = HIGH — I <sub>POS</sub> = 120 mA — L = 2.2 $\mu$ H  | <a href="#">Figure 113</a> |
| V <sub>NEG</sub> vs Output Voltage | V <sub>IN</sub> = 2.5 V to 5.5 V — V <sub>NEG</sub> = -5.0 V — SYNC = HIGH — I <sub>NEG</sub> = 120 mA — L = 2.2 $\mu$ H | <a href="#">Figure 114</a> |
| V <sub>NEG</sub> vs Output Voltage | V <sub>IN</sub> = 2.5 V to 5.5 V — V <sub>NEG</sub> = -5.4 V — SYNC = HIGH — I <sub>NEG</sub> = 120 mA — L = 2.2 $\mu$ H | <a href="#">Figure 115</a> |

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**NOTE**

In this section, I<sub>OUT</sub> means that the outputs are loaded with I<sub>POS</sub> = -I<sub>NEG</sub> simultaneously.

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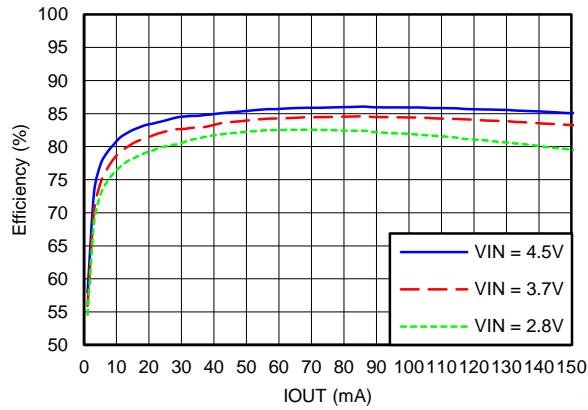


Figure 83. Combined Efficiency — ± 5.0 V — SYNC = HIGH  
L = 2.2 μH

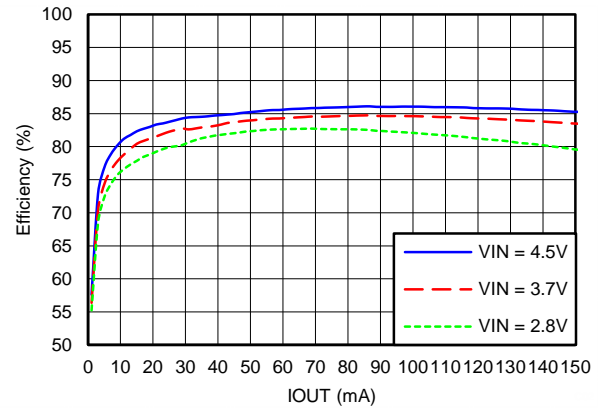


Figure 84. Combined Efficiency — ± 5.4 V — SYNC = HIGH  
L = 2.2 μH

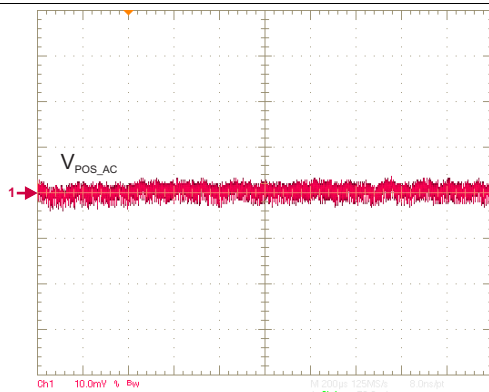


Figure 85. V<sub>POS</sub> Output Voltage Ripple — SYNC = HIGH

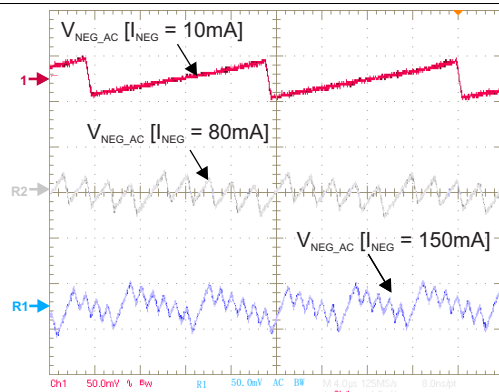


Figure 86. V<sub>NEG</sub> Output Voltage Ripple — SYNC = HIGH —  
L = 2.2 μH — C<sub>OUT</sub> = 10 μF

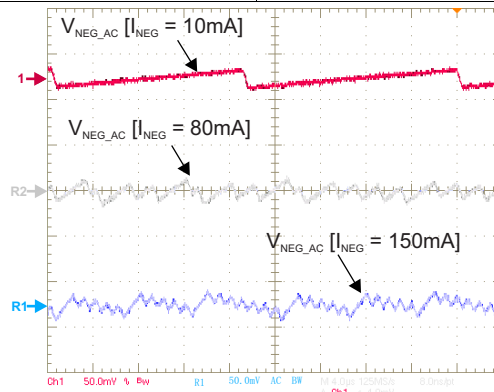


Figure 87. V<sub>NEG</sub> Output Voltage Ripple — SYNC = HIGH —  
L = 2.2 μH — C<sub>OUT</sub> = 2 × 10 μF



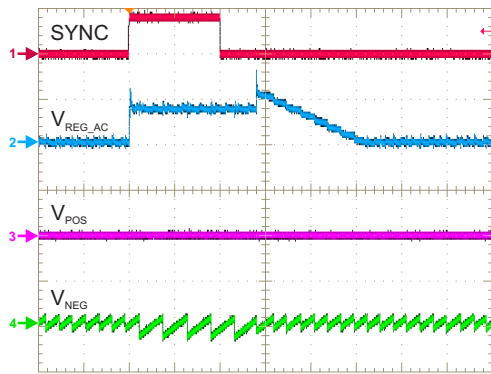


Figure 88. SYNC Signal —  $I_{OUT} = 10 \text{ mA}$

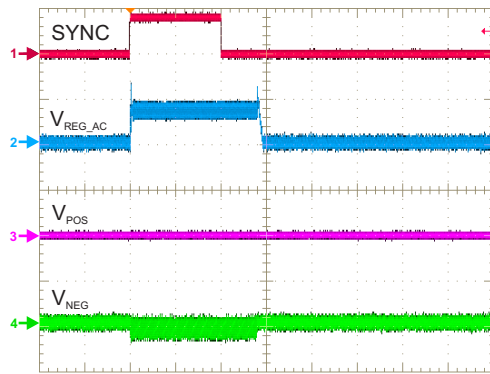


Figure 89. SYNC Signal —  $I_{OUT} = 150 \text{ mA}$

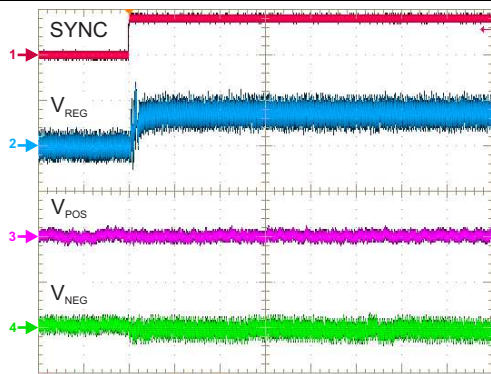


Figure 90. SYNC = HIGH (zoom)

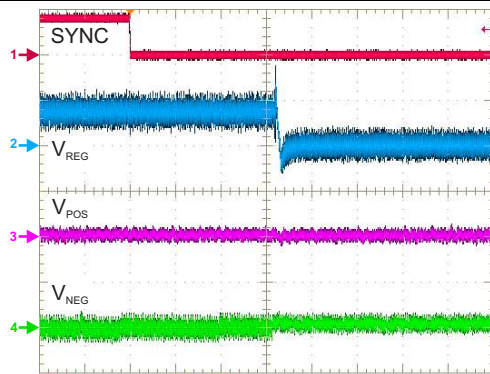


Figure 91. SYNC = LOW (zoom) with Delay

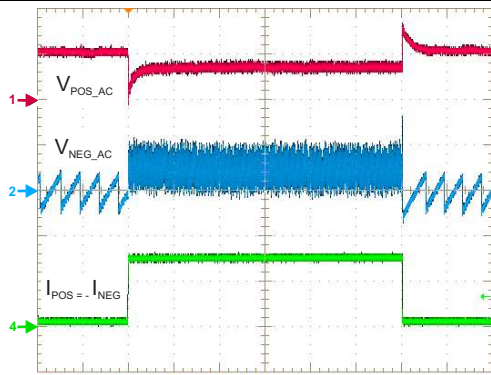


Figure 92. Load Transient —  $V_{IN} = 2.9 \text{ V}$   
SYNC = HIGH —  $\Delta I_{OUT} = 140 \text{ mA}$

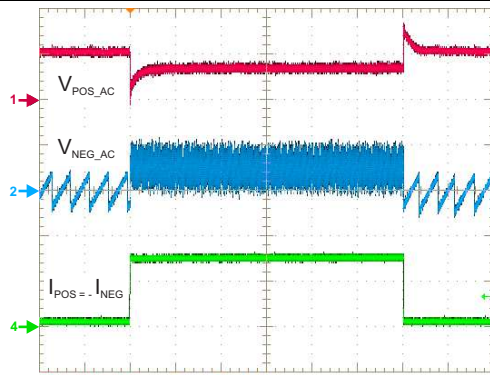


Figure 93. Load Transient —  $V_{IN} = 3.7 \text{ V}$   
SYNC = HIGH —  $\Delta I_{OUT} = 140 \text{ mA}$

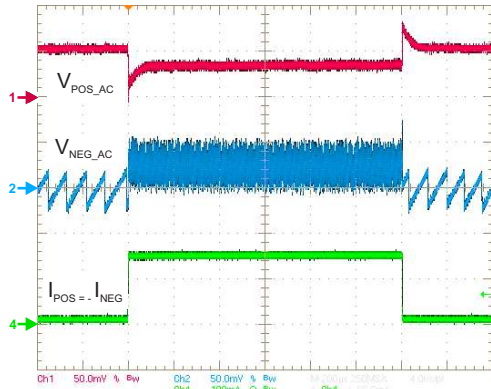


Figure 94. Load Transient —  $V_{IN} = 4.5\text{ V}$   
 SYNC = HIGH —  $\Delta I_{OUT} = 140\text{ mA}$

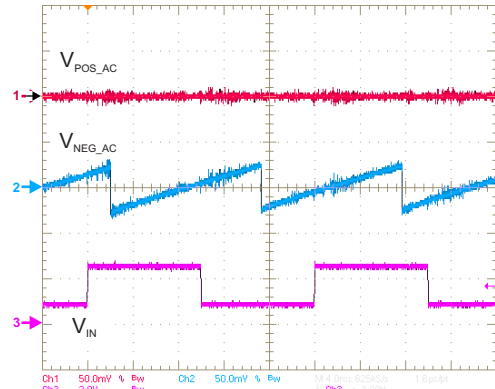


Figure 95. Line Transient —  $I_{OUT} = 10\text{ mA}$   
 SYNC = HIGH —  $\Delta V_{IN} = 1.7\text{ V}$

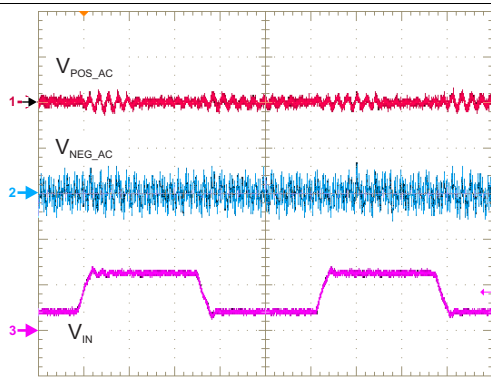


Figure 96. Line Transient —  $I_{OUT} = 100\text{ mA}$   
 SYNC = HIGH —  $\Delta V_{IN} = 1.7\text{ V}$

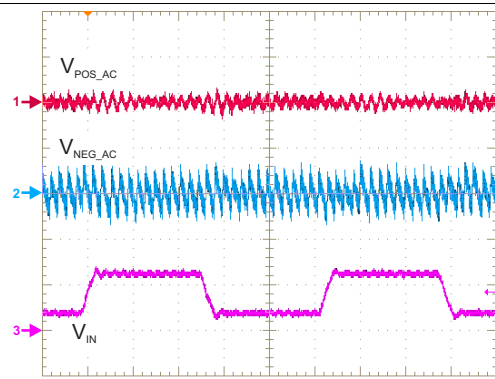


Figure 97. Line Transient —  $I_{OUT} = 150\text{ mA}$   
 SYNC = HIGH —  $\Delta V_{IN} = 1.7\text{ V}$

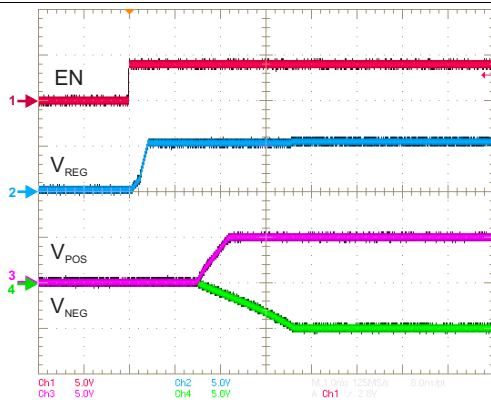


Figure 98. Power-Up Sequencing — Simultaneous  
 SYNC = HIGH

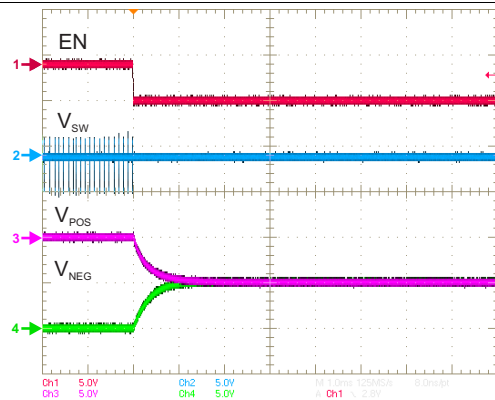


Figure 99. Power-Down Sequencing — Simultaneous  
 SYNC = HIGH

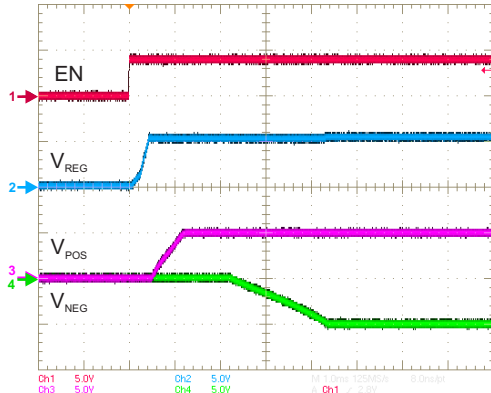


Figure 100. Power-Up Sequencing — Sequential VPOS → VNEG — SYNC = HIGH

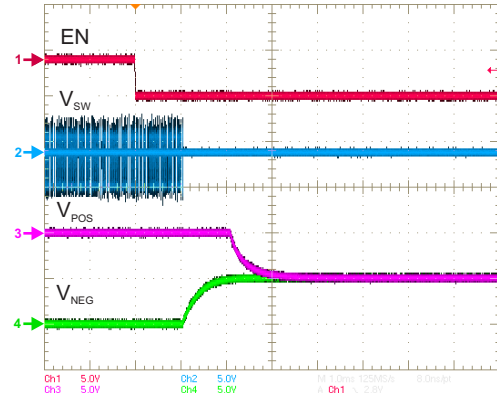


Figure 101. Power-Down Sequencing — Sequential VNEG → VPOS — SYNC = HIGH

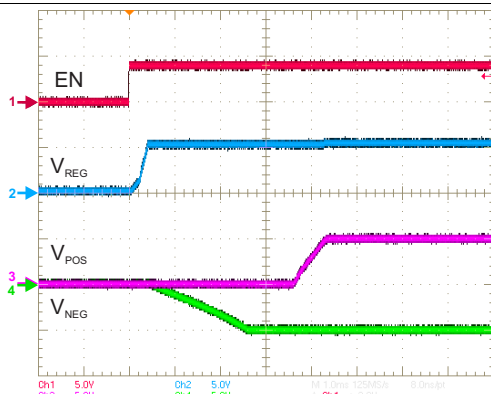


Figure 102. Power-Up Sequencing — Sequential VNEG → VPOS — SYNC = HIGH

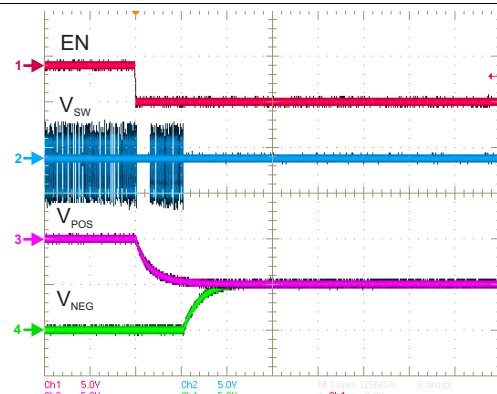


Figure 103. Power-Down Sequencing — Sequential VPOS → VNEG — SYNC = HIGH

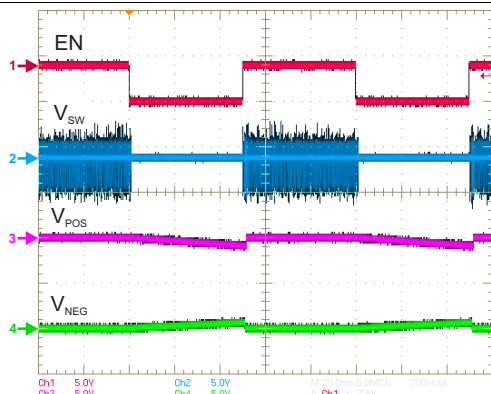


Figure 104. Power-Up/Down Without Active Discharge — SYNC = HIGH

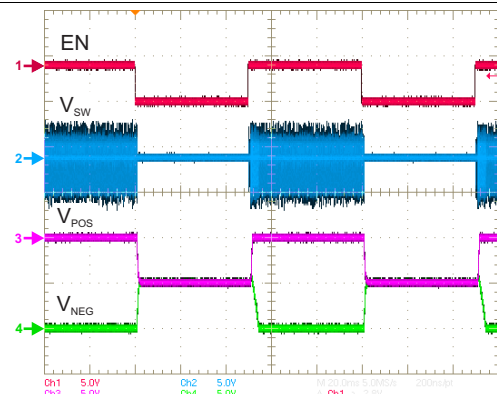


Figure 105. Power-Up/Down With Active Discharge — SYNC = HIGH

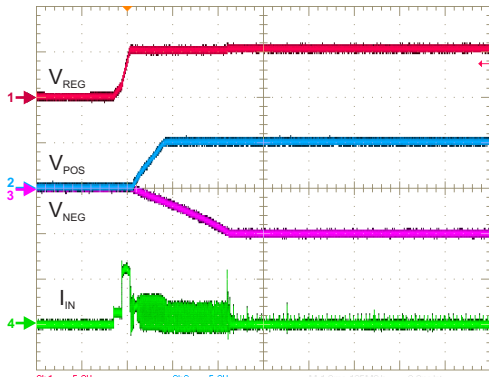


Figure 106. Inrush Current — Simultaneous — SYNC = HIGH

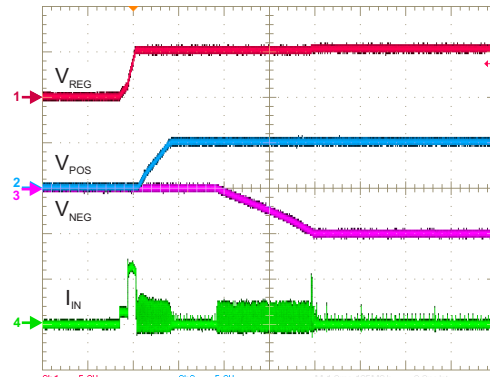


Figure 107. Inrush Current — Sequential SYNC = HIGH

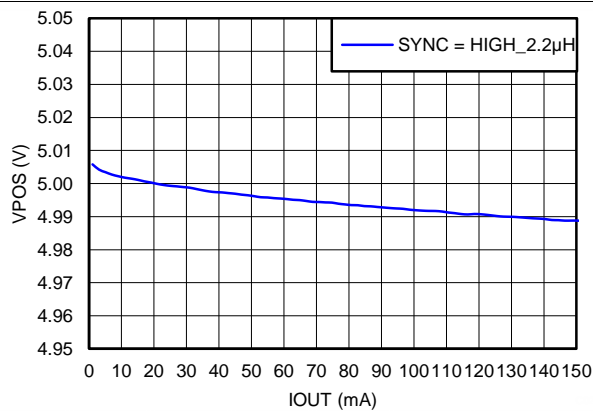


Figure 108. Load Regulation V<sub>POS</sub> = 5.0 V — SYNC = HIGH

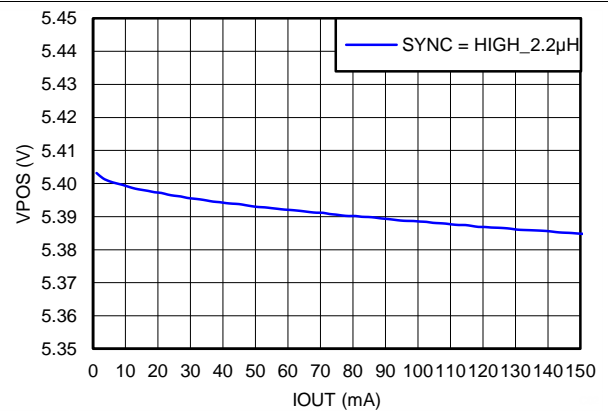


Figure 109. Load Regulation V<sub>POS</sub> = 5.4 V — SYNC = HIGH

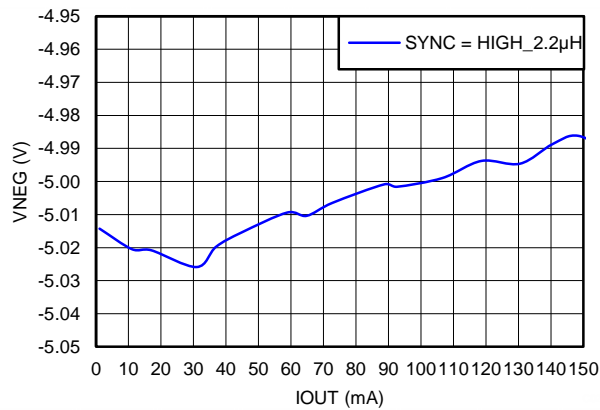


Figure 110. Load Regulation V<sub>NEG</sub> = -5.0 V — SYNC = HIGH

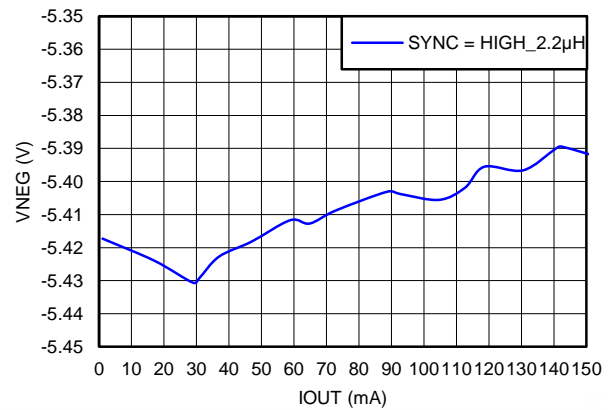


Figure 111. Load Regulation V<sub>NEG</sub> = -5.4 V — SYNC = HIGH

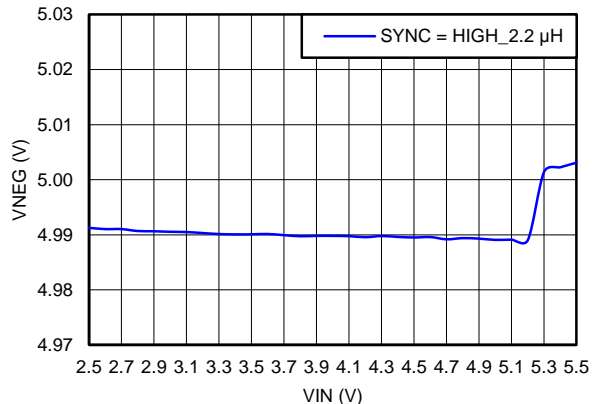


Figure 112. Line Regulation V<sub>POS</sub> = 5.0 V — SYNC = HIGH

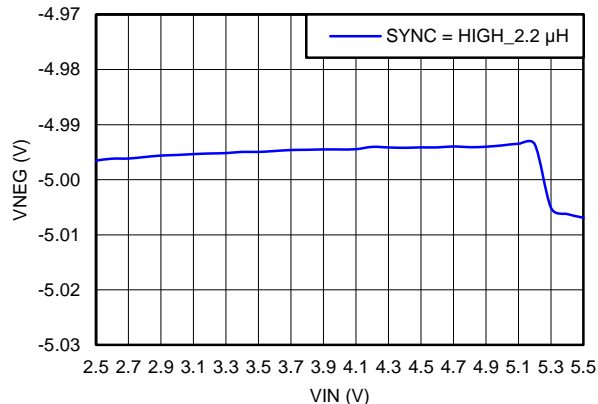


Figure 113. Line Regulation V<sub>POS</sub> = 5.4 V — SYNC = HIGH

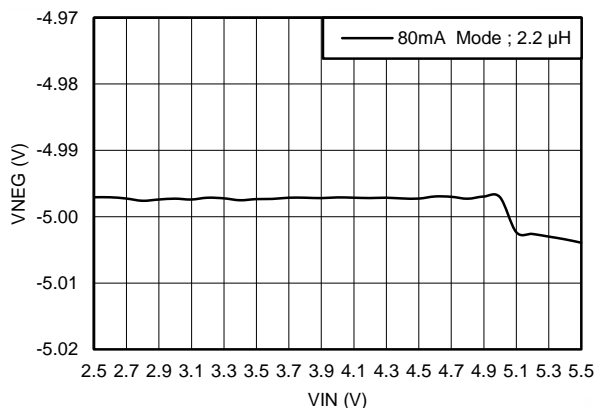


Figure 114. Line Regulation V<sub>NEG</sub> = -5.0 V — SYNC = HIGH

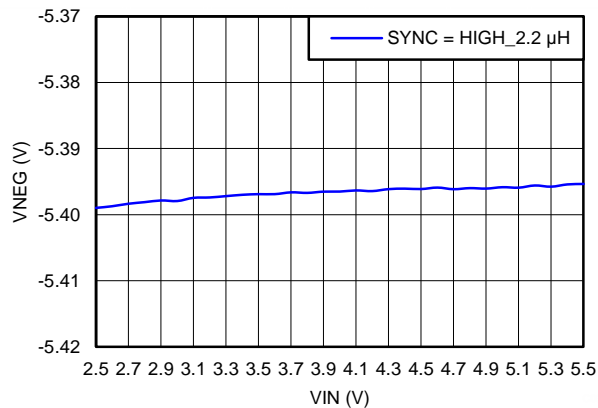


Figure 115. Line Regulation V<sub>NEG</sub> = -5.4 V — SYNC = HIGH

## 10 Power Supply Recommendations

The devices are designed to operate from an input voltage supply range between 2.5 V and 5.5 V. This input supply must be well regulated. A ceramic input capacitor with a value of 4.7  $\mu$ F is a typical choice.

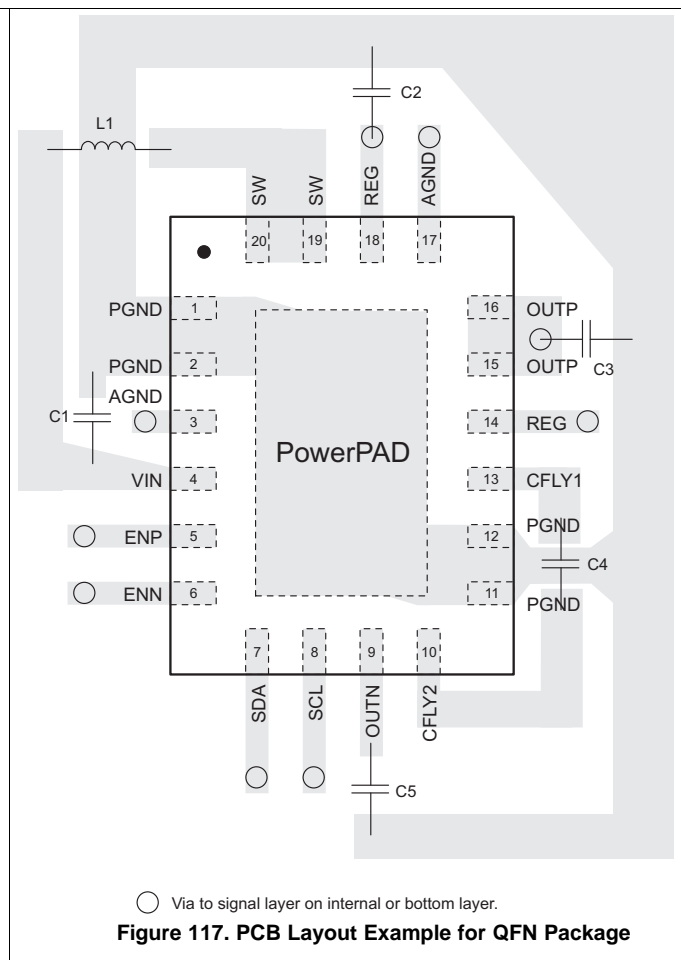
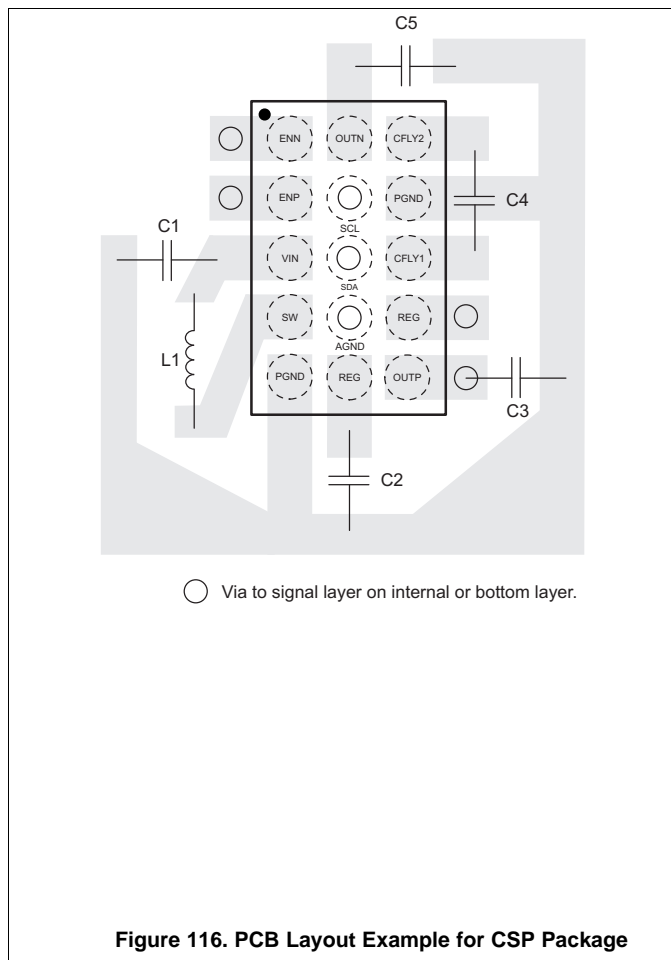
## 11 Layout

### 11.1 Layout Guidelines

PCB layout is an important task in the power supply design. Good PCB layout minimizes EMI and allows very good output voltage regulation. For the TPS65132 the following PCB layout guidelines are recommended.

- **Keep the power ground plane on the top layer (all capacitor grounds and PGND pins must be connected together with one uninterrupted ground plane).**
- **AGND and PGND must be connected together on the same ground plane.**
- **Place the flying capacitor as close as possible to the IC.**
- Always avoid vias when possible. They have high inductance and resistance. **If vias are necessary, always use more than one in parallel to decrease parasitics especially for power lines.**
- **Connect REG pins together.**
- For **high dv/dt** signals (switch pin traces): keep copper area to a minimum to prevent making unintentional parallel plate capacitors with other traces or to a ground plane. Best to route signal and return on same layer.
- For **high di/dt** signals: keep traces short, wide and closely spaced. This will reduce stray inductance and decrease the current loop area to help prevent EMI.
- Keep input capacitor close to the IC with low inductance traces.
- Keep trace from switching node pin to inductor short if possible: **it reduces EMI emissions and noise that may couple into other portions of the converter.**
- Isolate analog signal paths from power paths.

### 11.2 Layout Example



## 12 デバイスおよびドキュメントのサポート

### 12.1 デバイス・サポート

#### 12.1.1 デベロッパー・ネットワークの製品に関する免責事項

デベロッパー・ネットワークの製品またはサービスに関するTIの出版物は、単独またはTIの製品、サービスと一緒に提供される場合に関係なく、デベロッパー・ネットワークの製品またはサービスの適合性に関する是認、デベロッパー・ネットワークの製品またはサービスの是認の表明を意味するものではありません。

### 12.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、[ti.com](http://ti.com)のデバイス製品フォルダを開いてください。右上の隅にある「通知を受け取る」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

### 12.3 コミュニティ・リソース

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](http://e2e.ti.com), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 12.4 商標

E2E is a trademark of Texas Instruments.  
All other trademarks are the property of their respective owners.

### 12.5 静電気放電に関する注意事項



これらのデバイスは、限定的なESD(静電破壊)保護機能を内蔵しています。保存時または取り扱い時は、MOSゲートに対する静電破壊を防止するために、リード線同士をショートさせておくか、デバイスを導電フォームに入れる必要があります。

### 12.6 Glossary

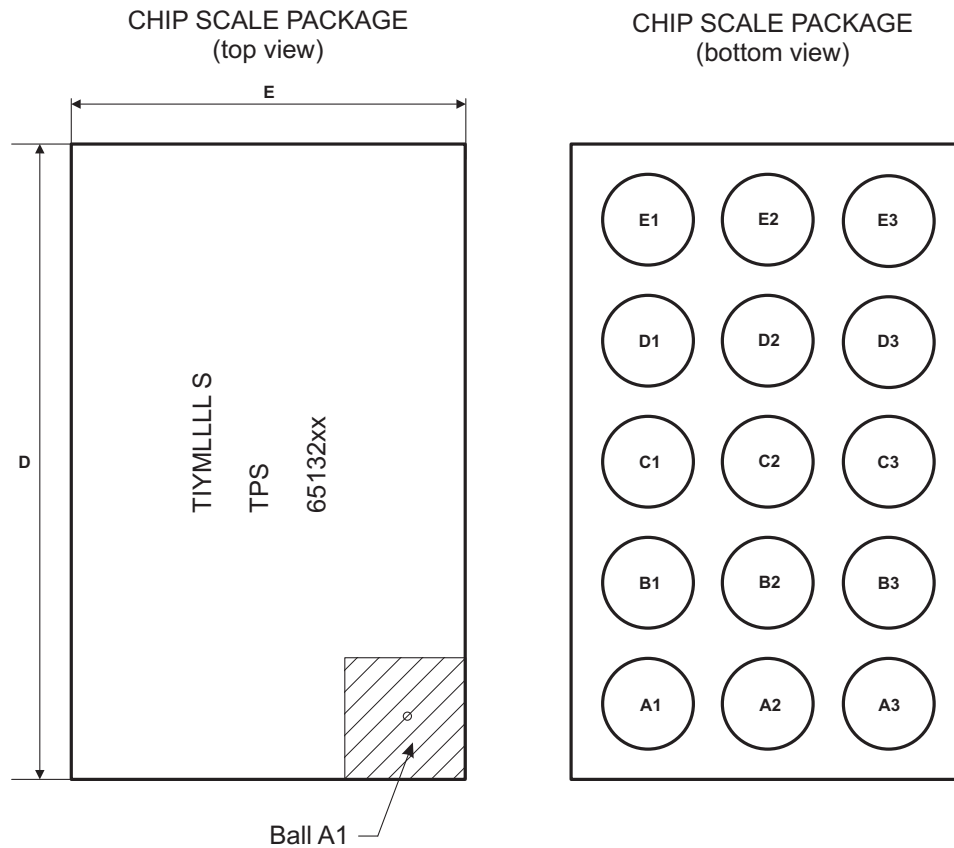
[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 13 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。これらの情報は、指定のデバイスに対して提供されている最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もあります。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。

### 13.1 CSPパッケージの概要


**Code:**

- TI -- TI letters
- YM -- Year-Month date code
- LLLL -- Lot trace code
- S -- Assembly site code
- xx -- Revision code (contains alpha-numeric characters - can be left blank), refer to the Ordering Information section for detailed information)

#### 13.1.1 チップ・スケール・パッケージの寸法

TPS65132 デバイスは、15バンプのチップスケール・パッケージ (YFF、NanoFree™) で供給されます。パッケージの寸法を次に示します。

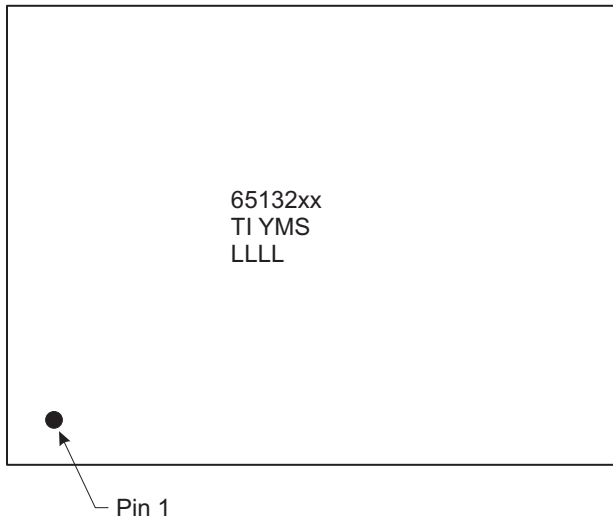
- D = 2108 ±30µm
- E = 1514 ±30µm



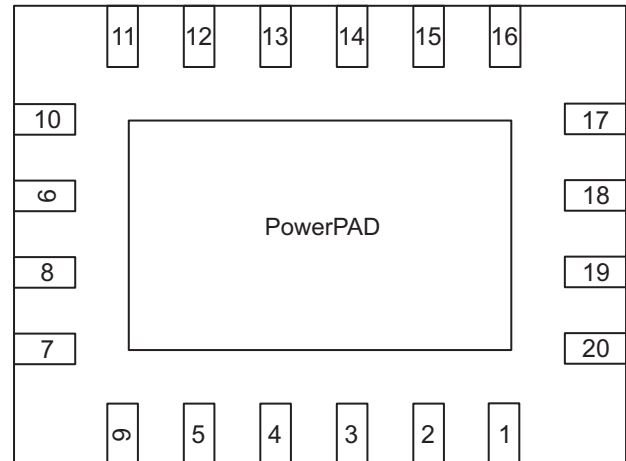
## CSPパッケージの概要 (continued)

### 13.1.2 RVCパッケージの概要

QFN PACKAGE  
(top view)



QFN PACKAGE  
(bottom view)



#### Code:

- TI -- TI letters
- YM -- Year-Month date code
- LLLL -- Lot trace code
- S -- Assembly site code
- xx -- Revision code (contains alpha-numeric characters - can be left blank), refer to the Ordering Information section for detailed information)

**PACKAGING INFORMATION**

| Orderable Device | Status<br>(1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan<br>(2) | Lead finish/<br>Ball material<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|-----------------|------|-------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| TPS65132A0YFFR   | ACTIVE        | DSBGA        | YFF             | 15   | 3000        | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 85    | TPS<br>65132A0          | <a href="#">Samples</a> |
| TPS65132AYFFR    | ACTIVE        | DSBGA        | YFF             | 15   | 3000        | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 85    | TPS<br>65132A           | <a href="#">Samples</a> |
| TPS65132B0YFFR   | ACTIVE        | DSBGA        | YFF             | 15   | 3000        | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 85    | TPS<br>65132B0          | <a href="#">Samples</a> |
| TPS65132B2YFFR   | ACTIVE        | DSBGA        | YFF             | 15   | 3000        | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 85    | TPS<br>65132B2          | <a href="#">Samples</a> |
| TPS65132B5YFFR   | ACTIVE        | DSBGA        | YFF             | 15   | 3000        | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 85    | TPS<br>65132B5          | <a href="#">Samples</a> |
| TPS65132BYFFR    | ACTIVE        | DSBGA        | YFF             | 15   | 3000        | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 85    | TPS<br>65132B           | <a href="#">Samples</a> |
| TPS65132L0YFFR   | ACTIVE        | DSBGA        | YFF             | 15   | 3000        | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 85    | TPS<br>65132L0          | <a href="#">Samples</a> |
| TPS65132L0YFFT   | ACTIVE        | DSBGA        | YFF             | 15   | 250         | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 85    | TPS<br>65132L0          | <a href="#">Samples</a> |
| TPS65132LYFFR    | ACTIVE        | DSBGA        | YFF             | 15   | 3000        | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 85    | TPS<br>65132L           | <a href="#">Samples</a> |
| TPS65132SYFFR    | ACTIVE        | DSBGA        | YFF             | 15   | 3000        | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 85    | TPS<br>65132S           | <a href="#">Samples</a> |
| TPS65132T6YFFR   | ACTIVE        | DSBGA        | YFF             | 15   | 3000        | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 85    | TPS<br>65132T6          | <a href="#">Samples</a> |
| TPS65132T6YFFT   | ACTIVE        | DSBGA        | YFF             | 15   | 250         | RoHS & Green    | SNAGCU                               | Level-1-260C-UNLIM   | -40 to 85    | TPS<br>65132T6          | <a href="#">Samples</a> |
| TPS65132WRVCR    | ACTIVE        | WQFN         | RVC             | 20   | 3000        | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -40 to 85    | 65132YA                 | <a href="#">Samples</a> |
| TPS65132WRVCT    | ACTIVE        | WQFN         | RVC             | 20   | 250         | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -40 to 85    | 65132YA                 | <a href="#">Samples</a> |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSELETE:** TI has discontinued the production of the device.

<sup>(2)</sup> **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of  $\leq 1000$ ppm threshold. Antimony trioxide based flame retardants must also meet the  $\leq 1000$ ppm threshold requirement.

<sup>(3)</sup> **MSL, Peak Temp.** - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> **Lead finish/Ball material** - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

| Device         | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPS65132A0YFFR | DSBGA        | YFF             | 15   | 3000 | 180.0              | 8.4                | 1.61    | 2.21    | 0.7     | 4.0     | 8.0    | Q1            |
| TPS65132AYFFR  | DSBGA        | YFF             | 15   | 3000 | 180.0              | 8.4                | 1.61    | 2.21    | 0.7     | 4.0     | 8.0    | Q1            |
| TPS65132B0YFFR | DSBGA        | YFF             | 15   | 3000 | 180.0              | 8.4                | 1.61    | 2.21    | 0.7     | 4.0     | 8.0    | Q1            |
| TPS65132B2YFFR | DSBGA        | YFF             | 15   | 3000 | 180.0              | 8.4                | 1.61    | 2.21    | 0.7     | 4.0     | 8.0    | Q1            |
| TPS65132B5YFFR | DSBGA        | YFF             | 15   | 3000 | 180.0              | 8.4                | 1.61    | 2.21    | 0.7     | 4.0     | 8.0    | Q1            |
| TPS65132BYFFR  | DSBGA        | YFF             | 15   | 3000 | 180.0              | 8.4                | 1.61    | 2.21    | 0.7     | 4.0     | 8.0    | Q1            |
| TPS65132L0YFFR | DSBGA        | YFF             | 15   | 3000 | 180.0              | 8.4                | 1.61    | 2.21    | 0.7     | 4.0     | 8.0    | Q1            |
| TPS65132L0YFFT | DSBGA        | YFF             | 15   | 250  | 180.0              | 8.4                | 1.61    | 2.21    | 0.7     | 4.0     | 8.0    | Q1            |
| TPS65132LYFFR  | DSBGA        | YFF             | 15   | 3000 | 180.0              | 8.4                | 1.61    | 2.21    | 0.7     | 4.0     | 8.0    | Q1            |
| TPS65132SYFFR  | DSBGA        | YFF             | 15   | 3000 | 180.0              | 8.4                | 1.61    | 2.21    | 0.7     | 4.0     | 8.0    | Q1            |
| TPS65132T6YFFR | DSBGA        | YFF             | 15   | 3000 | 180.0              | 8.4                | 1.61    | 2.21    | 0.7     | 4.0     | 8.0    | Q1            |
| TPS65132T6YFFT | DSBGA        | YFF             | 15   | 250  | 180.0              | 8.4                | 1.61    | 2.21    | 0.7     | 4.0     | 8.0    | Q1            |
| TPS65132WRVCR  | WQFN         | RVC             | 20   | 3000 | 330.0              | 12.4               | 3.3     | 4.3     | 1.1     | 8.0     | 12.0   | Q1            |
| TPS65132WRVCT  | WQFN         | RVC             | 20   | 250  | 180.0              | 12.4               | 3.3     | 4.3     | 1.1     | 8.0     | 12.0   | Q1            |

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

| Device         | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPS65132A0YFFR | DSBGA        | YFF             | 15   | 3000 | 182.0       | 182.0      | 20.0        |
| TPS65132AYFFR  | DSBGA        | YFF             | 15   | 3000 | 182.0       | 182.0      | 20.0        |
| TPS65132B0YFFR | DSBGA        | YFF             | 15   | 3000 | 182.0       | 182.0      | 20.0        |
| TPS65132B2YFFR | DSBGA        | YFF             | 15   | 3000 | 182.0       | 182.0      | 20.0        |
| TPS65132B5YFFR | DSBGA        | YFF             | 15   | 3000 | 182.0       | 182.0      | 20.0        |
| TPS65132BYFFR  | DSBGA        | YFF             | 15   | 3000 | 182.0       | 182.0      | 20.0        |
| TPS65132L0YFFR | DSBGA        | YFF             | 15   | 3000 | 182.0       | 182.0      | 20.0        |
| TPS65132L0YFFT | DSBGA        | YFF             | 15   | 250  | 182.0       | 182.0      | 20.0        |
| TPS65132LYFFR  | DSBGA        | YFF             | 15   | 3000 | 182.0       | 182.0      | 20.0        |
| TPS65132SYFFR  | DSBGA        | YFF             | 15   | 3000 | 182.0       | 182.0      | 20.0        |
| TPS65132T6YFFR | DSBGA        | YFF             | 15   | 3000 | 182.0       | 182.0      | 20.0        |
| TPS65132T6YFFT | DSBGA        | YFF             | 15   | 250  | 182.0       | 182.0      | 20.0        |
| TPS65132WRVCR  | WQFN         | RVC             | 20   | 3000 | 552.0       | 346.0      | 36.0        |
| TPS65132WRVCT  | WQFN         | RVC             | 20   | 250  | 552.0       | 185.0      | 36.0        |

**TUBE**


\*All dimensions are nominal

| Device        | Package Name | Package Type | Pins | SPQ  | L (mm) | W (mm) | T (μm) | B (mm) |
|---------------|--------------|--------------|------|------|--------|--------|--------|--------|
| TPS65132WRVCR | RVC          | WQFN         | 20   | 3000 | 381    | 4.83   | 2286   | 0      |
| TPS65132WRVCT | RVC          | WQFN         | 20   | 250  | 381    | 4.83   | 2286   | 0      |

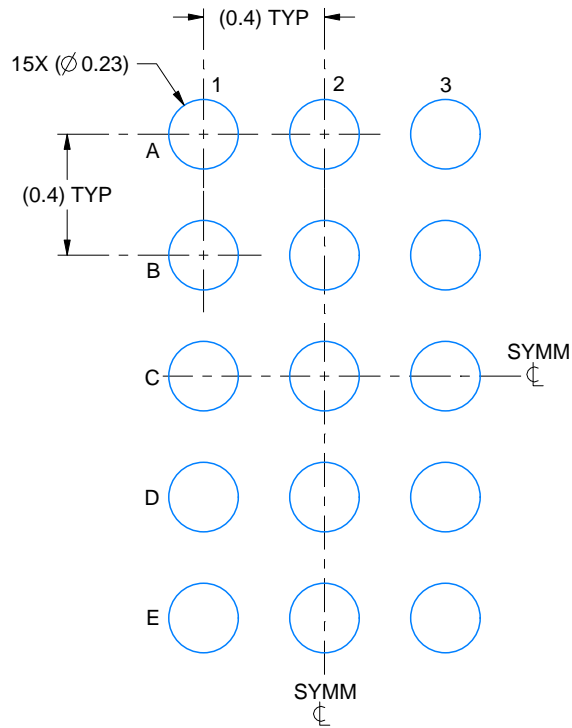


# EXAMPLE BOARD LAYOUT

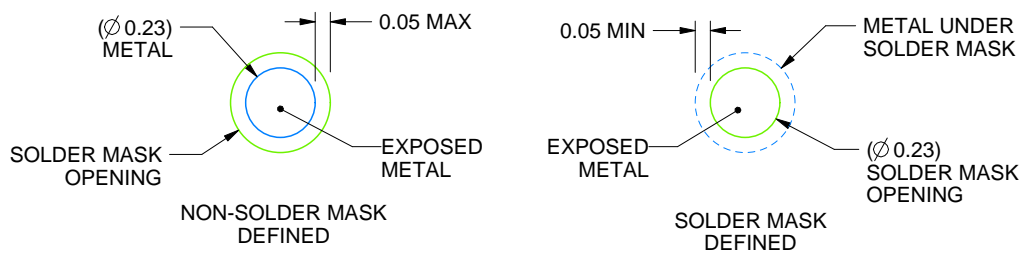
YFF0015

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:40X



SOLDER MASK DETAILS  
NOT TO SCALE

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NOTES: (continued)

- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 ([www.ti.com/lit/snva009](http://www.ti.com/lit/snva009)).

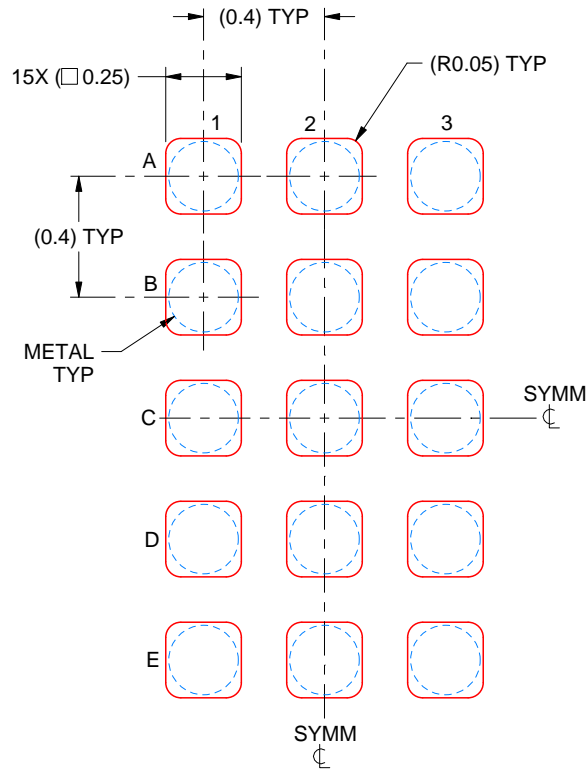


# EXAMPLE STENCIL DESIGN

YFF0015

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



SOLDER PASTE EXAMPLE  
BASED ON 0.1 mm THICK STENCIL  
SCALE:40X

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NOTES: (continued)

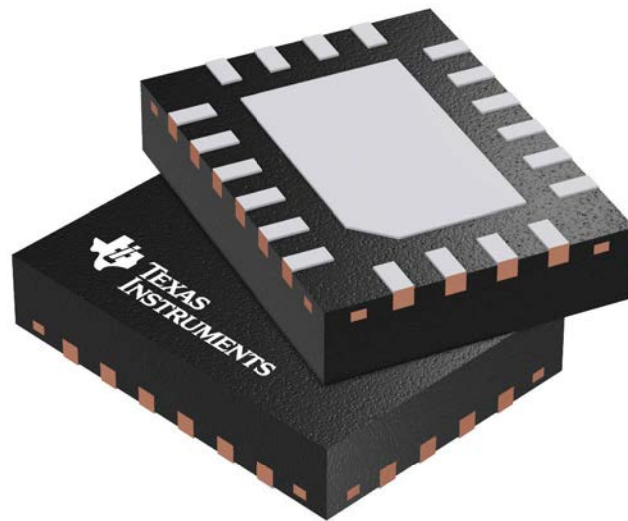
4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

RVC 20

GENERIC PACKAGE VIEW

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.

4209819/B

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郵送先住所 : Texas Instruments, Post Office Box 655303, Dallas, Texas 75265  
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